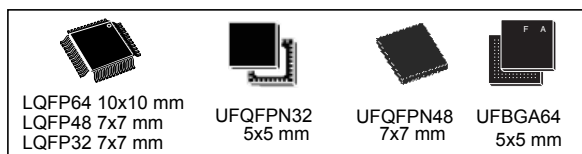


## ARM-based 32-bit MCU, 16 to 64-KB Flash, timers, ADC, DAC and communication interfaces, 2.0-3.6 V

Datasheet – production data

### Features

- Core: ARM® 32-bit Cortex™-M0 CPU, frequency up to 48 MHz
- Memories
  - 16 to 64 Kbytes of Flash memory
  - 8 Kbytes of SRAM with HW parity checking
- CRC calculation unit
- Reset and power management
  - Voltage range: 2.0 V to 3.6 V
  - Power-on/Power down reset (POR/PDR)
  - Programmable voltage detector (PVD)
  - Low power modes: Sleep, Stop, Standby
  - V<sub>BAT</sub> supply for RTC and backup registers
- Clock management
  - 4 to 32 MHz crystal oscillator
  - 32 kHz oscillator for RTC with calibration
  - Internal 8 MHz RC with x6 PLL option
  - Internal 40 kHz RC oscillator
- Up to 55 fast I/Os
  - All mappable on external interrupt vectors
  - Up to 36 I/Os with 5 V tolerant capability
- 5-channel DMA controller
- 1 x 12-bit, 1.0 µs ADC (up to 16 channels)
  - Conversion range: 0 to 3.6 V
  - Separate analog supply from 2.4 up to 3.6
- One 12-bit D/A converter
- Two fast low-power analog comparators with programmable input and output
- Up to 18 capacitive sensing channels supporting touchkey, linear and rotary touch sensors
- Up to 11 timers
  - One 16-bit 7-channel advanced-control timer for 6 channels PWM output, with deadtime generation and emergency stop
  - One 32-bit and one 16-bit timer, with up to 4 IC/OC, usable for IR control decoding



- One 16-bit timer, with 2 IC/OC, 1 OCN, deadtime generation and emergency stop
- Two 16-bit timers, each with IC/OC and OCN, deadtime generation, emergency stop and modulator gate for IR control
- One 16-bit timer with 1 IC/OC
- Independent and system watchdog timers
- SysTick timer: 24-bit downcounter
- One 16-bit basic timer to drive the DAC
- Calendar RTC with alarm and periodic wakeup from Stop/Standby
- Communication interfaces
  - Up to 2 I<sup>2</sup>C interfaces; one supporting Fast Mode Plus (1 Mbit/s) with 20 mA current sink, SMBus/PMBus and wakeup from STOP
  - Up to two USARTs supporting master synchronous SPI and modem control; one with ISO7816 interface, LIN, IrDA capability, auto baud rate detection and wakeup feature
  - Up to two SPIs (18 Mbit/s) with 4 to 16 programmable bit frame, 1 with I<sup>2</sup>S interface multiplexed
- HDMI CEC interface, wakeup on header reception
- Serial wire debug (SWD)
- 96-bit unique ID
- All packages ECOPACK®2

**Table 1. Device summary**

| Reference   | Part number                                                                                                             |
|-------------|-------------------------------------------------------------------------------------------------------------------------|
| STM32F051xx | STM32F051K4, STM32F051C4, STM32F051R4<br>STM32F051K6, STM32F051C6, STM32F051R6<br>STM32F051C8, STM32F051R8, STM32F051K8 |

# Contents

|          |                                                    |           |
|----------|----------------------------------------------------|-----------|
| <b>1</b> | <b>Introduction</b>                                | <b>8</b>  |
| <b>2</b> | <b>Description</b>                                 | <b>9</b>  |
| <b>3</b> | <b>Functional overview</b>                         | <b>12</b> |
| 3.1      | ARM® CortexTM-M0 core with embedded Flash and SRAM | 12        |
| 3.2      | Memories                                           | 12        |
| 3.3      | Boot modes                                         | 12        |
| 3.4      | Cyclic redundancy check calculation unit (CRC)     | 13        |
| 3.5      | Power management                                   | 13        |
| 3.5.1    | Power supply schemes                               | 13        |
| 3.5.2    | Power supply supervisors                           | 13        |
| 3.5.3    | Voltage regulator                                  | 13        |
| 3.5.4    | Low-power modes                                    | 14        |
| 3.6      | Clocks and startup                                 | 15        |
| 3.7      | General-purpose inputs/outputs (GPIOs)             | 16        |
| 3.8      | Direct memory access controller (DMA)              | 16        |
| 3.9      | Interrupts and events                              | 16        |
| 3.9.1    | Nested vectored interrupt controller (NVIC)        | 16        |
| 3.9.2    | Extended interrupt/event controller (EXTI)         | 16        |
| 3.10     | Analog to digital converter (ADC)                  | 17        |
| 3.10.1   | Temperature sensor                                 | 17        |
| 3.10.2   | Internal voltage reference ( $V_{REFINT}$ )        | 17        |
| 3.10.3   | $V_{BAT}$ battery voltage monitoring               | 18        |
| 3.11     | Digital-to-analog converter (DAC)                  | 18        |
| 3.12     | Comparators (COMP)                                 | 18        |
| 3.13     | Touch sensing controller (TSC)                     | 18        |
| 3.14     | Timers and watchdogs                               | 20        |
| 3.14.1   | Advanced-control timer (TIM1)                      | 21        |
| 3.14.2   | General-purpose timers (TIM2..3, TIM14..17)        | 21        |
| 3.14.3   | Basic timer TIM6                                   | 22        |
| 3.14.4   | Independent watchdog (IWDG)                        | 22        |
| 3.14.5   | System window watchdog (WWDG)                      | 22        |

|          |                                                                                        |           |
|----------|----------------------------------------------------------------------------------------|-----------|
| 3.14.6   | SysTick timer                                                                          | 22        |
| 3.15     | Real-time clock (RTC) and backup registers                                             | 22        |
| 3.16     | Inter-integrated circuit interfaces (I <sup>2</sup> C)                                 | 23        |
| 3.17     | Universal synchronous/asynchronous receiver transmitters (USART)                       | 24        |
| 3.18     | Serial peripheral interface (SPI)/Inter-integrated sound interfaces (I <sup>2</sup> S) | 25        |
| 3.19     | High-definition multimedia interface (HDMI) - consumer electronics control (CEC)       | 26        |
| 3.20     | Serial wire debug port (SW-DP)                                                         | 26        |
| <b>4</b> | <b>Pinouts and pin descriptions</b>                                                    | <b>27</b> |
| <b>5</b> | <b>Memory mapping</b>                                                                  | <b>39</b> |
| <b>6</b> | <b>Electrical characteristics</b>                                                      | <b>42</b> |
| 6.1      | Parameter conditions                                                                   | 42        |
| 6.1.1    | Minimum and maximum values                                                             | 42        |
| 6.1.2    | Typical values                                                                         | 42        |
| 6.1.3    | Typical curves                                                                         | 42        |
| 6.1.4    | Loading capacitor                                                                      | 42        |
| 6.1.5    | Pin input voltage                                                                      | 42        |
| 6.1.6    | Power supply scheme                                                                    | 43        |
| 6.1.7    | Current consumption measurement                                                        | 44        |
| 6.2      | Absolute maximum ratings                                                               | 44        |
| 6.3      | Operating conditions                                                                   | 46        |
| 6.3.1    | General operating conditions                                                           | 46        |
| 6.3.2    | Operating conditions at power-up / power-down                                          | 47        |
| 6.3.3    | Embedded reset and power control block characteristics                                 | 47        |
| 6.3.4    | Embedded reference voltage                                                             | 48        |
| 6.3.5    | Supply current characteristics                                                         | 49        |
| 6.3.6    | Wakeup time from low-power mode                                                        | 60        |
| 6.3.7    | External clock source characteristics                                                  | 61        |
| 6.3.8    | Internal clock source characteristics                                                  | 67        |
| 6.3.9    | PLL characteristics                                                                    | 69        |
| 6.3.10   | Memory characteristics                                                                 | 70        |
| 6.3.11   | EMC characteristics                                                                    | 70        |
| 6.3.12   | Electrical sensitivity characteristics                                                 | 72        |
| 6.3.13   | I/O current injection characteristics                                                  | 72        |

|          |                                             |            |
|----------|---------------------------------------------|------------|
| 6.3.14   | I/O port characteristics                    | 73         |
| 6.3.15   | NRST pin characteristics                    | 78         |
| 6.3.16   | 12-bit ADC characteristics                  | 79         |
| 6.3.17   | DAC electrical specifications               | 83         |
| 6.3.18   | Comparator characteristics                  | 85         |
| 6.3.19   | Temperature sensor characteristics          | 86         |
| 6.3.20   | V <sub>BAT</sub> monitoring characteristics | 86         |
| 6.3.21   | Timer characteristics                       | 87         |
| 6.3.22   | Communication interfaces                    | 88         |
| <b>7</b> | <b>Package characteristics</b>              | <b>95</b>  |
| 7.1      | Package mechanical data                     | 95         |
| 7.2      | Thermal characteristics                     | 108        |
| 7.2.1    | Reference document                          | 108        |
| 7.2.2    | Selecting the product temperature range     | 108        |
| <b>8</b> | <b>Part numbering</b>                       | <b>111</b> |
| <b>9</b> | <b>Revision history</b>                     | <b>112</b> |

## List of tables

|           |                                                                                                            |    |
|-----------|------------------------------------------------------------------------------------------------------------|----|
| Table 1.  | Device summary . . . . .                                                                                   | 1  |
| Table 2.  | STM32F051xx family device features and peripheral counts . . . . .                                         | 10 |
| Table 3.  | Temperature sensor calibration values . . . . .                                                            | 17 |
| Table 4.  | Internal voltage reference calibration values . . . . .                                                    | 17 |
| Table 5.  | Capacitive sensing GPIOs available on STM32F051xx devices . . . . .                                        | 19 |
| Table 6.  | No. of capacitive sensing channels available on STM32F051xx devices . . . . .                              | 19 |
| Table 7.  | Timer feature comparison . . . . .                                                                         | 20 |
| Table 8.  | Comparison of I2C analog and digital filters . . . . .                                                     | 23 |
| Table 9.  | STM32F051xx I <sup>2</sup> C implementation . . . . .                                                      | 24 |
| Table 10. | STM32F051xx USART implementation . . . . .                                                                 | 24 |
| Table 11. | STM32F051xx SPI/I2S implementation . . . . .                                                               | 25 |
| Table 12. | Legend/abbreviations used in the pinout table . . . . .                                                    | 31 |
| Table 13. | Pin definitions . . . . .                                                                                  | 31 |
| Table 14. | Alternate functions selected through GPIOA_AFR registers for port A . . . . .                              | 37 |
| Table 15. | Alternate functions selected through GPIOB_AFR registers for port B . . . . .                              | 38 |
| Table 16. | STM32F051xx peripheral register boundary addresses . . . . .                                               | 40 |
| Table 17. | Voltage characteristics . . . . .                                                                          | 44 |
| Table 18. | Current characteristics . . . . .                                                                          | 45 |
| Table 19. | Thermal characteristics . . . . .                                                                          | 45 |
| Table 20. | General operating conditions . . . . .                                                                     | 46 |
| Table 21. | Operating conditions at power-up / power-down . . . . .                                                    | 47 |
| Table 22. | Embedded reset and power control block characteristics . . . . .                                           | 47 |
| Table 23. | Programmable voltage detector characteristics . . . . .                                                    | 47 |
| Table 24. | Embedded internal reference voltage . . . . .                                                              | 48 |
| Table 25. | Typical and maximum current consumption from the V <sub>DD</sub> supply at V <sub>DD</sub> = 3.6 . . . . . | 50 |
| Table 26. | Typical and maximum current consumption from the V <sub>DDA</sub> supply . . . . .                         | 51 |
| Table 27. | Typical and maximum current consumption in Stop and Standby modes . . . . .                                | 52 |
| Table 28. | Typical and maximum current consumption from the V <sub>BAT</sub> supply . . . . .                         | 53 |
| Table 29. | Typical current consumption in Run mode, code with data processing<br>running from Flash . . . . .         | 54 |
| Table 30. | Typical current consumption in Sleep mode, code running from Flash or RAM . . . . .                        | 55 |
| Table 31. | Switching output I/O current consumption . . . . .                                                         | 57 |
| Table 32. | Peripheral current consumption . . . . .                                                                   | 59 |
| Table 33. | Low-power mode wakeup timings . . . . .                                                                    | 60 |
| Table 34. | High-speed external user clock characteristics . . . . .                                                   | 61 |
| Table 35. | Low-speed external user clock characteristics . . . . .                                                    | 62 |
| Table 36. | HSE oscillator characteristics . . . . .                                                                   | 63 |
| Table 37. | LSE oscillator characteristics (f <sub>LSE</sub> = 32.768 kHz) . . . . .                                   | 65 |
| Table 38. | HSI oscillator characteristics . . . . .                                                                   | 67 |
| Table 39. | HSI14 oscillator characteristics . . . . .                                                                 | 68 |
| Table 40. | LSI oscillator characteristics . . . . .                                                                   | 69 |
| Table 41. | PLL characteristics . . . . .                                                                              | 69 |
| Table 42. | Flash memory characteristics . . . . .                                                                     | 70 |
| Table 43. | Flash memory endurance and data retention . . . . .                                                        | 70 |
| Table 44. | EMS characteristics . . . . .                                                                              | 71 |
| Table 45. | EMI characteristics . . . . .                                                                              | 71 |
| Table 46. | ESD absolute maximum ratings . . . . .                                                                     | 72 |
| Table 47. | Electrical sensitivities . . . . .                                                                         | 72 |

|           |                                                                                                                  |     |
|-----------|------------------------------------------------------------------------------------------------------------------|-----|
| Table 48. | I/O current injection susceptibility . . . . .                                                                   | 73  |
| Table 49. | I/O static characteristics . . . . .                                                                             | 73  |
| Table 50. | Output voltage characteristics . . . . .                                                                         | 76  |
| Table 51. | I/O AC characteristics . . . . .                                                                                 | 77  |
| Table 52. | NRST pin characteristics . . . . .                                                                               | 78  |
| Table 53. | ADC characteristics . . . . .                                                                                    | 79  |
| Table 54. | $R_{AIN}$ max for $f_{ADC} = 14$ MHz . . . . .                                                                   | 80  |
| Table 55. | ADC accuracy . . . . .                                                                                           | 81  |
| Table 56. | DAC characteristics . . . . .                                                                                    | 83  |
| Table 57. | Comparator characteristics . . . . .                                                                             | 85  |
| Table 58. | TS characteristics . . . . .                                                                                     | 86  |
| Table 59. | $V_{BAT}$ monitoring characteristics . . . . .                                                                   | 86  |
| Table 60. | TIMx characteristics . . . . .                                                                                   | 87  |
| Table 61. | IWDG min/max timeout period at 40 kHz (LSI) . . . . .                                                            | 87  |
| Table 62. | WWDG min/max timeout value at 48 MHz (PCLK) . . . . .                                                            | 88  |
| Table 63. | I2C characteristics . . . . .                                                                                    | 88  |
| Table 64. | I2C analog filter characteristics . . . . .                                                                      | 89  |
| Table 65. | SPI characteristics . . . . .                                                                                    | 90  |
| Table 66. | I <sup>2</sup> S characteristics . . . . .                                                                       | 93  |
| Table 67. | LQFP64 – 10 x 10 mm 64 pin low-profile quad flat package mechanical data . . . . .                               | 96  |
| Table 68. | LQFP48 – 7 x 7 mm, 48-pin low-profile quad flat package mechanical data . . . . .                                | 98  |
| Table 69. | LQFP32 – 7 x 7mm 32-pin low-profile quad flat package mechanical data . . . . .                                  | 100 |
| Table 70. | UFBGA64 – 5 x 5 mm, 0.5 mm pitch, package mechanical data . . . . .                                              | 103 |
| Table 71. | UFQFPN48 – 7 x 7 mm, 0.5 mm pitch, package mechanical data . . . . .                                             | 105 |
| Table 72. | UFQFPN32 – 32-lead ultra thin fine pitch quad flat no-lead package (5 x 5),<br>package mechanical data . . . . . | 107 |
| Table 73. | Package thermal characteristics . . . . .                                                                        | 108 |
| Table 74. | Ordering information scheme . . . . .                                                                            | 111 |
| Table 75. | Document revision history . . . . .                                                                              | 112 |

## List of figures

|            |                                                                                              |     |
|------------|----------------------------------------------------------------------------------------------|-----|
| Figure 1.  | Block diagram . . . . .                                                                      | 11  |
| Figure 2.  | Clock tree . . . . .                                                                         | 15  |
| Figure 3.  | LQFP64 64-pin package pinout (top view) . . . . .                                            | 27  |
| Figure 4.  | UFBGA64 64-pin package ball-out (top view) . . . . .                                         | 28  |
| Figure 5.  | LQFP48 48-pin package pinout (top view) . . . . .                                            | 29  |
| Figure 6.  | UFQFPN48 48-pin package pinout (top view) . . . . .                                          | 29  |
| Figure 7.  | LQFP32 32-pin package pinout (top view) . . . . .                                            | 30  |
| Figure 8.  | UFQFPN32 32-pin package pinout (top view) . . . . .                                          | 30  |
| Figure 9.  | STM32F051xx memory map . . . . .                                                             | 39  |
| Figure 10. | Pin loading conditions . . . . .                                                             | 42  |
| Figure 11. | Pin input voltage . . . . .                                                                  | 42  |
| Figure 12. | Power supply scheme . . . . .                                                                | 43  |
| Figure 13. | Current consumption measurement scheme . . . . .                                             | 44  |
| Figure 14. | High-speed external clock source AC timing diagram . . . . .                                 | 61  |
| Figure 15. | Low-speed external clock source AC timing diagram . . . . .                                  | 62  |
| Figure 16. | Typical application with an 8 MHz crystal . . . . .                                          | 64  |
| Figure 17. | Typical application with a 32.768 kHz crystal . . . . .                                      | 66  |
| Figure 18. | HSI oscillator accuracy characterization results . . . . .                                   | 67  |
| Figure 19. | HSI14 oscillator accuracy characterization results . . . . .                                 | 68  |
| Figure 20. | TC and TTa I/O input characteristics . . . . .                                               | 75  |
| Figure 21. | Five volt tolerant (FT and FTf) I/O input characteristics . . . . .                          | 75  |
| Figure 22. | I/O AC characteristics definition . . . . .                                                  | 78  |
| Figure 23. | Recommended NRST pin protection . . . . .                                                    | 79  |
| Figure 24. | ADC accuracy characteristics . . . . .                                                       | 82  |
| Figure 25. | Typical connection diagram using the ADC . . . . .                                           | 82  |
| Figure 26. | 12-bit buffered / non-buffered DAC . . . . .                                                 | 84  |
| Figure 27. | I <sup>2</sup> C bus AC waveforms and measurement circuit . . . . .                          | 90  |
| Figure 28. | SPI timing diagram - slave mode and CPHA = 0 . . . . .                                       | 91  |
| Figure 29. | SPI timing diagram - slave mode and CPHA = 1 . . . . .                                       | 92  |
| Figure 30. | SPI timing diagram - master mode . . . . .                                                   | 92  |
| Figure 31. | I2S slave timing diagram (Philips protocol) . . . . .                                        | 94  |
| Figure 32. | I2S master timing diagram (Philips protocol) . . . . .                                       | 94  |
| Figure 33. | LQFP64 – 10 x 10 mm 64 pin low-profile quad flat package outline . . . . .                   | 96  |
| Figure 34. | LQFP64 recommended footprint . . . . .                                                       | 97  |
| Figure 35. | LQFP48 – 7 x 7 mm, 48 pin low-profile quad flat package outline . . . . .                    | 98  |
| Figure 36. | LQFP48 recommended footprint . . . . .                                                       | 99  |
| Figure 37. | LQFP32 – 7 x 7mm 32-pin low-profile quad flat package outline . . . . .                      | 100 |
| Figure 38. | LQFP32 recommended footprint . . . . .                                                       | 101 |
| Figure 39. | UFBGA64 - 5 x 5 mm, 0.5 mm pitch, package outline . . . . .                                  | 102 |
| Figure 40. | UFQFPN48 – 7 x 7 mm, 0.5 mm pitch, package outline . . . . .                                 | 104 |
| Figure 41. | UFQFPN48 recommended footprint . . . . .                                                     | 105 |
| Figure 42. | UFQFPN32 – 32-lead ultra thin fine pitch quad flat no-lead package outline (5 x 5) . . . . . | 106 |
| Figure 43. | UFQFPN32 recommended footprint . . . . .                                                     | 107 |
| Figure 44. | LQFP64 P <sub>D</sub> max vs. T <sub>A</sub> . . . . .                                       | 110 |

# 1 Introduction

This datasheet provides the ordering information and mechanical device characteristics of the STM32F051xx microcontrollers.

This document should be read in conjunction with the STM32F0xxxx reference manual (RM0091). The reference manual is available from the STMicroelectronics website [www.st.com](http://www.st.com).

For information on the ARM Cortex™-M0 core, please refer to the Cortex™-M0 Technical Reference Manual, available from the [www.arm.com](http://www.arm.com) website at the following address:  
<http://infocenter.arm.com/help/index.jsp?topic=/com.arm.doc.ddi0432c/index.html>.





## 2 Description

The STM32F051xx microcontrollers incorporate the high-performance ARM Cortex™-M0 32-bit RISC core operating at a 48 MHz frequency, high-speed embedded memories (up to 64 Kbytes of Flash memory and 8 Kbytes of SRAM), and an extensive range of enhanced peripherals and I/Os. All devices offer standard communication interfaces (up to two I<sup>2</sup>Cs, two SPIs, one I2S, one HDMI CEC and up to two USARTs), one 12-bit ADC, one 12-bit DAC, up to six general-purpose 16-bit timers, a 32-bit timer and an advanced-control PWM timer.

The STM32F051xx microcontrollers operate in the -40 to +85 °C and -40 to +105 °C temperature ranges from a 2.0 to 3.6 V power supply. A comprehensive set of power-saving modes allows the design of low-power applications.

The STM32F051xx microcontrollers include devices in six different packages ranging from 32 pins to 64 pins. Depending on the device chosen, different sets of peripherals are included. The description below provides an overview of the complete range of STM32F051xx peripherals proposed.

These features make the STM32F051xx microcontrollers suitable for a wide range of applications such as application control and user interfaces, handheld equipment, A/V receivers and digital TV, PC peripherals, gaming and GPS platforms, industrial applications, PLCs, inverters, printers, scanners, alarm systems, video intercoms, and HVACs.

Table 2. STM32F051xx family device features and peripheral counts

| Peripheral                      |                          | STM32F051Kx                                                                                                 |    |    | STM32F051Cx          |    |       | STM32F051Rx             |    |       |
|---------------------------------|--------------------------|-------------------------------------------------------------------------------------------------------------|----|----|----------------------|----|-------|-------------------------|----|-------|
| Flash (Kbytes)                  |                          | 16                                                                                                          | 32 | 64 | 16                   | 32 | 64    | 16                      | 32 | 64    |
| SRAM (Kbytes)                   |                          | 8                                                                                                           |    |    |                      |    |       |                         |    |       |
| Timers                          | Advanced control         | 1 (16-bit)                                                                                                  |    |    |                      |    |       |                         |    |       |
|                                 | General purpose          | 5 (16-bit)<br>1 (32-bit)                                                                                    |    |    |                      |    |       |                         |    |       |
|                                 | Basic                    | 1 (16-bit)                                                                                                  |    |    |                      |    |       |                         |    |       |
| Comm. interfaces                | SPI [I2S] <sup>(1)</sup> | 1 [1] <sup>(2)</sup>                                                                                        |    |    | 1 [1] <sup>(2)</sup> |    | 2 [1] | 1 [1] <sup>(2)</sup>    |    | 2 [1] |
|                                 | I <sup>2</sup> C         | 1 <sup>(3)</sup>                                                                                            |    |    | 1 <sup>(3)</sup>     |    | 2     | 1 <sup>(3)</sup>        |    | 2     |
|                                 | USART                    | 1 <sup>(4)</sup>                                                                                            | 2  |    | 1 <sup>(4)</sup>     | 2  |       | 1 <sup>(4)</sup>        | 2  |       |
|                                 | CEC                      | 1                                                                                                           |    |    |                      |    |       |                         |    |       |
| 12-bit ADC (number of channels) |                          | 1<br>(10 ext. + 3 int.)                                                                                     |    |    |                      |    |       | 1<br>(16 ext. + 3 int.) |    |       |
| GPIOs                           |                          | 25 (on LQFP32)<br>27 (on UFQFPN32)                                                                          |    |    | 39                   |    |       | 55                      |    |       |
| Capacitive sensing channels     |                          | 13 (on LQFP32)<br>14 (on UFQFPN32)                                                                          |    |    | 17                   |    |       | 18                      |    |       |
| 12-bit ADC (number of channels) |                          | 1<br>16 ext. + 3 int.                                                                                       |    |    |                      |    |       |                         |    |       |
| Analog comparator               |                          | 2                                                                                                           |    |    |                      |    |       |                         |    |       |
| Max. CPU frequency              |                          | 48 MHz                                                                                                      |    |    |                      |    |       |                         |    |       |
| Operating voltage               |                          | 2.0 to 3.6 V                                                                                                |    |    |                      |    |       |                         |    |       |
| Operating temperature           |                          | Ambient operating temperature: -40 °C to 85 °C / -40 °C to 105 °C<br>Junction temperature: -40 °C to 125 °C |    |    |                      |    |       |                         |    |       |
| Packages                        |                          | LQFP32<br>UFQFPN32                                                                                          |    |    | LQFP48<br>UFQFPN48   |    |       | LQFP64<br>UFBGA64       |    |       |

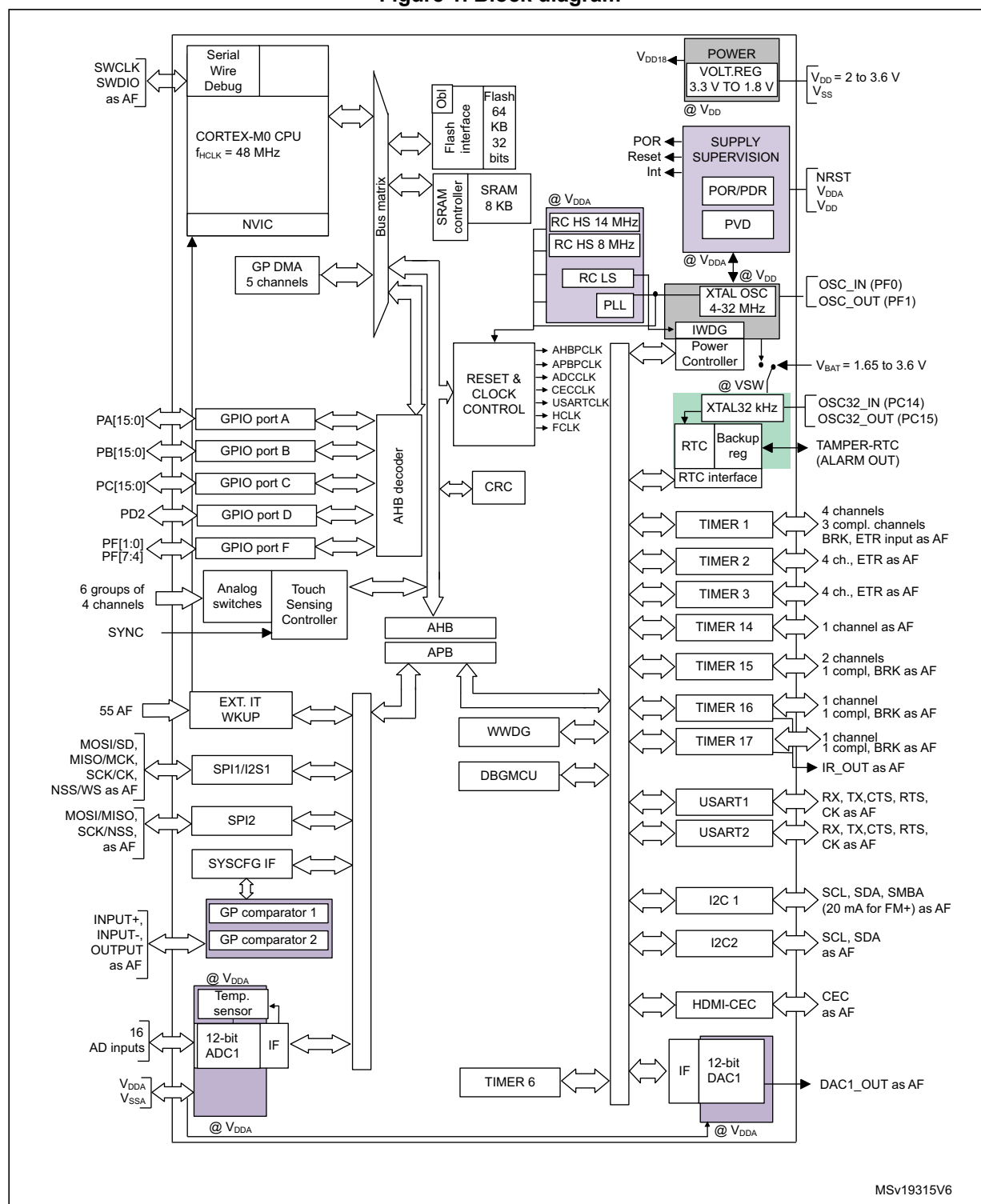
1. The SPI1 interface can be used either in SPI mode or in I2S audio mode.

2. SPI2 is not present.

3. I2C2 is not present.

4. USART2 is not present.

**Figure 1. Block diagram**



## 3 Functional overview

### 3.1 ARM® Cortex™-M0 core with embedded Flash and SRAM

The ARM Cortex™-M0 processor is the latest generation of ARM processors for embedded systems. It has been developed to provide a low-cost platform that meets the needs of MCU implementation, with a reduced pin count and low-power consumption, while delivering outstanding computational performance and an advanced system response to interrupts.

The ARM Cortex™-M0 32-bit RISC processor features exceptional code-efficiency, delivering the high-performance expected from an ARM core in the memory size usually associated with 8- and 16-bit devices.

The STM32F0xx family has an embedded ARM core and is therefore compatible with all ARM tools and software.

*Figure 1* shows the general block diagram of the device family.

### 3.2 Memories

The device has the following features:

- 8 Kbytes of embedded SRAM accessed (read/write) at CPU clock speed with 0 wait states and featuring embedded parity checking with exception generation for fail-critical applications.
- The non-volatile memory is divided into two arrays:
  - 16 to 64 Kbytes of embedded Flash memory for programs and data
  - Option bytes

The option bytes are used to write-protect the memory (with 4 KB granularity) and/or readout-protect the whole memory with the following options:

- Level 0: no readout protection
- Level 1: memory readout protection, the Flash memory cannot be read from or written to if either debug features are connected or boot in RAM is selected
- Level 2: chip readout protection, debug features (Cortex-M0 serial wire) and boot in RAM selection disabled

### 3.3 Boot modes

At startup, the boot pin and boot selector option bit are used to select one of three boot options:

- Boot from User Flash
- Boot from System Memory
- Boot from embedded SRAM

The boot loader is located in System Memory. It is used to reprogram the Flash memory by using USART on pins PA14/PA15 or PA9/PA10.

### 3.4 Cyclic redundancy check calculation unit (CRC)

The CRC (cyclic redundancy check) calculation unit is used to get a CRC code from a 32-bit data word and a CRC-32 (Ethernet) polynomial.

Among other applications, CRC-based techniques are used to verify data transmission or storage integrity. In the scope of the EN/IEC 60335-1 standard, they offer a means of verifying the Flash memory integrity. The CRC calculation unit helps compute a signature of the software during runtime, to be compared with a reference signature generated at link-time and stored at a given memory location.

### 3.5 Power management

#### 3.5.1 Power supply schemes

- $V_{DD} = 2.0$  to  $3.6$  V: external power supply for I/Os and the internal regulator. Provided externally through  $V_{DD}$  pins.
- $V_{DDA} = 2.0$  to  $3.6$  V: external analog power supply for ADC, Reset blocks, RCs and PLL (minimum voltage to be applied to  $V_{DDA}$  is  $2.4$  V when the ADC and DAC are used). The  $V_{DDA}$  voltage level must be always greater or equal to the  $V_{DD}$  voltage level and must be provided first.
- $V_{BAT} = 1.65$  to  $3.6$  V: power supply for RTC, external clock  $32$  kHz oscillator and backup registers (through power switch) when  $V_{DD}$  is not present.

For more details on how to connect power pins, refer to [Figure 12: Power supply scheme](#).

#### 3.5.2 Power supply supervisors

The device has integrated power-on reset (POR) and power-down reset (PDR) circuits. They are always active, and ensure proper operation above a threshold of  $2$  V. The device remains in reset mode when the monitored supply voltage is below a specified threshold,  $V_{POR/PDR}$ , without the need for an external reset circuit.

- The POR monitors only the  $V_{DD}$  supply voltage. During the startup phase it is required that  $V_{DDA}$  should arrive first and be greater than or equal to  $V_{DD}$ .
- The PDR monitors both the  $V_{DD}$  and  $V_{DDA}$  supply voltages, however the  $V_{DDA}$  power supply supervisor can be disabled (by programming a dedicated Option bit) to reduce the power consumption if the application design ensures that  $V_{DDA}$  is higher than or equal to  $V_{DD}$ .

The device features an embedded programmable voltage detector (PVD) that monitors the  $V_{DD}$  power supply and compares it to the  $V_{PVD}$  threshold. An interrupt can be generated when  $V_{DD}$  drops below the  $V_{PVD}$  threshold and/or when  $V_{DD}$  is higher than the  $V_{PVD}$  threshold. The interrupt service routine can then generate a warning message and/or put the MCU into a safe state. The PVD is enabled by software.

#### 3.5.3 Voltage regulator

The regulator has two operating modes and it is always enabled after reset.

- Main (MR) is used in normal operating mode (Run).
- Low power (LPR) can be used in Stop mode where the power demand is reduced.

In Standby mode, it is put in power down mode. In this mode, the regulator output is in high impedance and the kernel circuitry is powered down, inducing zero consumption (but the contents of the registers and SRAM are lost).

### 3.5.4 Low-power modes

The STM32F051xx microcontrollers support three low-power modes to achieve the best compromise between low power consumption, short startup time and available wakeup sources:

- **Sleep mode**

In Sleep mode, only the CPU is stopped. All peripherals continue to operate and can wake up the CPU when an interrupt/event occurs.

- **Stop mode**

Stop mode achieves very low power consumption while retaining the content of SRAM and registers. All clocks in the 1.8 V domain are stopped, the PLL, the HSI RC and the HSE crystal oscillators are disabled. The voltage regulator can also be put either in normal or in low power mode.

The device can be woken up from Stop mode by any of the EXTI lines. The EXTI line source can be one of the 16 external lines, the PVD output, RTC alarm, COMPx, I2C1, USART1 or the CEC.

The I2C1, USART1 and the CEC can be configured to enable the HSI RC oscillator for processing incoming data. If this is used when the voltage regulator is put in low power mode, the regulator is first switched to normal mode before the clock is provided to the given peripheral.

- **Standby mode**

The Standby mode is used to achieve the lowest power consumption. The internal voltage regulator is switched off so that the entire 1.8 V domain is powered off. The PLL, the HSI RC and the HSE crystal oscillators are also switched off. After entering Standby mode, SRAM and register contents are lost except for registers in the RTC domain and Standby circuitry.

The device exits Standby mode when an external reset (NRST pin), an IWDG reset, a rising edge on the WKUP pins, or an RTC event occurs.

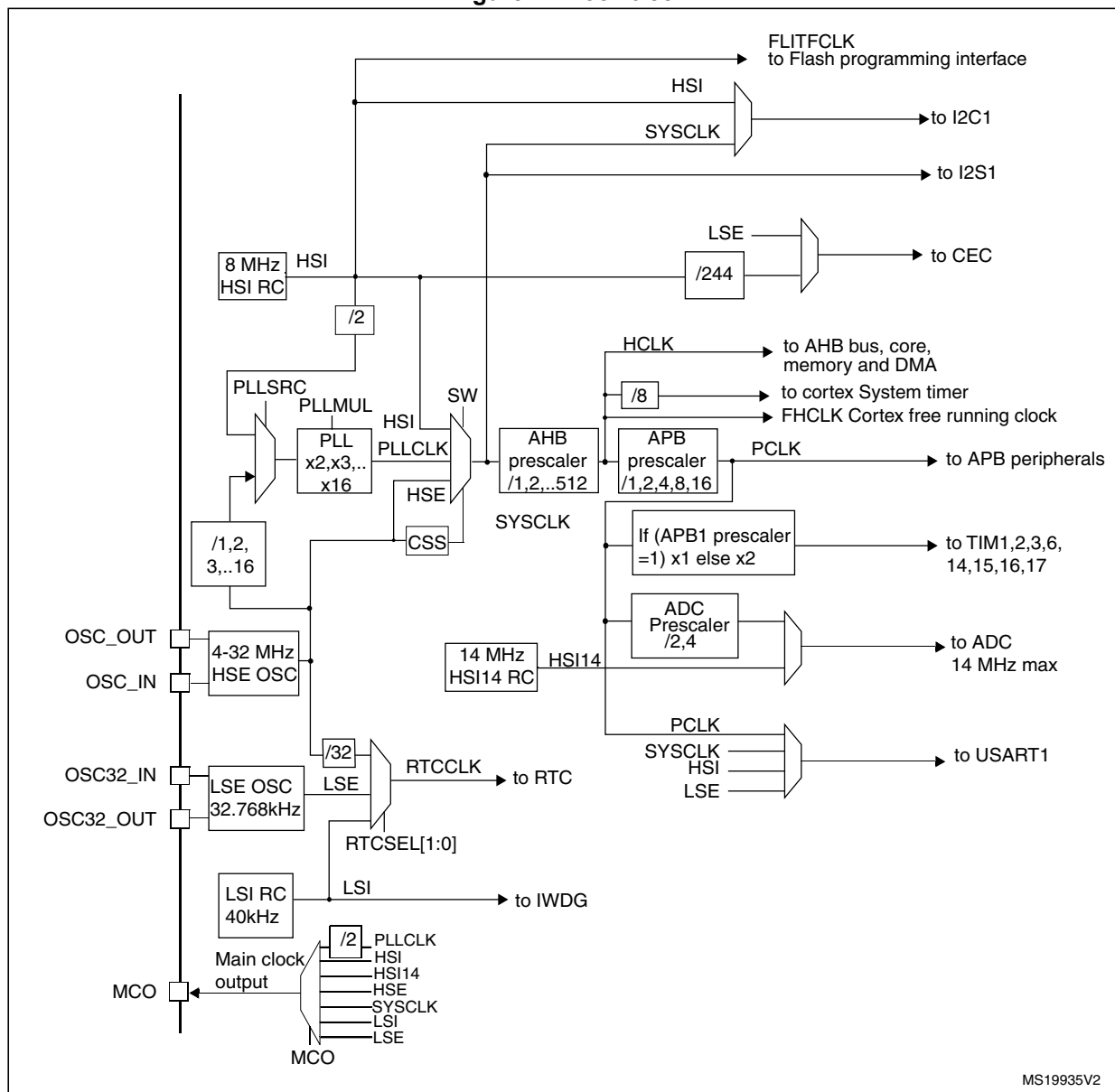
*Note: The RTC, the IWDG, and the corresponding clock sources are not stopped by entering Stop or Standby mode.*

### 3.6 Clocks and startup

System clock selection is performed on startup, however the internal RC 8 MHz oscillator is selected as default CPU clock on reset. An external 4-32 MHz clock can be selected, in which case it is monitored for failure. If failure is detected, the system automatically switches back to the internal RC oscillator. A software interrupt is generated if enabled. Similarly, full interrupt management of the PLL clock entry is available when necessary (for example on failure of an indirectly used external crystal, resonator or oscillator).

Several prescalers allow the application to configure the frequency of the AHB and the APB domains. The maximum frequency of the AHB and the APB domains is 48 MHz.

### Figure 2. Clock tree



### 3.7 General-purpose inputs/outputs (GPIOs)

Each of the GPIO pins can be configured by software as output (push-pull or open-drain), as input (with or without pull-up or pull-down) or as peripheral alternate function. Most of the GPIO pins are shared with digital or analog alternate functions.

The I/O configuration can be locked if needed following a specific sequence in order to avoid spurious writing to the I/Os registers.

### 3.8 Direct memory access controller (DMA)

The 5-channel general-purpose DMAs manage memory-to-memory, peripheral-to-memory and memory-to-peripheral transfers.

The DMA supports circular buffer management, removing the need for user code intervention when the controller reaches the end of the buffer.

Each channel is connected to dedicated hardware DMA requests, with support for software trigger on each channel. Configuration is made by software and transfer sizes between source and destination are independent.

DMA can be used with the main peripherals: SPI, I2S, I2C, USART, all TIMx timers (except TIM14), DAC and ADC.

### 3.9 Interrupts and events

#### 3.9.1 Nested vectored interrupt controller (NVIC)

The STM32F0xx family embeds a nested vectored interrupt controller able to handle up to 32 maskable interrupt channels (not including the 16 interrupt lines of Cortex™-M0) and 4 priority levels.

- Closely coupled NVIC gives low latency interrupt processing
- Interrupt entry vector table address passed directly to the core
- Closely coupled NVIC core interface
- Allows early processing of interrupts
- Processing of late arriving higher priority interrupts
- Support for tail-chaining
- Processor state automatically saved
- Interrupt entry restored on interrupt exit with no instruction overhead

This hardware block provides flexible interrupt management features with minimal interrupt latency.

#### 3.9.2 Extended interrupt/event controller (EXTI)

The extended interrupt/event controller consists of 24 edge detector lines used to generate interrupt/event requests and wake-up the system. Each line can be independently configured to select the trigger event (rising edge, falling edge, both) and can be masked independently. A pending register maintains the status of the interrupt requests. The EXTI can detect an external line with a pulse width shorter than the internal clock period. Up to 55 GPIOs can be connected to the 16 external interrupt lines.



### 3.10 Analog to digital converter (ADC)

The 12-bit analog to digital converter has up to 16 external and 3 internal (temperature sensor, voltage reference, VBAT voltage measurement) channels and performs conversions in single-shot or scan modes. In scan mode, automatic conversion is performed on a selected group of analog inputs.

The ADC can be served by the DMA controller.

An analog watchdog feature allows very precise monitoring of the converted voltage of one, some or all selected channels. An interrupt is generated when the converted voltage is outside the programmed thresholds.

#### 3.10.1 Temperature sensor

The temperature sensor (TS) generates a voltage  $V_{SENSE}$  that varies linearly with temperature.

The temperature sensor is internally connected to the ADC\_IN16 input channel which is used to convert the sensor output voltage into a digital value.

The sensor provides good linearity but it has to be calibrated to obtain good overall accuracy of the temperature measurement. As the offset of the temperature sensor varies from chip to chip due to process variation, the uncalibrated internal temperature sensor is suitable for applications that detect temperature changes only.

To improve the accuracy of the temperature sensor measurement, each device is individually factory-calibrated by ST. The temperature sensor factory calibration data are stored by ST in the system memory area, accessible in read-only mode.

**Table 3. Temperature sensor calibration values**

| Calibration value name | Description                                                                                         | Memory address            |
|------------------------|-----------------------------------------------------------------------------------------------------|---------------------------|
| TS_CAL1                | TS ADC raw data acquired at a temperature of 30 °C ( $\pm 5$ °C), $V_{DDA} = 3.3$ V ( $\pm 10$ mV)  | 0x1FFF F7B8 - 0x1FFF F7B9 |
| TS_CAL2                | TS ADC raw data acquired at a temperature of 110 °C ( $\pm 5$ °C), $V_{DDA} = 3.3$ V ( $\pm 10$ mV) | 0x1FFF F7C2 - 0x1FFF F7C3 |

#### 3.10.2 Internal voltage reference ( $V_{REFINT}$ )

The internal voltage reference ( $V_{REFINT}$ ) provides a stable (bandgap) voltage output for the ADC and Comparators.  $V_{REFINT}$  is internally connected to the ADC\_IN17 input channel. The precise voltage of  $V_{REFINT}$  is individually measured for each part by ST during production test and stored in the system memory area. It is accessible in read-only mode.

**Table 4. Internal voltage reference calibration values**

| Calibration value name | Description                                                                                 | Memory address            |
|------------------------|---------------------------------------------------------------------------------------------|---------------------------|
| VREFINT_CAL            | Raw data acquired at a temperature of 30 °C ( $\pm 5$ °C), $V_{DDA} = 3.3$ V ( $\pm 10$ mV) | 0x1FFF F7BA - 0x1FFF F7BB |

### 3.10.3 $V_{BAT}$ battery voltage monitoring

This embedded hardware feature allows the application to measure the  $V_{BAT}$  battery voltage using the internal ADC channel ADC\_IN18. As the  $V_{BAT}$  voltage may be higher than  $V_{DDA}$ , and thus outside the ADC input range, the  $V_{BAT}$  pin is internally connected to a bridge divider by 2. As a consequence, the converted digital value is half the  $V_{BAT}$  voltage.

## 3.11 Digital-to-analog converter (DAC)

The 12-bit buffered DAC channel can be used to convert digital signals into analog voltage signal outputs. The chosen design structure is composed of integrated resistor strings and an amplifier in non-inverting configuration.

This digital Interface supports the following features:

- Left or right data alignment in 12-bit mode
- Synchronized update capability
- DMA capability
- External triggers for conversion

Five DAC trigger inputs are used in the device. The DAC is triggered through the timer trigger outputs and the DAC interface is generating its own DMA requests.

## 3.12 Comparators (COMP)

The device embeds two fast rail-to-rail low-power comparators with programmable reference voltage (internal or external), hysteresis and speed (low speed for low power) and with selectable output polarity.

The reference voltage can be one of the following:

- External I/O
- DAC output pins
- Internal reference voltage or submultiple (1/4, 1/2, 3/4). Refer to [Table 24: Embedded internal reference voltage](#) for the value and precision of the internal reference voltage.

Both comparators can wake up from STOP mode, generate interrupts and breaks for the timers and can be also combined into a window comparator.

## 3.13 Touch sensing controller (TSC)

The STM32F051xx devices provide a simple solution for adding capacitive sensing functionality to any application. These devices offer up to 18 capacitive sensing channels distributed over 6 analog I/O groups.

Capacitive sensing technology is able to detect the presence of a finger near a sensor which is protected from direct touch by a dielectric (glass, plastic...). The capacitive variation introduced by the finger (or any conductive object) is measured using a proven implementation based on a surface charge transfer acquisition principle. It consists of charging the sensor capacitance and then transferring a part of the accumulated charges into a sampling capacitor until the voltage across this capacitor has reached a specific

threshold. To limit the CPU bandwidth usage, this acquisition is directly managed by the hardware touch sensing controller and only requires few external components to operate.

The touch sensing controller is fully supported by the STMTouch touch sensing firmware library, which is free to use and allows touch sensing functionality to be implemented reliably in the end application.

**Table 5. Capacitive sensing GPIOs available on STM32F051xx devices**

| Group | Capacitive sensing signal name | Pin name | Group | Capacitive sensing signal name | Pin name |
|-------|--------------------------------|----------|-------|--------------------------------|----------|
| 1     | TSC_G1_IO1                     | PA0      | 4     | TSC_G4_IO1                     | PA9      |
|       | TSC_G1_IO2                     | PA1      |       | TSC_G4_IO2                     | PA10     |
|       | TSC_G1_IO3                     | PA2      |       | TSC_G4_IO3                     | PA11     |
|       | TSC_G1_IO4                     | PA3      |       | TSC_G4_IO4                     | PA12     |
| 2     | TSC_G2_IO1                     | PA4      | 5     | TSC_G5_IO1                     | PB3      |
|       | TSC_G2_IO2                     | PA5      |       | TSC_G5_IO2                     | PB4      |
|       | TSC_G2_IO3                     | PA6      |       | TSC_G5_IO3                     | PB6      |
|       | TSC_G2_IO4                     | PA7      |       | TSC_G5_IO4                     | PB7      |
| 3     | TSC_G3_IO1                     | PC5      | 6     | TSC_G6_IO1                     | PB11     |
|       | TSC_G3_IO2                     | PB0      |       | TSC_G6_IO2                     | PB12     |
|       | TSC_G3_IO3                     | PB1      |       | TSC_G6_IO3                     | PB13     |
|       | TSC_G3_IO4                     | PB2      |       | TSC_G6_IO4                     | PB14     |

**Table 6. No. of capacitive sensing channels available on STM32F051xx devices**

| Analog I/O group                      | Number of capacitive sensing channels |             |                        |                      |
|---------------------------------------|---------------------------------------|-------------|------------------------|----------------------|
|                                       | STM32F051Rx                           | STM32F051Cx | STM32F051Kx (UFQFPN32) | STM32F051Kx (LQFP32) |
| G1                                    | 3                                     | 3           | 3                      | 3                    |
| G2                                    | 3                                     | 3           | 3                      | 3                    |
| G3                                    | 3                                     | 2           | 2                      | 1                    |
| G4                                    | 3                                     | 3           | 3                      | 3                    |
| G5                                    | 3                                     | 3           | 3                      | 3                    |
| G6                                    | 3                                     | 3           | 0                      | 0                    |
| Number of capacitive sensing channels | 18                                    | 17          | 14                     | 13                   |

### 3.14 Timers and watchdogs

The STM32F051xx devices include up to six general-purpose timers, one basic timer and an advanced control timer.

[Table 7](#) compares the features of the advanced-control, general-purpose and basic timers.

**Table 7. Timer feature comparison**

| Timer type       | Timer        | Counter resolution | Counter type      | Prescaler factor                | DMA request generation | Capture/compare channels | Complementary outputs |
|------------------|--------------|--------------------|-------------------|---------------------------------|------------------------|--------------------------|-----------------------|
| Advanced control | TIM1         | 16-bit             | Up, down, up/down | Any integer between 1 and 65536 | Yes                    | 4                        | Yes                   |
| General purpose  | TIM2         | 32-bit             | Up, down, up/down | Any integer between 1 and 65536 | Yes                    | 4                        | No                    |
|                  | TIM3         | 16-bit             | Up, down, up/down | Any integer between 1 and 65536 | Yes                    | 4                        | No                    |
|                  | TIM14        | 16-bit             | Up                | Any integer between 1 and 65536 | No                     | 1                        | No                    |
|                  | TIM15        | 16-bit             | Up                | Any integer between 1 and 65536 | Yes                    | 2                        | Yes                   |
|                  | TIM16, TIM17 | 16-bit             | Up                | Any integer between 1 and 65536 | Yes                    | 1                        | Yes                   |
| Basic            | TIM6         | 16-bit             | Up                | Any integer between 1 and 65536 | Yes                    | 0                        | No                    |

### 3.14.1 Advanced-control timer (TIM1)

The advanced-control timer (TIM1) can be seen as a three-phase PWM multiplexed on six channels. It has complementary PWM outputs with programmable inserted dead times. It can also be seen as a complete general-purpose timer. The four independent channels can be used for:

- Input capture
- Output compare
- PWM generation (edge or center-aligned modes)
- One-pulse mode output

If configured as a standard 16-bit timer, it has the same features as the TIMx timer. If configured as the 16-bit PWM generator, it has full modulation capability (0-100%).

The counter can be frozen in debug mode.

Many features are shared with those of the standard timers which have the same architecture. The advanced control timer can therefore work together with the other timers via the Timer Link feature for synchronization or event chaining.

### 3.14.2 General-purpose timers (TIM2..3, TIM14..17)

There are six synchronizable general-purpose timers embedded in the STM32F051xx devices (see [Table 7](#) for differences). Each general-purpose timer can be used to generate PWM outputs, or as simple time base.

#### TIM2, TIM3

STM32F051xx devices feature two synchronizable 4-channel general-purpose timers. TIM2 is based on a 32-bit auto-reload up/downcounter and a 16-bit prescaler. TIM3 is based on a 16-bit auto-reload up/downcounter and a 16-bit prescaler. They feature 4 independent channels each for input capture/output compare, PWM or one-pulse mode output. This gives up to 12 input captures/output compares/PWMs on the largest packages.

The TIM2 and TIM3 general-purpose timers can work together or with the TIM1 advanced-control timer via the Timer Link feature for synchronization or event chaining.

TIM2 and TIM3 both have independent DMA request generation.

These timers are capable of handling quadrature (incremental) encoder signals and the digital outputs from 1 to 3 hall-effect sensors.

Their counters can be frozen in debug mode.

#### TIM14

This timer is based on a 16-bit auto-reload upcounter and a 16-bit prescaler.

TIM14 features one single channel for input capture/output compare, PWM or one-pulse mode output.

Its counter can be frozen in debug mode.

#### TIM15, TIM16 and TIM17

These timers are based on a 16-bit auto-reload upcounter and a 16-bit prescaler.

TIM15 has two independent channels, whereas TIM16 and TIM17 feature one single

channel for input capture/output compare, PWM or one-pulse mode output.

The TIM15, TIM16 and TIM17 timers can work together, and TIM15 can also operate with TIM1 via the Timer Link feature for synchronization or event chaining.

TIM15 can be synchronized with TIM16 and TIM17.

TIM15, TIM16 and TIM17 have a complementary output with dead-time generation and independent DMA request generation.

Their counters can be frozen in debug mode.

### 3.14.3 Basic timer TIM6

This timer is mainly used for DAC trigger generation. It can also be used as a generic 16-bit time base.

### 3.14.4 Independent watchdog (IWDG)

The independent watchdog is based on an 8-bit prescaler and 12-bit downcounter with user-defined refresh window. It is clocked from an independent 40 kHz internal RC and as it operates independently from the main clock, it can operate in Stop and Standby modes. It can be used either as a watchdog to reset the device when a problem occurs, or as a free running timer for application timeout management. It is hardware or software configurable through the option bytes. The counter can be frozen in debug mode.

### 3.14.5 System window watchdog (WWDG)

The system window watchdog is based on a 7-bit downcounter that can be set as free running. It can be used as a watchdog to reset the device when a problem occurs. It is clocked from the APB clock (PCLK). It has an early warning interrupt capability and the counter can be frozen in debug mode.

### 3.14.6 SysTick timer

This timer is dedicated to real-time operating systems, but could also be used as a standard down counter. It features:

- A 24-bit down counter
- Autoreload capability
- Maskable system interrupt generation when the counter reaches 0
- Programmable clock source (HCLK or HCLK/8)

## 3.15 Real-time clock (RTC) and backup registers

The RTC and the 5 backup registers are supplied through a switch that takes power either on  $V_{DD}$  supply when present or through the  $V_{BAT}$  pin. The backup registers are five 32-bit registers used to store 20 bytes of user application data when  $V_{DD}$  power is not present. They are not reset by a system or power reset, or when the device wakes up from Standby mode.

The RTC is an independent BCD timer/counter. Its main features are the following:

- Calendar with subseconds, seconds, minutes, hours (12 or 24 format), week day, date, month, year, in BCD (binary-coded decimal) format.
- Automatically correction for 28, 29 (leap year), 30, and 31 day of the month.
- Programmable alarm with wake up from Stop and Standby mode capability.
- On-the-fly correction from 1 to 32767 RTC clock pulses. This can be used to synchronize it with a master clock.
- Digital calibration circuit with 1 ppm resolution, to compensate for quartz crystal inaccuracy.
- 2 anti-tamper detection pins with programmable filter. The MCU can be woken up from Stop and Standby modes on tamper event detection.
- Timestamp feature which can be used to save the calendar content. This function can be triggered by an event on the timestamp pin, or by a tamper event. The MCU can be woken up from Stop and Standby modes on timestamp event detection.
- Reference clock detection: a more precise second source clock (50 or 60 Hz) can be used to enhance the calendar precision.

The RTC clock sources can be:

- A 32.768 kHz external crystal
- A resonator or oscillator
- The internal low-power RC oscillator (typical frequency of 40 kHz)
- The high-speed external clock divided by 32

### 3.16 Inter-integrated circuit interfaces (I<sup>2</sup>C)

Up to two I<sup>2</sup>C interfaces (I2C1 and I2C2) can operate in multimaster or slave modes. Both can support Standard mode (up to 100 kbit/s) or Fast mode (up to 400 kbit/s) and I2C1 supports also Fast Mode Plus (up to 1 Mbit/s) with 20 mA output drive.

Both support 7-bit and 10-bit addressing modes, multiple 7-bit slave addresses (2 addresses, 1 with configurable mask). They also include programmable analog and digital noise filters.

**Table 8. Comparison of I2C analog and digital filters**

|                                  | Analog filter                                         | Digital filter                                                                     |
|----------------------------------|-------------------------------------------------------|------------------------------------------------------------------------------------|
| Pulse width of suppressed spikes | ≥ 50 ns                                               | Programmable length from 1 to 15 I2C peripheral clocks                             |
| Benefits                         | Available in Stop mode                                | 1. Extra filtering capability vs. standard requirements.<br>2. Stable length       |
| Drawbacks                        | Variations depending on temperature, voltage, process | Wakeup from Stop on address match is not available when digital filter is enabled. |

In addition, I2C1 provides hardware support for SMBUS 2.0 and PMBUS 1.1: ARP capability, Host notify protocol, hardware CRC (PEC) generation/verification, timeouts verifications and ALERT protocol management. I2C1 also has a clock domain independent

from the CPU clock, allowing the I2C1 to wake up the MCU from Stop mode on address match.

The I2C interfaces can be served by the DMA controller.

Refer to [Table 9](#) for the differences between I2C1 and I2C2.

**Table 9. STM32F051xx I<sup>2</sup>C implementation**

| I2C features <sup>(1)</sup>                                 | I2C1 | I2C2 |
|-------------------------------------------------------------|------|------|
| 7-bit addressing mode                                       | X    | X    |
| 10-bit addressing mode                                      | X    | X    |
| Standard mode (up to 100 kbit/s)                            | X    | X    |
| Fast mode (up to 400 kbit/s)                                | X    | X    |
| Fast Mode Plus with 20mA output drive I/Os (up to 1 Mbit/s) | X    |      |
| Independent clock                                           | X    |      |
| SMBus                                                       | X    |      |
| Wakeup from STOP                                            | X    |      |

1. X = supported.

### 3.17 Universal synchronous/asynchronous receiver transmitters (USART)

The device embeds up to two universal synchronous/asynchronous receiver transmitters (USART1 and USART2), which communicate at speeds of up to 6 Mbit/s.

They provide hardware management of the CTS, RTS and RS485 DE signals, multiprocessor communication mode, master synchronous communication and single-wire half-duplex communication mode. USART1 supports also SmartCard communication (ISO 7816), IrDA SIR ENDEC, LIN Master/Slave capability and auto baud rate feature, and has a clock domain independent from the CPU clock, allowing USART1 to wake up the MCU from Stop mode.

The USART interfaces can be served by the DMA controller.

Refer to [Table 10](#) for the differences between USART1 and USART2.

**Table 10. STM32F051xx USART implementation**

| USART modes/features <sup>(1)</sup>   | USART1 | USART2 |
|---------------------------------------|--------|--------|
| Hardware flow control for modem       | X      | X      |
| Continuous communication using DMA    | X      | X      |
| Multiprocessor communication          | X      | X      |
| Synchronous mode                      | X      | X      |
| Smartcard mode                        | X      |        |
| Single-wire half-duplex communication | X      | X      |



**Table 10. STM32F051xx USART implementation (continued)**

| USART modes/features <sup>(1)</sup>         | USART1 | USART2 |
|---------------------------------------------|--------|--------|
| IrDA SIR ENDEC block                        | X      |        |
| LIN mode                                    | X      |        |
| Dual clock domain and wakeup from Stop mode | X      |        |
| Receiver timeout interrupt                  | X      |        |
| Modbus communication                        | X      |        |
| Auto baud rate detection                    | X      |        |
| Driver Enable                               | X      | X      |

1. X = supported.

### 3.18 Serial peripheral interface (SPI)/Inter-integrated sound interfaces (I<sup>2</sup>S)

Up to two SPIs are able to communicate up to 18 Mbits/s in slave and master modes in full-duplex and half-duplex communication modes. The 3-bit prescaler gives 8 master mode frequencies and the frame size is configurable from 4 bits to 16 bits.

One standard I<sup>2</sup>S interface (multiplexed with SPI1) supporting four different audio standards can operate as master or slave at half-duplex communication mode. It can be configured to transfer 16 and 24 or 32 bits with 16-bit or 32-bit data resolution and synchronized by a specific signal. Audio sampling frequency from 8 kHz up to 192 kHz can be set by an 8-bit programmable linear prescaler. When operating in master mode, it can output a clock for an external audio component at 256 times the sampling frequency.

Refer to [Table 11](#) for the differences between SPI1 and SPI2.

**Table 11. STM32F051xx SPI/I2S implementation**

| SPI features <sup>(1)</sup> | SPI1 | SPI2 |
|-----------------------------|------|------|
| Hardware CRC calculation    | X    | X    |
| Rx/Tx FIFO                  | X    | X    |
| NSS pulse mode              | X    | X    |
| I2S mode                    | X    |      |
| TI mode                     | X    | X    |

1. X = supported.

### 3.19 High-definition multimedia interface (HDMI) - consumer electronics control (CEC)

The device embeds a HDMI-CEC controller that provides hardware support for the Consumer Electronics Control (CEC) protocol (Supplement 1 to the HDMI standard).

This protocol provides high-level control functions between all audiovisual products in an environment. It is specified to operate at low speeds with minimum processing and memory overhead. It has a clock domain independent from the CPU clock, allowing the HDMI\_CEC controller to wakeup the MCU from Stop mode on data reception.

### 3.20 Serial wire debug port (SW-DP)

An ARM SW-DP interface is provided to allow a serial wire debugging tool to be connected to the MCU.

## 4 Pinouts and pin descriptions

Figure 3. LQFP64 64-pin package pinout (top view)

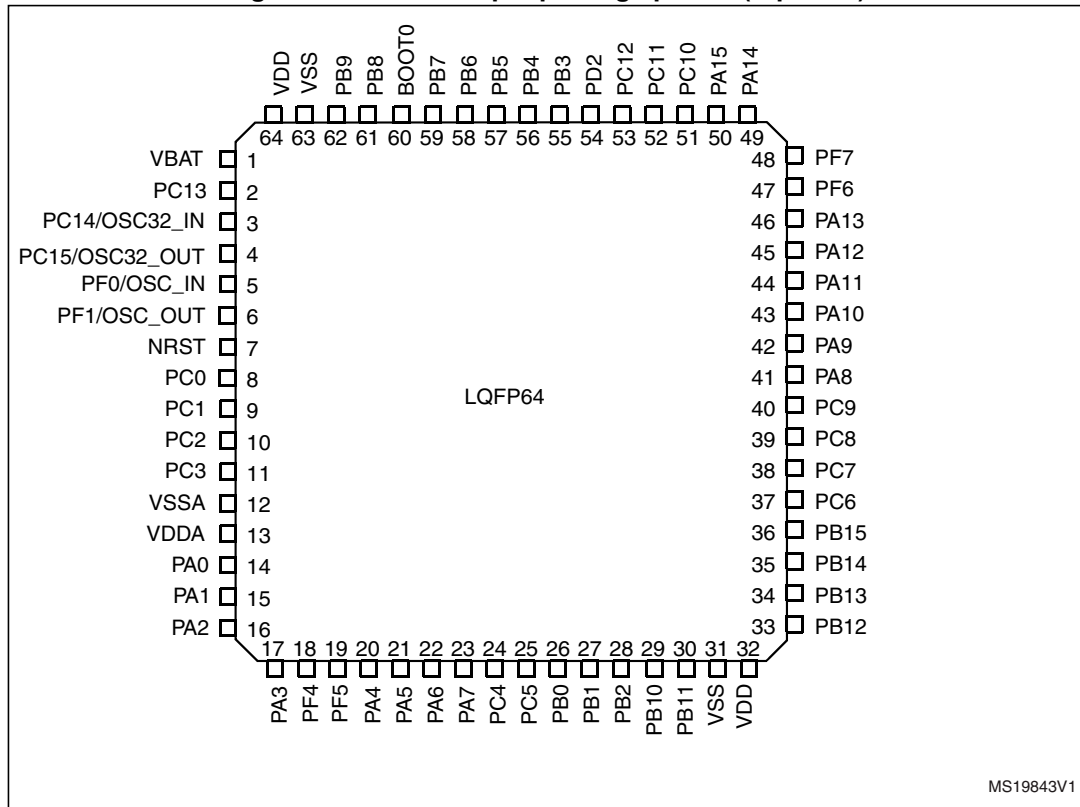


Figure 4. UFBGA64 64-pin package ball-out (top view)

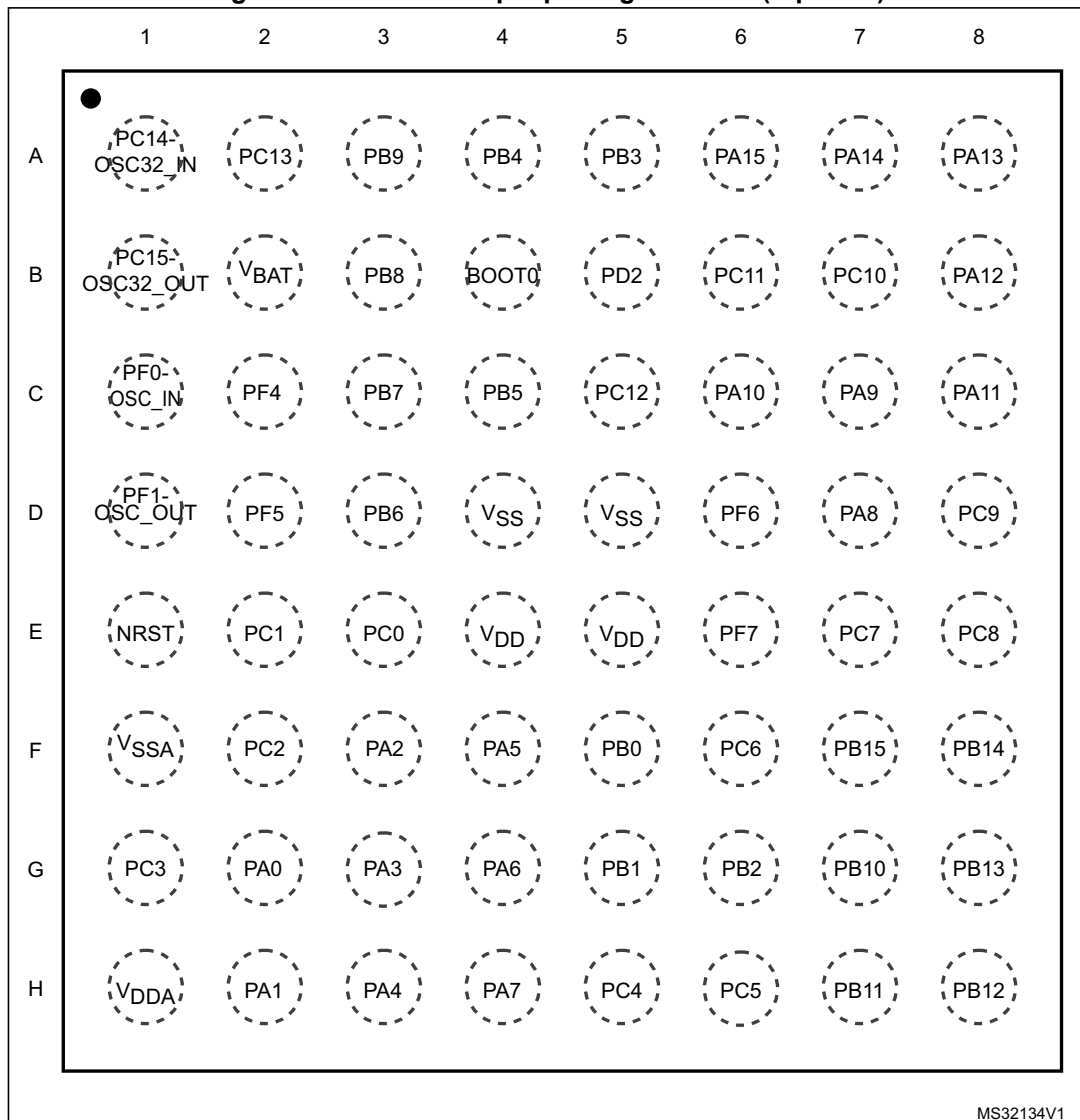


Figure 5. LQFP48 48-pin package pinout (top view)

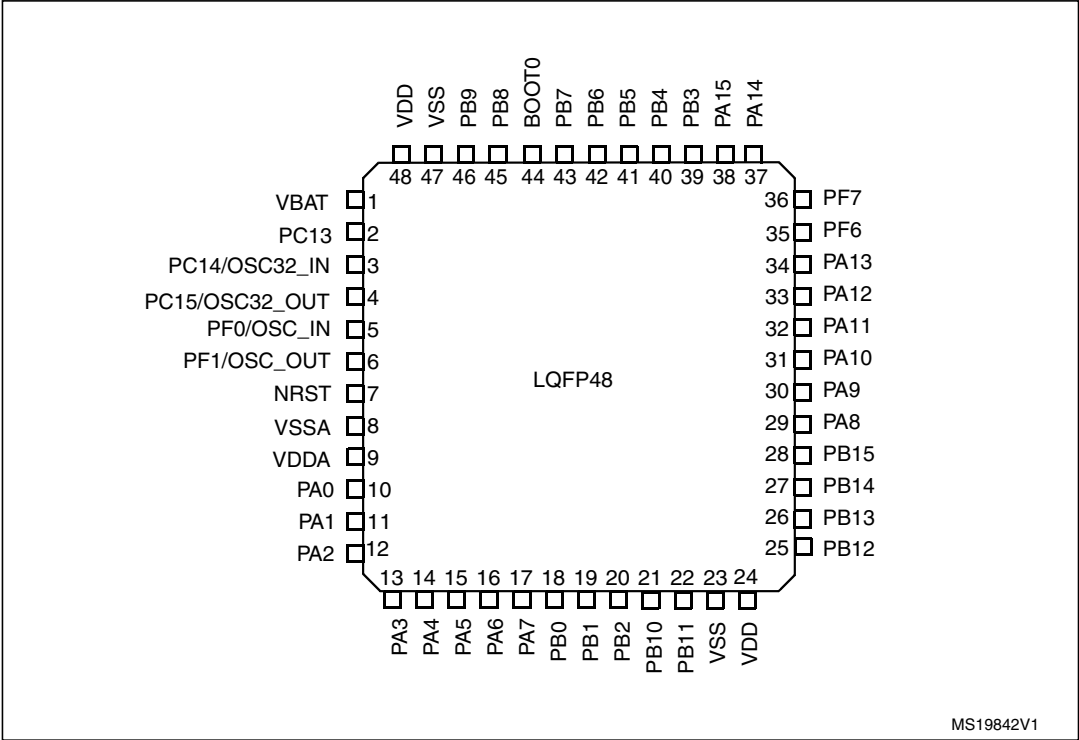


Figure 6. UFQFPN48 48-pin package pinout (top view)

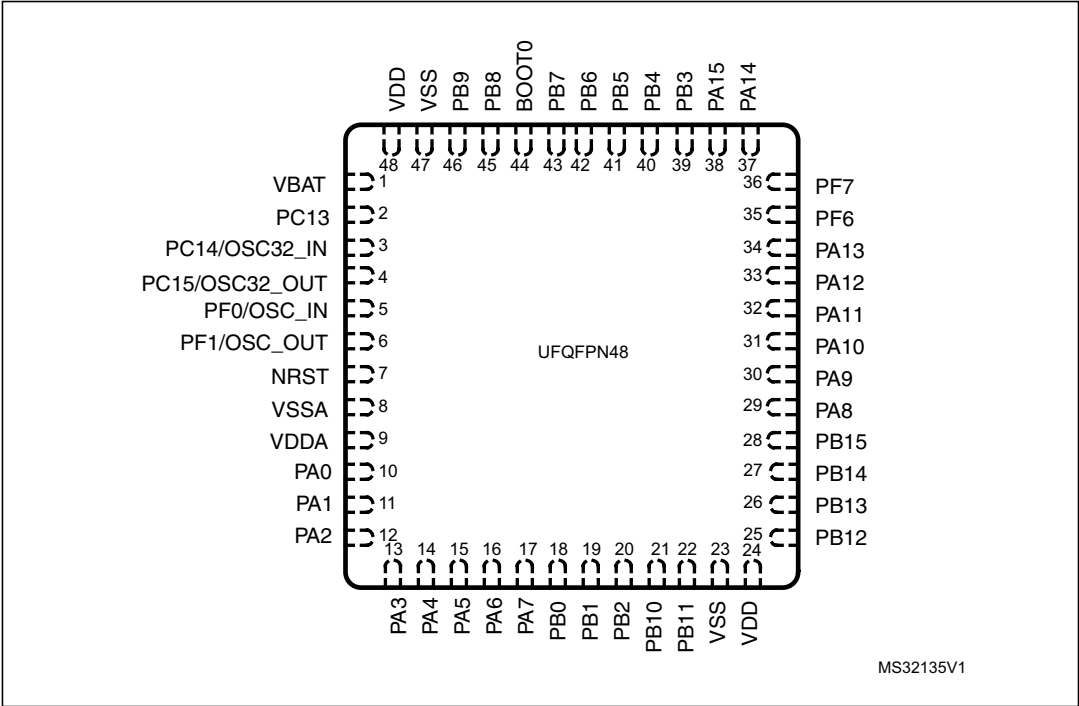


Figure 7. LQFP32 32-pin package pinout (top view)

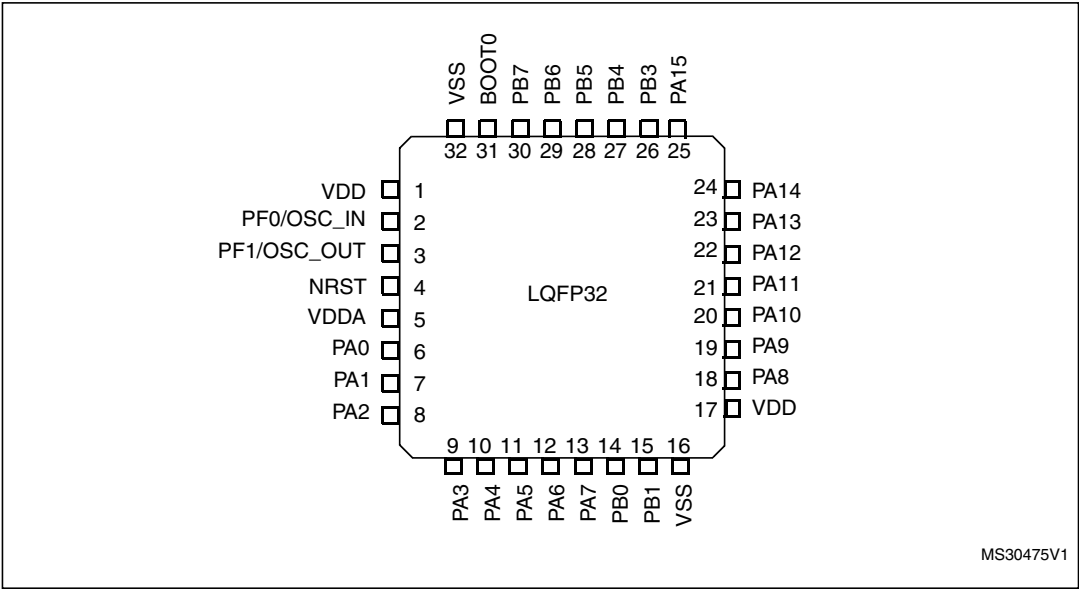


Figure 8. UFQFPN32 32-pin package pinout (top view)

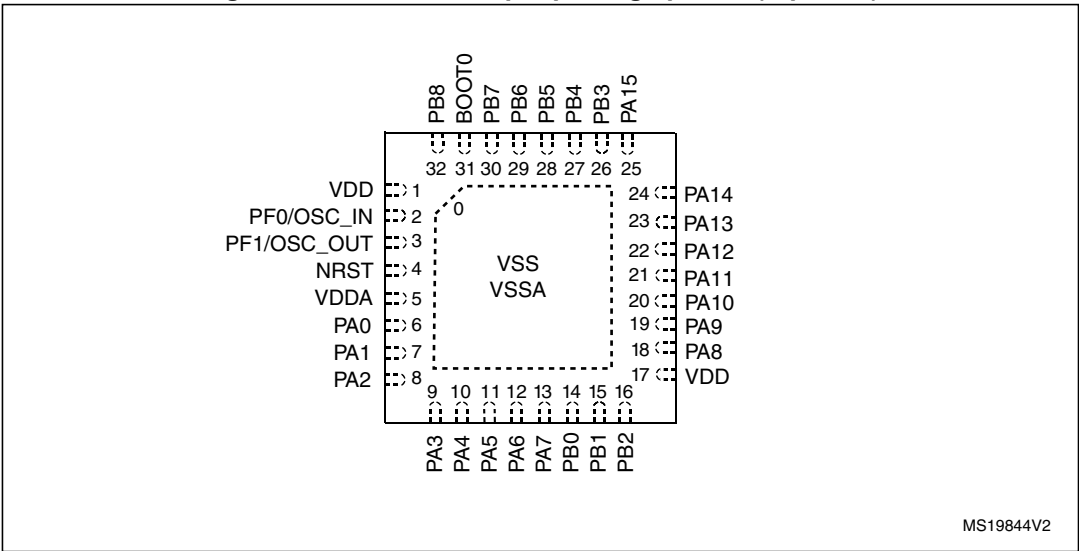


Table 12. Legend/abbreviations used in the pinout table

| Name          |                      | Abbreviation                                                                                                                          | Definition                                                  |
|---------------|----------------------|---------------------------------------------------------------------------------------------------------------------------------------|-------------------------------------------------------------|
| Pin name      |                      | Unless otherwise specified in brackets below the pin name, the pin function during and after reset is the same as the actual pin name |                                                             |
| Pin type      |                      | S                                                                                                                                     | Supply pin                                                  |
|               |                      | I                                                                                                                                     | Input only pin                                              |
|               |                      | I/O                                                                                                                                   | Input / output pin                                          |
| I/O structure |                      | FT                                                                                                                                    | 5 V tolerant I/O                                            |
|               |                      | FTf                                                                                                                                   | 5 V tolerant I/O, FM+ capable                               |
|               |                      | TTa                                                                                                                                   | 3.3 V tolerant I/O directly connected to ADC                |
|               |                      | TC                                                                                                                                    | Standard 3.3 V I/O                                          |
|               |                      | B                                                                                                                                     | Dedicated BOOT0 pin                                         |
|               |                      | RST                                                                                                                                   | Bidirectional reset pin with embedded weak pull-up resistor |
| Notes         |                      | Unless otherwise specified by a note, all I/Os are set as floating inputs during and after reset.                                     |                                                             |
| Pin functions | Alternate functions  | Functions selected through GPIOx_AFR registers                                                                                        |                                                             |
|               | Additional functions | Functions directly selected/enabled through peripheral registers                                                                      |                                                             |

Table 13. Pin definitions

| Pin number |         |                 |        |          | Pin name<br>(function after reset) | Pin type | I/O structure | Notes  | Pin functions       |                                            |
|------------|---------|-----------------|--------|----------|------------------------------------|----------|---------------|--------|---------------------|--------------------------------------------|
| LQFP64     | UFBGA64 | LQFP48/UFQFPN48 | LQFP32 | UFQFPN32 |                                    |          |               |        | Alternate functions | Additional functions                       |
| 1          | B2      | 1               | -      | -        | VBAT                               | S        |               |        | Backup power supply |                                            |
| 2          | A2      | 2               | -      | -        | PC13                               | I/O      | TC            | (1)(2) | -                   | RTC_TAMP1,<br>RTC_TS,<br>RTC_OUT,<br>WKUP2 |
| 3          | A1      | 3               | -      | -        | PC14-OSC32_IN<br>(PC14)            | I/O      | TC            | (1)(2) | -                   | OSC32_IN                                   |
| 4          | B1      | 4               | -      | -        | PC15-OSC32_OUT<br>(PC15)           | I/O      | TC            | (1)(2) | -                   | OSC32_OUT                                  |
| 5          | C1      | 5               | 2      | 2        | PF0-OSC_IN<br>(PF0)                | I/O      | FT            |        | -                   | OSC_IN                                     |
| 6          | D1      | 6               | 3      | 3        | PF1-OSC_OUT<br>(PF1)               | I/O      | FT            |        | -                   | OSC_OUT                                    |

Table 13. Pin definitions (continued)

| Pin number |         |                 |        |          | Pin name<br>(function after<br>reset) | Pin type | I/O structure | Notes | Pin functions                                                     |                                                    |
|------------|---------|-----------------|--------|----------|---------------------------------------|----------|---------------|-------|-------------------------------------------------------------------|----------------------------------------------------|
| LQFP64     | UFBGA64 | LQFP48/UFQFPN48 | LQFP32 | UFQFPN32 |                                       |          |               |       | Alternate functions                                               | Additional functions                               |
| 7          | E1      | 7               | 4      | 4        | NRST                                  | I/O      | RST           |       | Device reset input / internal reset output<br>(active low)        |                                                    |
| 8          | E3      | -               | -      | -        | PC0                                   | I/O      | TTa           |       | EVENTOUT                                                          | ADC_IN10                                           |
| 9          | E2      | -               | -      | -        | PC1                                   | I/O      | TTa           |       | EVENTOUT                                                          | ADC_IN11                                           |
| 10         | F2      | -               | -      | -        | PC2                                   | I/O      | TTa           |       | EVENTOUT                                                          | ADC_IN12                                           |
| 11         | A2      | -               | -      | -        | PC3                                   | I/O      | TTa           |       | EVENTOUT                                                          | ADC_IN13                                           |
| 12         | F1      | 8               | -      | 0        | VSSA                                  | S        |               |       | Analog ground                                                     |                                                    |
| 13         | H1      | 9               | 5      | 5        | VDDA                                  | S        |               |       | Analog power supply                                               |                                                    |
| 14         | G2      | 10              | 6      | 6        | PA0                                   | I/O      | TTa           |       | USART2_CTS,<br>TIM2_CH1_ETR,<br>COMP1_OUT,<br>TSC_G1_IO1          | ADC_IN0,<br>COMP1_INM6,<br>RTC_TAMP2,<br>WKUP1     |
| 15         | H2      | 11              | 7      | 7        | PA1                                   | I/O      | TTa           |       | USART2_RTS,<br>TIM2_CH2,<br>TSC_G1_IO2,<br>EVENTOUT               | ADC_IN1,<br>COMP1_INP                              |
| 16         | F3      | 12              | 8      | 8        | PA2                                   | I/O      | TTa           |       | USART2_TX,<br>TIM2_CH3,<br>TIM15_CH1,<br>COMP2_OUT,<br>TSC_G1_IO3 | ADC_IN2,<br>COMP2_INM6                             |
| 17         | G3      | 13              | 9      | 9        | PA3                                   | I/O      | TTa           |       | USART2_RX,<br>TIM2_CH4,<br>TIM15_CH2,<br>TSC_G1_IO4               | ADC_IN3,<br>COMP2_INP                              |
| 18         | C2      | -               | -      | -        | PF4                                   | I/O      | FT            |       | EVENTOUT                                                          | -                                                  |
| 19         | D2      | -               | -      | -        | PF5                                   | I/O      | FT            |       | EVENTOUT                                                          | -                                                  |
| 20         | H3      | 14              | 10     | 10       | PA4                                   | I/O      | TTa           |       | SPI1_NSS,<br>I2S1_WS,<br>USART2_CK,<br>TIM14_CH1,<br>TSC_G2_IO1   | ADC_IN4,<br>COMP1_INM4,<br>COMP2_INM4,<br>DAC1_OUT |
| 21         | F4      | 15              | 11     | 11       | PA5                                   | I/O      | TTa           |       | SPI1_SCK,<br>I2S1_CK, CEC,<br>TIM2_CH1_ETR,<br>TSC_G2_IO2         | ADC_IN5,<br>COMP1_INM5,<br>COMP2_INM5              |



Table 13. Pin definitions (continued)

| Pin number |         |                 |        |          | Pin name<br>(function after<br>reset) | Pin type | I/O structure | Notes | Pin functions                                                                                                          |                      |
|------------|---------|-----------------|--------|----------|---------------------------------------|----------|---------------|-------|------------------------------------------------------------------------------------------------------------------------|----------------------|
| LQFP64     | UFBGA64 | LQFP48/UFQFPN48 | LQFP32 | UFQFPN32 |                                       |          |               |       | Alternate functions                                                                                                    | Additional functions |
| 22         | G4      | 16              | 12     | 12       | PA6                                   | I/O      | TTa           |       | SPI1_MISO,<br>I2S1_MCK,<br>TIM3_CH1,<br>TIM1_BKIN,<br>TIM16_CH1,<br>COMP1_OUT,<br>TSC_G2_IO3,<br>EVENTOUT              | ADC_IN6              |
| 23         | H4      | 17              | 13     | 13       | PA7                                   | I/O      | TTa           |       | SPI1_MOSI,<br>I2S1_SD,<br>TIM3_CH2,<br>TIM14_CH1,<br>TIM1_CH1N,<br>TIM17_CH1,<br>COMP2_OUT,<br>TSC_G2_IO4,<br>EVENTOUT | ADC_IN7              |
| 24         | H5      | -               | -      | -        | PC4                                   | I/O      | TTa           |       | EVENTOUT                                                                                                               | ADC_IN14             |
| 25         | H6      | -               | -      | -        | PC5                                   | I/O      | TTa           |       | TSC_G3_IO1                                                                                                             | ADC_IN15             |
| 26         | F5      | 18              | 14     | 14       | PB0                                   | I/O      | TTa           |       | TIM3_CH3,<br>TIM1_CH2N,<br>TSC_G3_IO2,<br>EVENTOUT                                                                     | ADC_IN8              |
| 27         | G5      | 19              | 15     | 15       | PB1                                   | I/O      | TTa           |       | TIM3_CH4,<br>TIM14_CH1,<br>TIM1_CH3N,<br>TSC_G3_IO3                                                                    | ADC_IN9              |
| 28         | G6      | 20              | -      | 16       | PB2                                   | I/O      | FT            | (3)   | TSC_G3_IO4                                                                                                             | -                    |
| 29         | G7      | 21              | -      | -        | PB10                                  | I/O      | FT            |       | I2C2_SCL,<br>CEC,<br>TIM2_CH3,<br>TSC_SYNC                                                                             | -                    |
| 30         | H7      | 22              | -      | -        | PB11                                  | I/O      | FT            |       | I2C2_SDA,<br>TIM2_CH4,<br>TSC_G6_IO1,<br>EVENTOUT                                                                      | -                    |
| 31         | D4      | 23              | 16     | 0        | VSS                                   | S        |               |       | Ground                                                                                                                 |                      |
| 32         | E4      | 24              | 17     | 17       | VDD                                   | S        |               |       | Digital power supply                                                                                                   |                      |

Table 13. Pin definitions (continued)

| Pin number |         |                 |        |          | Pin name<br>(function after<br>reset) | Pin type | I/O structure | Notes | Pin functions                                                     |                      |
|------------|---------|-----------------|--------|----------|---------------------------------------|----------|---------------|-------|-------------------------------------------------------------------|----------------------|
| LQFP64     | UFBGA64 | LQFP48/UFQFPN48 | LQFP32 | UFQFPN32 |                                       |          |               |       | Alternate functions                                               | Additional functions |
| 33         | H8      | 25              | -      | -        | PB12                                  | I/O      | FT            |       | SPI2_NSS,<br>TIM1_BKIN,<br>TSC_G6_IO2,<br>EVENTOUT                | -                    |
| 34         | G8      | 26              | -      | -        | PB13                                  | I/O      | FT            |       | SPI2_SCK,<br>TIM1_CH1N,<br>TSC_G6_IO3                             | -                    |
| 35         | F8      | 27              | -      | -        | PB14                                  | I/O      | FT            |       | SPI2_MISO,<br>TIM1_CH2N,<br>TIM15_CH1,<br>TSC_G6_IO4              | -                    |
| 36         | F7      | 28              | -      | -        | PB15                                  | I/O      | FT            |       | SPI2_MOSI,<br>TIM1_CH3N,<br>TIM15_CH1N,<br>TIM15_CH2              | RTC_REFIN            |
| 37         | F6      | -               | -      | -        | PC6                                   | I/O      | FT            |       | TIM3_CH1                                                          | -                    |
| 38         | E7      | -               | -      | -        | PC7                                   | I/O      | FT            |       | TIM3_CH2                                                          | -                    |
| 39         | E8      | -               | -      | -        | PC8                                   | I/O      | FT            |       | TIM3_CH3                                                          | -                    |
| 40         | D8      | -               | -      | -        | PC9                                   | I/O      | FT            |       | TIM3_CH4                                                          | -                    |
| 41         | D7      | 29              | 18     | 18       | PA8                                   | I/O      | FT            |       | USART1_CK,<br>TIM1_CH1,<br>EVENTOUT,<br>MCO                       | -                    |
| 42         | C7      | 30              | 19     | 19       | PA9                                   | I/O      | FT            |       | USART1_TX,<br>TIM1_CH2,<br>TIM15_BKIN,<br>TSC_G4_IO1              | -                    |
| 43         | C6      | 31              | 20     | 20       | PA10                                  | I/O      | FT            |       | USART1_RX,<br>TIM1_CH3,<br>TIM17_BKIN,<br>TSC_G4_IO2              | -                    |
| 44         | C8      | 32              | 21     | 21       | PA11                                  | I/O      | FT            |       | USART1_CTS,<br>TIM1_CH4,<br>COMP1_OUT,<br>TSC_G4_IO3,<br>EVENTOUT | -                    |

Table 13. Pin definitions (continued)

| Pin number |         |                 |        |          | Pin name<br>(function after<br>reset) | Pin type | I/O structure | Notes | Pin functions                                                     |                      |
|------------|---------|-----------------|--------|----------|---------------------------------------|----------|---------------|-------|-------------------------------------------------------------------|----------------------|
| LQFP64     | UFBGA64 | LQFP48/UFQFPN48 | LQFP32 | UFQFPN32 |                                       |          |               |       | Alternate functions                                               | Additional functions |
| 45         | B8      | 33              | 22     | 22       | PA12                                  | I/O      | FT            |       | USART1_RTS,<br>TIM1_ETR,<br>COMP2_OUT,<br>TSC_G4_IO4,<br>EVENTOUT | -                    |
| 46         | A8      | 34              | 23     | 23       | PA13<br>(SWDIO)                       | I/O      | FT            | (4)   | IR_OUT,<br>SWDIO                                                  | -                    |
| 47         | D6      | 35              | -      | -        | PF6                                   | I/O      | FTf           |       | I2C2_SCL                                                          | -                    |
| 48         | E6      | 36              | -      | -        | PF7                                   | I/O      | FTf           |       | I2C2_SDA                                                          | -                    |
| 49         | A7      | 37              | 24     | 24       | PA14<br>(SWCLK)                       | I/O      | FT            | (4)   | USART2_TX,<br>SWCLK                                               | -                    |
| 50         | A6      | 38              | 25     | 25       | PA15                                  | I/O      | FT            |       | SPI1_NSS,<br>I2S1_WS,<br>USART2_RX,<br>TIM2_CH1_ETR,<br>EVENTOUT  | -                    |
| 51         | B7      | -               | -      | -        | PC10                                  | I/O      | FT            |       |                                                                   | -                    |
| 52         | B6      | -               | -      | -        | PC11                                  | I/O      | FT            |       |                                                                   | -                    |
| 53         | C5      | -               | -      | -        | PC12                                  | I/O      | FT            |       |                                                                   | -                    |
| 54         | B5      | -               | -      | -        | PD2                                   | I/O      | FT            |       | TIM3_ETR                                                          | -                    |
| 55         | A5      | 39              | 26     | 26       | PB3                                   | I/O      | FT            |       | SPI1_SCK,<br>I2S1_CK,<br>TIM2_CH2,<br>TSC_G5_IO1,<br>EVENTOUT     | -                    |
| 56         | A4      | 40              | 27     | 27       | PB4                                   | I/O      | FT            |       | SPI1_MISO,<br>I2S1_MCK,<br>TIM3_CH1,<br>TSC_G5_IO2,<br>EVENTOUT   | -                    |
| 57         | C4      | 41              | 28     | 28       | PB5                                   | I/O      | FT            |       | SPI1_MOSI,<br>I2S1_SD,<br>I2C1_SMBA,<br>TIM16_BKIN,<br>TIM3_CH2   | -                    |

Table 13. Pin definitions (continued)

| Pin number |         |                 |        |          | Pin name<br>(function after<br>reset) | Pin type | I/O structure | Notes | Pin functions                                        |                      |
|------------|---------|-----------------|--------|----------|---------------------------------------|----------|---------------|-------|------------------------------------------------------|----------------------|
| LQFP64     | UFBGA64 | LQFP48/UFQFPN48 | LQFP32 | UFQFPN32 |                                       |          |               |       | Alternate functions                                  | Additional functions |
| 58         | D3      | 42              | 29     | 29       | PB6                                   | I/O      | FTf           |       | I2C1_SCL,<br>USART1_TX,<br>TIM16_CH1N,<br>TSC_G5_IO3 | -                    |
| 59         | C3      | 43              | 30     | 30       | PB7                                   | I/O      | FTf           |       | I2C1_SDA,<br>USART1_RX,<br>TIM17_CH1N,<br>TSC_G5_IO4 | -                    |
| 60         | B4      | 44              | 31     | 31       | BOOT0                                 | I        | B             |       | Boot memory selection                                |                      |
| 61         | B3      | 45              | -      | 32       | PB8                                   | I/O      | FTf           | (4)   | I2C1_SCL,<br>CEC,<br>TIM16_CH1,<br>TSC_SYNC          | -                    |
| 62         | A3      | 46              | -      | -        | PB9                                   | I/O      | FTf           |       | I2C1_SDA,<br>IR_OUT,<br>TIM17_CH1,<br>EVENTOUT       | -                    |
| 63         | D5      | 47              | 32     | 0        | VSS                                   | S        |               |       | Ground                                               |                      |
| 64         | E5      | 48              | 1      | 1        | VDD                                   | S        |               |       | Digital power supply                                 |                      |

- PC13, PC14 and PC15 are supplied through the power switch. Since the switch only sinks a limited amount of current (3 mA), the use of GPIOs PC13 to PC15 in output mode is limited:
  - The speed should not exceed 2 MHz with a maximum load of 30 pF.
  - These GPIOs must not be used as current sources (e.g. to drive an LED).
- After the first RTC domain power-up, PC13, PC14 and PC15 operate as GPIOs. Their function then depends on the content of the RTC registers which are not reset by the main reset. For details on how to manage these GPIOs, refer to the RTC domain and RTC register descriptions in the reference manual.
- On the LQFP32 package, PB2 and PB8 should be treated as unconnected pins (even when they are not available on the package, they are not forced to a defined level by hardware).
- After reset, these pins are configured as SWDIO and SWCLK alternate functions, and the internal pull-up on the SWDIO pin and the internal pull-down on the SWCLK pin are activated.

**Table 14. Alternate functions selected through GPIOA\_AFR registers for port A**

| Pin name | AF0                 | AF1        | AF2          | AF3        | AF4       | AF5       | AF6      | AF7       |
|----------|---------------------|------------|--------------|------------|-----------|-----------|----------|-----------|
| PA0      |                     | USART2_CTS | TIM2_CH1_ETR | TSC_G1_IO1 |           |           |          | COMP1_OUT |
| PA1      | EVENTOUT            | USART2_RTS | TIM2_CH2     | TSC_G1_IO2 |           |           |          |           |
| PA2      | TIM15_CH1           | USART2_TX  | TIM2_CH3     | TSC_G1_IO3 |           |           |          | COMP2_OUT |
| PA3      | TIM15_CH2           | USART2_RX  | TIM2_CH4     | TSC_G1_IO4 |           |           |          |           |
| PA4      | SPI1_NSS, I2S1_WS   | USART2_CK  |              | TSC_G2_IO1 | TIM14_CH1 |           |          |           |
| PA5      | SPI1_SCK, I2S1_CK   | CEC        | TIM2_CH1_ETR | TSC_G2_IO2 |           |           |          |           |
| PA6      | SPI1_MISO, I2S1_MCK | TIM3_CH1   | TIM1_BKIN    | TSC_G2_IO3 |           | TIM16_CH1 | EVENTOUT | COMP1_OUT |
| PA7      | SPI1_MOSI, I2S1_SD  | TIM3_CH2   | TIM1_CH1N    | TSC_G2_IO4 | TIM14_CH1 | TIM17_CH1 | EVENTOUT | COMP2_OUT |
| PA8      | MCO                 | USART1_CK  | TIM1_CH1     | EVENTOUT   |           |           |          |           |
| PA9      | TIM15_BKIN          | USART1_TX  | TIM1_CH2     | TSC_G4_IO1 |           |           |          |           |
| PA10     | TIM17_BKIN          | USART1_RX  | TIM1_CH3     | TSC_G4_IO2 |           |           |          |           |
| PA11     | EVENTOUT            | USART1_CTS | TIM1_CH4     | TSC_G4_IO3 |           |           |          | COMP1_OUT |
| PA12     | EVENTOUT            | USART1_RTS | TIM1_ETR     | TSC_G4_IO4 |           |           |          | COMP2_OUT |
| PA13     | SWDIO               | IR_OUT     |              |            |           |           |          |           |
| PA14     | SWCLK               | USART2_TX  |              |            |           |           |          |           |
| PA15     | SPI1_NSS, I2S1_WS   | USART2_RX  | TIM2_CH1_ETR | EVENTOUT   |           |           |          |           |

Table 15. Alternate functions selected through GPIOB\_AFR registers for port B

| Pin name | AF0                 | AF1       | AF2        | AF3        |
|----------|---------------------|-----------|------------|------------|
| PB0      | EVENTOUT            | TIM3_CH3  | TIM1_CH2N  | TSC_G3_IO2 |
| PB1      | TIM14_CH1           | TIM3_CH4  | TIM1_CH3N  | TSC_G3_IO3 |
| PB2      |                     |           |            | TSC_G3_IO4 |
| PB3      | SPI1_SCK, I2S1_CK   | EVENTOUT  | TIM2_CH2   | TSC_G5_IO1 |
| PB4      | SPI1_MISO, I2S1_MCK | TIM3_CH1  | EVENTOUT   | TSC_G5_IO2 |
| PB5      | SPI1_MOSI, I2S1_SD  | TIM3_CH2  | TIM16_BKIN | I2C1_SMBA  |
| PB6      | USART1_TX           | I2C1_SCL  | TIM16_CH1N | TSC_G5_IO3 |
| PB7      | USART1_RX           | I2C1_SDA  | TIM17_CH1N | TSC_G5_IO4 |
| PB8      | CEC                 | I2C1_SCL  | TIM16_CH1  | TSC_SYNC   |
| PB9      | IR_OUT              | I2C1_SDA  | TIM17_CH1  | EVENTOUT   |
| PB10     | CEC                 | I2C2_SCL  | TIM2_CH3   | TSC_SYNC   |
| PB11     | EVENTOUT            | I2C2_SDA  | TIM2_CH4   | TSC_G6_IO1 |
| PB12     | SPI2_NSS            | EVENTOUT  | TIM1_BKIN  | TSC_G6_IO2 |
| PB13     | SPI2_SCK            |           | TIM1_CH1N  | TSC_G6_IO3 |
| PB14     | SPI2_MISO           | TIM15_CH1 | TIM1_CH2N  | TSC_G6_IO4 |
| PB15     | SPI2_MOSI           | TIM15_CH2 | TIM1_CH3N  | TIM15_CH1N |

## 5 Memory mapping

### Figure 9. STM32F051xx memory map

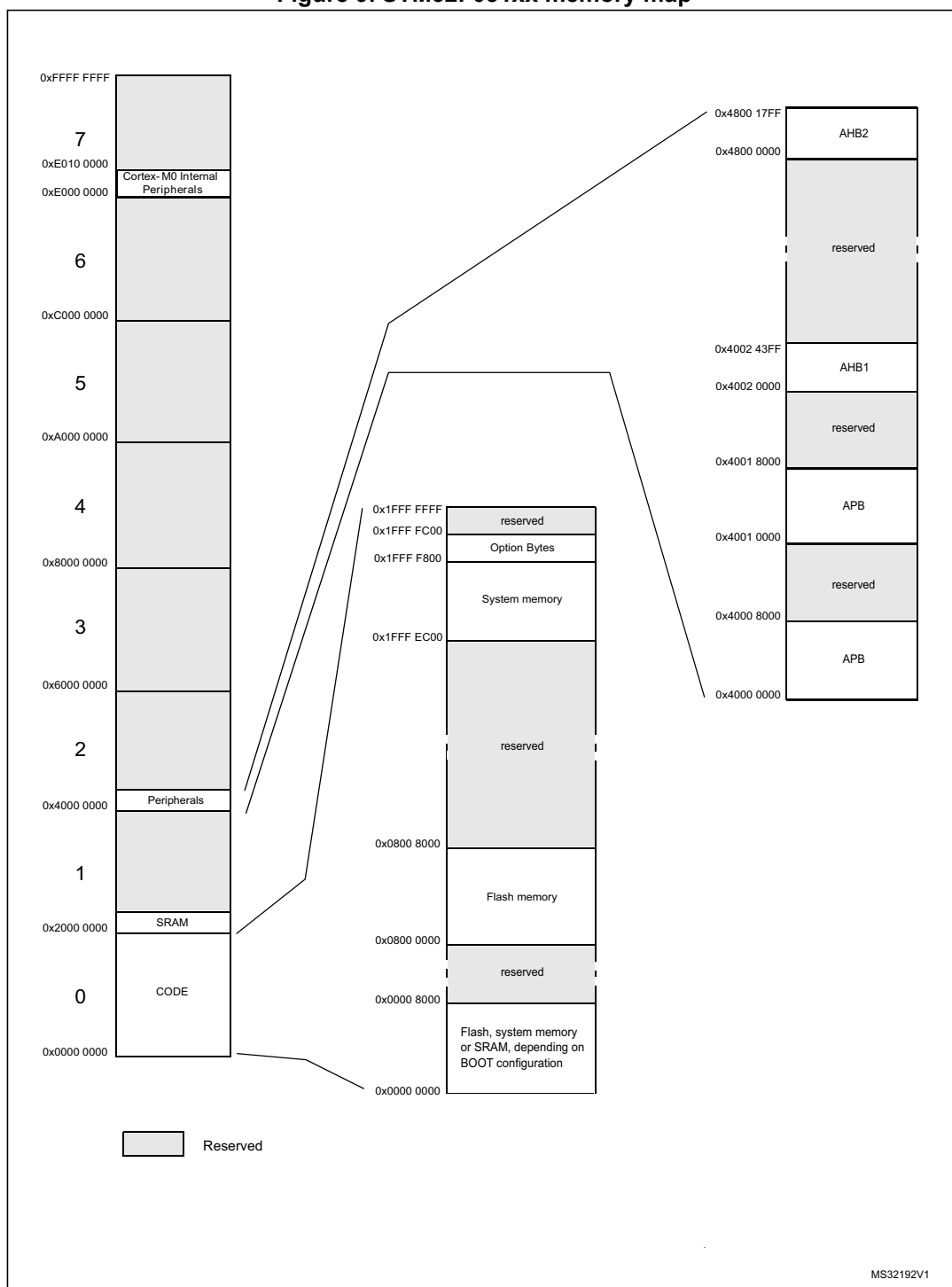


Table 16. STM32F051xx peripheral register boundary addresses

| Bus  | Boundary address          | Size    | Peripheral      |
|------|---------------------------|---------|-----------------|
|      | 0x4800 1800 - 0x5FFF FFFF | ~384 MB | Reserved        |
| AHB2 | 0x4800 1400 - 0x4800 17FF | 1 KB    | GPIOF           |
|      | 0x4800 1000 - 0x4800 13FF | 1 KB    | Reserved        |
|      | 0x4800 0C00 - 0x4800 0FFF | 1 KB    | GPIOD           |
|      | 0x4800 0800 - 0x4800 0BFF | 1 KB    | GPIOC           |
|      | 0x4800 0400 - 0x4800 07FF | 1 KB    | GPIOB           |
|      | 0x4800 0000 - 0x4800 03FF | 1 KB    | GPIOA           |
|      | 0x4002 4400 - 0x47FF FFFF | ~128 MB | Reserved        |
| AHB1 | 0x4002 4000 - 0x4002 43FF | 1 KB    | TSC             |
|      | 0x4002 3400 - 0x4002 3FFF | 3 KB    | Reserved        |
|      | 0x4002 3000 - 0x4002 33FF | 1 KB    | CRC             |
|      | 0x4002 2400 - 0x4002 2FFF | 3 KB    | Reserved        |
|      | 0x4002 2000 - 0x4002 23FF | 1 KB    | FLASH Interface |
|      | 0x4002 1400 - 0x4002 1FFF | 3 KB    | Reserved        |
|      | 0x4002 1000 - 0x4002 13FF | 1 KB    | RCC             |
|      | 0x4002 0400 - 0x4002 0FFF | 3 KB    | Reserved        |
|      | 0x4002 0000 - 0x4002 03FF | 1 KB    | DMA             |
|      | 0x4001 8000 - 0x4001 FFFF | 32 KB   | Reserved        |
| APB  | 0x4001 5C00 - 0x4001 7FFF | 9 KB    | Reserved        |
|      | 0x4001 5800 - 0x4001 5BFF | 1 KB    | DBGMCU          |
|      | 0x4001 4C00 - 0x4001 57FF | 3 KB    | Reserved        |
|      | 0x4001 4800 - 0x4001 4BFF | 1 KB    | TIM17           |
|      | 0x4001 4400 - 0x4001 47FF | 1 KB    | TIM16           |
|      | 0x4001 4000 - 0x4001 43FF | 1 KB    | TIM15           |
|      | 0x4001 3C00 - 0x4001 3FFF | 1 KB    | Reserved        |
|      | 0x4001 3800 - 0x4001 3BFF | 1 KB    | USART1          |
|      | 0x4001 3400 - 0x4001 37FF | 1 KB    | Reserved        |
|      | 0x4001 3000 - 0x4001 33FF | 1 KB    | SPI1/I2S1       |
|      | 0x4001 2C00 - 0x4001 2FFF | 1 KB    | TIM1            |
|      | 0x4001 2800 - 0x4001 2BFF | 1 KB    | Reserved        |
|      | 0x4001 2400 - 0x4001 27FF | 1 KB    | ADC             |
|      | 0x4001 0800 - 0x4001 23FF | 7 KB    | Reserved        |
|      | 0x4001 0400 - 0x4001 07FF | 1 KB    | EXTI            |
|      | 0x4001 0000 - 0x4001 03FF | 1 KB    | SYSCFG + COMP   |
|      | 0x4000 8000 - 0x4000 FFFF | 32 KB   | Reserved        |



Table 16. STM32F051xx peripheral register boundary addresses (continued)

| Bus | Boundary address          | Size | Peripheral |
|-----|---------------------------|------|------------|
| APB | 0x4000 7C00 - 0x4000 7FFF | 1 KB | Reserved   |
|     | 0x4000 7800 - 0x4000 7BFF | 1 KB | CEC        |
|     | 0x4000 7400 - 0x4000 77FF | 1 KB | DAC        |
|     | 0x4000 7000 - 0x4000 73FF | 1 KB | PWR        |
|     | 0x4000 5C00 - 0x4000 6FFF | 5 KB | Reserved   |
|     | 0x4000 5800 - 0x4000 5BFF | 1 KB | I2C2       |
|     | 0x4000 5400 - 0x4000 57FF | 1 KB | I2C1       |
|     | 0x4000 4800 - 0x4000 53FF | 3 KB | Reserved   |
|     | 0x4000 4400 - 0x4000 47FF | 1 KB | USART2     |
|     | 0x4000 3C00 - 0x4000 43FF | 2 KB | Reserved   |
|     | 0x4000 3800 - 0x4000 3BFF | 1 KB | SPI2       |
|     | 0x4000 3400 - 0x4000 37FF | 1 KB | Reserved   |
|     | 0x4000 3000 - 0x4000 33FF | 1 KB | IWDG       |
|     | 0x4000 2C00 - 0x4000 2FFF | 1 KB | WWDG       |
|     | 0x4000 2800 - 0x4000 2BFF | 1 KB | RTC        |
|     | 0x4000 2400 - 0x4000 27FF | 1 KB | Reserved   |
|     | 0x4000 2000 - 0x4000 23FF | 1 KB | TIM14      |
|     | 0x4000 1400 - 0x4000 1FFF | 3 KB | Reserved   |
|     | 0x4000 1000 - 0x4000 13FF | 1 KB | TIM6       |
|     | 0x4000 0800 - 0x4000 0FFF | 2 KB | Reserved   |
|     | 0x4000 0400 - 0x4000 07FF | 1 KB | TIM3       |
|     | 0x4000 0000 - 0x4000 03FF | 1 KB | TIM2       |

# 6 Electrical characteristics

## 6.1 Parameter conditions

Unless otherwise specified, all voltages are referenced to  $V_{SS}$ .

### 6.1.1 Minimum and maximum values

Unless otherwise specified, the minimum and maximum values are guaranteed in the worst conditions of ambient temperature, supply voltage and frequencies by tests in production on 100% of the devices with an ambient temperature at  $T_A = 25\text{ }^{\circ}\text{C}$  and  $T_A = T_{A\text{max}}$  (given by the selected temperature range).

Data based on characterization results, design simulation and/or technology characteristics are indicated in the table footnotes and are not tested in production. Based on characterization, the minimum and maximum values refer to sample tests and represent the mean value plus or minus three times the standard deviation (mean  $\pm 3\sigma$ ).

### 6.1.2 Typical values

Unless otherwise specified, typical data are based on  $T_A = 25\text{ }^{\circ}\text{C}$ ,  $V_{DD} = V_{DDA} = 3.3\text{ V}$ . They are given only as design guidelines and are not tested.

Typical ADC accuracy values are determined by characterization of a batch of samples from a standard diffusion lot over the full temperature range, where 95% of the devices have an error less than or equal to the value indicated (mean  $\pm 2\sigma$ ).

### 6.1.3 Typical curves

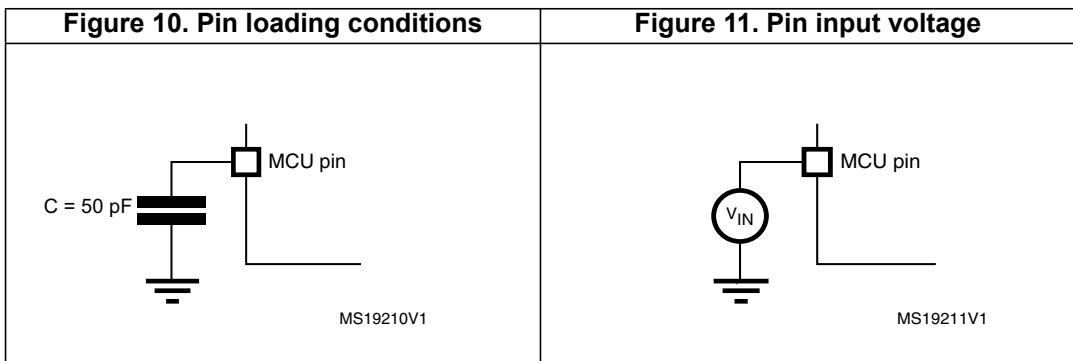
Unless otherwise specified, all typical curves are given only as design guidelines and are not tested.

### 6.1.4 Loading capacitor

The loading conditions used for pin parameter measurement are shown in [Figure 10](#).

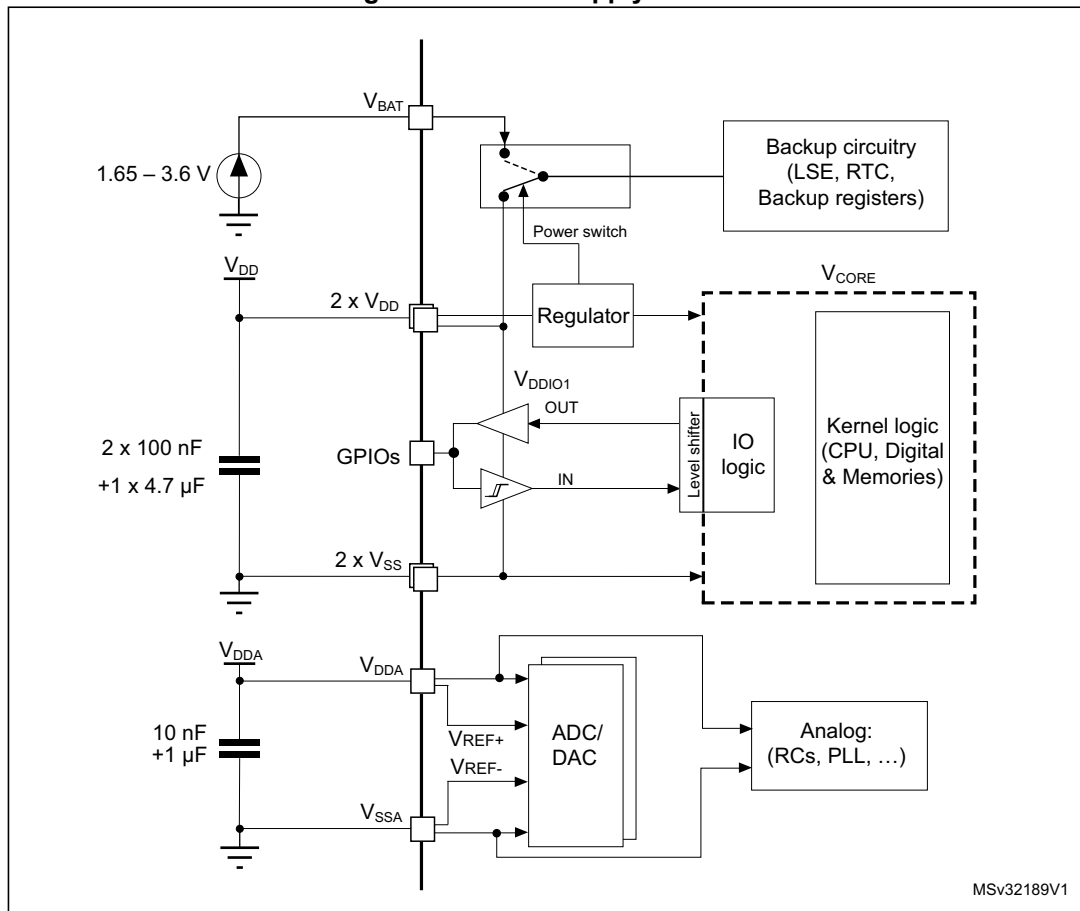
### 6.1.5 Pin input voltage

The input voltage measurement on a pin of the device is described in [Figure 11](#).



### 6.1.6 Power supply scheme

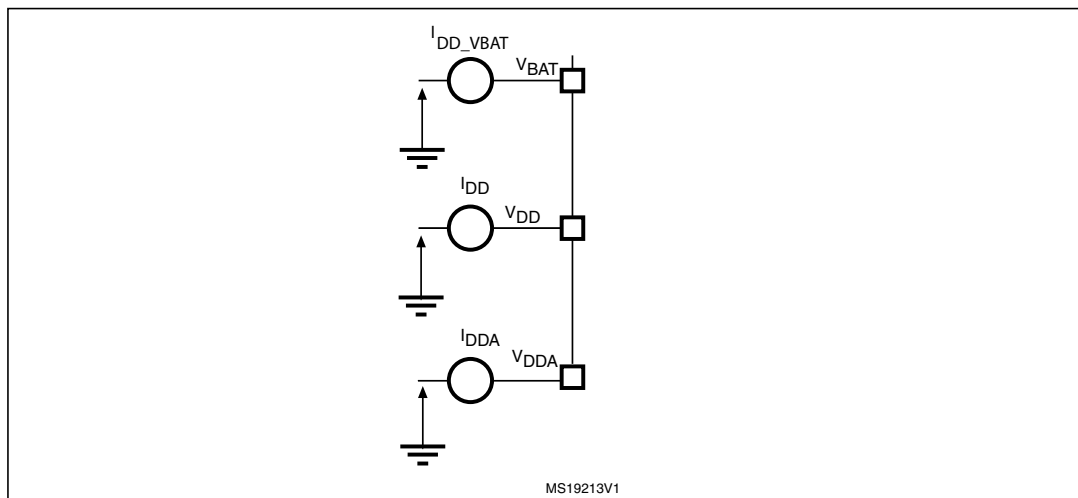
Figure 12. Power supply scheme



**Caution:** Each power supply pair ( $V_{DD}/V_{SS}$ ,  $V_{DDA}/V_{SSA}$  etc.) must be decoupled with filtering ceramic capacitors as shown above. These capacitors must be placed as close as possible to, or below, the appropriate pins on the underside of the PCB to ensure the good functionality of the device.

### 6.1.7 Current consumption measurement

Figure 13. Current consumption measurement scheme



## 6.2 Absolute maximum ratings

Stresses above the absolute maximum ratings listed in [Table 17: Voltage characteristics](#), [Table 18: Current characteristics](#), and [Table 19: Thermal characteristics](#) may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these conditions is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

Table 17. Voltage characteristics<sup>(1)</sup>

| Symbol               | Ratings                                                                      | Min                                                                        | Max               | Unit |
|----------------------|------------------------------------------------------------------------------|----------------------------------------------------------------------------|-------------------|------|
| $V_{DDx}-V_{SS}$     | External main supply voltage (including $V_{DDA}$ , $V_{DD}$ and $V_{BAT}$ ) | -0.3                                                                       | 4.0               | V    |
| $V_{DD}-V_{DDA}$     | Allowed voltage difference for $V_{DD} > V_{DDA}$                            | -                                                                          | 0.4               | V    |
| $V_{IN}^{(2)}$       | Input voltage on FT and FTf pins                                             | $V_{SS} - 0.3$                                                             | $V_{DDIOx} + 4.0$ | V    |
|                      | Input voltage on TTa pins                                                    | $V_{SS} - 0.3$                                                             | 4.0               | V    |
|                      | Input voltage on any other pin                                               | $V_{SS} - 0.3$                                                             | 4.0               | V    |
| $ \Delta V_{DDx} $   | Variations between different $V_{DD}$ power pins                             | -                                                                          | 50                | mV   |
| $ V_{SSx} - V_{SS} $ | Variations between all the different ground pins                             | -                                                                          | 50                | mV   |
| $V_{ESD(HBM)}$       | Electrostatic discharge voltage (human body model)                           | see <a href="#">Section 6.3.12: Electrical sensitivity characteristics</a> |                   |      |

1. All main power ( $V_{DD}$ ,  $V_{DDA}$ ) and ground ( $V_{SS}$ ,  $V_{SSA}$ ) pins must always be connected to the external power supply, in the permitted range.
2.  $V_{IN}$  maximum must always be respected. Refer to [Table 18: Current characteristics](#) for the maximum allowed injected current values.

Table 18. Current characteristics

| Symbol                | Ratings                                                                        | Max.                 | Unit |
|-----------------------|--------------------------------------------------------------------------------|----------------------|------|
| $\Sigma I_{VDD}$      | Total current into sum of all VDD power lines (source) <sup>(1)</sup>          | 120                  | mA   |
| $\Sigma I_{VSS}$      | Total current out of sum of all VSS ground lines (sink) <sup>(1)</sup>         | -120                 |      |
| $I_{VDD(PIN)}$        | Maximum current into each VDD power pin (source) <sup>(1)</sup>                | 100                  |      |
| $I_{VSS(PIN)}$        | Maximum current out of each VSS ground pin (sink) <sup>(1)</sup>               | -100                 |      |
| $I_{IO(PIN)}$         | Output current sunk by any I/O and control pin                                 | 25                   |      |
|                       | Output current source by any I/O and control pin                               | -25                  |      |
| $\Sigma I_{IO(PIN)}$  | Total output current sunk by sum of all IOs and control pins <sup>(2)</sup>    | 80                   |      |
|                       | Total output current sourced by sum of all IOs and control pins <sup>(2)</sup> | -80                  |      |
| $I_{INJ(PIN)}^{(3)}$  | Injected current on FT, FTf and B pins                                         | -5/+0 <sup>(4)</sup> |      |
|                       | Injected current on TC and RST pin                                             | ± 5                  |      |
|                       | Injected current on TTa pins <sup>(5)</sup>                                    | ± 5                  |      |
| $\Sigma I_{INJ(PIN)}$ | Total injected current (sum of all I/O and control pins) <sup>(6)</sup>        | ± 25                 |      |

1. All main power (VDD, VDDA) and ground (VSS, VSSA) pins must always be connected to the external power supply, in the permitted range.
2. This current consumption must be correctly distributed over all I/Os and control pins. The total output current must not be sunk/sourced between two consecutive power supply pins referring to high pin count QFP packages.
3. A positive injection is induced by  $V_{IN} > V_{DDIOx}$  while a negative injection is induced by  $V_{IN} < V_{SS}$ .  $I_{INJ(PIN)}$  must never be exceeded. Refer to [Table 17: Voltage characteristics](#) for the maximum allowed input voltage values.
4. Positive injection is not possible on these I/Os and does not occur for input voltages lower than the specified maximum value.
5. On these I/Os, a positive injection is induced by  $V_{IN} > V_{DDA}$ . Negative injection disturbs the analog performance of the device. See note <sup>(2)</sup> below [Table 55: ADC accuracy](#).
6. When several inputs are submitted to a current injection, the maximum  $\Sigma I_{INJ(PIN)}$  is the absolute sum of the positive and negative injected currents (instantaneous values).

Table 19. Thermal characteristics

| Symbol    | Ratings                      | Value       | Unit |
|-----------|------------------------------|-------------|------|
| $T_{STG}$ | Storage temperature range    | -65 to +150 | °C   |
| $T_J$     | Maximum junction temperature | 150         | °C   |

## 6.3 Operating conditions

### 6.3.1 General operating conditions

Table 20. General operating conditions

| Symbol     | Parameter                                                                                                                               | Conditions                                             | Min  | Max                | Unit               |
|------------|-----------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------------------------|------|--------------------|--------------------|
| $f_{HCLK}$ | Internal AHB clock frequency                                                                                                            |                                                        | 0    | 48                 | MHz                |
| $f_{PCLK}$ | Internal APB clock frequency                                                                                                            |                                                        | 0    | 48                 |                    |
| $V_{DD}$   | Standard operating voltage                                                                                                              |                                                        | 2    | 3.6                | V                  |
| $V_{DDA}$  | Analog operating voltage (ADC and DAC not used)                                                                                         | Must have a potential equal to or higher than $V_{DD}$ | 2    | 3.6                | V                  |
|            | Analog operating voltage (ADC and DAC used)                                                                                             |                                                        | 2.4  | 3.6                |                    |
| $V_{BAT}$  | Backup operating voltage                                                                                                                |                                                        | 1.65 | 3.6                | V                  |
| $V_{IN}$   | I/O input voltage                                                                                                                       | TC and RST I/O                                         | -0.3 | $V_{DDIOx}+0.3$    | V                  |
|            |                                                                                                                                         | TTa I/O                                                | -0.3 | $V_{DDA}+0.3$      |                    |
|            |                                                                                                                                         | FT and FTf I/O                                         | -0.3 | 5.5 <sup>(1)</sup> |                    |
|            |                                                                                                                                         | BOOT0                                                  | 0    | 9.0                |                    |
| $P_D$      | Power dissipation at $T_A = 85\text{ }^{\circ}\text{C}$ for suffix 6 or $T_A = 105\text{ }^{\circ}\text{C}$ for suffix 7 <sup>(2)</sup> | LQFP64                                                 | -    | 444                | mW                 |
|            |                                                                                                                                         | LQFP48                                                 | -    | 364                |                    |
|            |                                                                                                                                         | LQFP32                                                 | -    | 357                |                    |
|            |                                                                                                                                         | UFQFPN32                                               | -    | 526                |                    |
|            |                                                                                                                                         | UFQFPN48                                               | -    | 625                |                    |
|            |                                                                                                                                         | UFBGA64                                                | -    | 308                |                    |
| $T_A$      | Ambient temperature for the suffix 6 version                                                                                            | Maximum power dissipation                              | -40  | 85                 | $^{\circ}\text{C}$ |
|            |                                                                                                                                         | Low power dissipation <sup>(3)</sup>                   | -40  | 105                |                    |
|            | Ambient temperature for the suffix 7 version                                                                                            | Maximum power dissipation                              | -40  | 105                | $^{\circ}\text{C}$ |
|            |                                                                                                                                         | Low power dissipation <sup>(3)</sup>                   | -40  | 125                |                    |
| $T_J$      | Junction temperature range                                                                                                              | Suffix 6 version                                       | -40  | 105                | $^{\circ}\text{C}$ |
|            |                                                                                                                                         | Suffix 7 version                                       | -40  | 125                |                    |

1. To sustain a voltage higher than  $V_{DDIOx}+0.3\text{ V}$ , the internal pull-up/pull-down resistors must be disabled.
2. If  $T_A$  is lower, higher  $P_D$  values are allowed as long as  $T_J$  does not exceed  $T_{Jmax}$ .
3. In low power dissipation state,  $T_A$  can be extended to this range as long as  $T_J$  does not exceed  $T_{Jmax}$  (see [Section 7.2: Thermal characteristics](#)).

### 6.3.2 Operating conditions at power-up / power-down

The parameters given in [Table 21](#) are derived from tests performed under the ambient temperature condition summarized in [Table 20](#).

**Table 21. Operating conditions at power-up / power-down**

| Symbol     | Parameter                | Conditions | Min | Max      | Unit            |
|------------|--------------------------|------------|-----|----------|-----------------|
| $t_{VDD}$  | $V_{DD}$ rise time rate  |            | 0   | $\infty$ | $\mu\text{s/V}$ |
|            | $V_{DD}$ fall time rate  |            | 20  | $\infty$ |                 |
| $t_{VDDA}$ | $V_{DDA}$ rise time rate |            | 0   | $\infty$ |                 |
|            | $V_{DDA}$ fall time rate |            | 20  | $\infty$ |                 |

### 6.3.3 Embedded reset and power control block characteristics

The parameters given in [Table 22](#) are derived from tests performed under the ambient temperature and supply voltage conditions summarized in [Table 20: General operating conditions](#).

**Table 22. Embedded reset and power control block characteristics**

| Symbol               | Parameter                           | Conditions                  | Min                 | Typ  | Max                 | Unit |
|----------------------|-------------------------------------|-----------------------------|---------------------|------|---------------------|------|
| $V_{POR/PDR}^{(1)}$  | Power on/power down reset threshold | Falling edge <sup>(2)</sup> | 1.80                | 1.88 | 1.96 <sup>(3)</sup> | V    |
|                      |                                     | Rising edge                 | 1.84 <sup>(3)</sup> | 1.92 | 2.00                | V    |
| $V_{PDRhyst}$        | PDR hysteresis                      |                             | -                   | 40   | -                   | mV   |
| $t_{RSTTEMPO}^{(4)}$ | Reset temporization                 |                             | 1.50                | 2.50 | 4.50                | ms   |

1. The PDR detector monitors  $V_{DD}$  and also  $V_{DDA}$  (if kept enabled in the option bytes). The POR detector monitors only  $V_{DD}$ .
2. The product behavior is guaranteed by design down to the minimum  $V_{POR/PDR}$  value.
3. Data based on characterization results, not tested in production.
4. Guaranteed by design, not tested in production.

**Table 23. Programmable voltage detector characteristics**

| Symbol     | Parameter       | Conditions   | Min  | Typ  | Max  | Unit |
|------------|-----------------|--------------|------|------|------|------|
| $V_{PVD0}$ | PVD threshold 0 | Rising edge  | 2.1  | 2.18 | 2.26 | V    |
|            |                 | Falling edge | 2    | 2.08 | 2.16 | V    |
| $V_{PVD1}$ | PVD threshold 1 | Rising edge  | 2.19 | 2.28 | 2.37 | V    |
|            |                 | Falling edge | 2.09 | 2.18 | 2.27 | V    |
| $V_{PVD2}$ | PVD threshold 2 | Rising edge  | 2.28 | 2.38 | 2.48 | V    |
|            |                 | Falling edge | 2.18 | 2.28 | 2.38 | V    |
| $V_{PVD3}$ | PVD threshold 3 | Rising edge  | 2.38 | 2.48 | 2.58 | V    |
|            |                 | Falling edge | 2.28 | 2.38 | 2.48 | V    |

Table 23. Programmable voltage detector characteristics (continued)

| Symbol              | Parameter               | Conditions   | Min  | Typ  | Max                 | Unit |
|---------------------|-------------------------|--------------|------|------|---------------------|------|
| $V_{PVD4}$          | PVD threshold 4         | Rising edge  | 2.47 | 2.58 | 2.69                | V    |
|                     |                         | Falling edge | 2.37 | 2.48 | 2.59                | V    |
| $V_{PVD5}$          | PVD threshold 5         | Rising edge  | 2.57 | 2.68 | 2.79                | V    |
|                     |                         | Falling edge | 2.47 | 2.58 | 2.69                | V    |
| $V_{PVD6}$          | PVD threshold 6         | Rising edge  | 2.66 | 2.78 | 2.9                 | V    |
|                     |                         | Falling edge | 2.56 | 2.68 | 2.8                 | V    |
| $V_{PVD7}$          | PVD threshold 7         | Rising edge  | 2.76 | 2.88 | 3                   | V    |
|                     |                         | Falling edge | 2.66 | 2.78 | 2.9                 | V    |
| $V_{PVDhyst}^{(1)}$ | PVD hysteresis          |              | -    | 100  | -                   | mV   |
| $I_{DD(PVD)}$       | PVD current consumption |              | -    | 0.15 | 0.26 <sup>(1)</sup> | μA   |

1. Guaranteed by design, not tested in production.

### 6.3.4 Embedded reference voltage

The parameters given in [Table 24](#) are derived from tests performed under the ambient temperature and supply voltage conditions summarized in [Table 20: General operating conditions](#).

Table 24. Embedded internal reference voltage

| Symbol                 | Parameter                                                     | Conditions                             | Min                 | Typ | Max                 | Unit   |
|------------------------|---------------------------------------------------------------|----------------------------------------|---------------------|-----|---------------------|--------|
| $V_{REFINT}$           | Internal reference voltage                                    | $-40\text{ °C} < T_A < +105\text{ °C}$ | 1.16                | 1.2 | 1.25                | V      |
|                        |                                                               | $-40\text{ °C} < T_A < +85\text{ °C}$  | 1.16                | 1.2 | 1.24 <sup>(1)</sup> | V      |
| $T_{S\_vrefint}^{(2)}$ | ADC sampling time when reading the internal reference voltage |                                        | 17.1 <sup>(3)</sup> | -   | -                   | μs     |
| $\Delta V_{REFINT}$    | Internal reference voltage spread over the temperature range  | $V_{DDA} = 3\text{ V}$                 | -                   | -   | 10 <sup>(3)</sup>   | mV     |
| $T_{Ccoeff}$           | Temperature coefficient                                       |                                        | -                   | -   | 100 <sup>(3)</sup>  | ppm/°C |

1. Data based on characterization results, not tested in production.

2. The shortest sampling time can be determined in the application by multiple iterations.

3. Guaranteed by design, not tested in production.



### 6.3.5 Supply current characteristics

The current consumption is a function of several parameters and factors such as the operating voltage, ambient temperature, I/O pin loading, device software configuration, operating frequencies, I/O pin switching rate, program location in memory and executed binary code.

The current consumption is measured as described in [Figure 13: Current consumption measurement scheme](#).

All Run-mode current consumption measurements given in this section are performed with a reduced code that gives a consumption equivalent to CoreMark code.

#### Typical and maximum current consumption

The MCU is placed under the following conditions:

- All I/O pins are in analog input mode
- All peripherals are disabled except when explicitly mentioned
- The Flash memory access time is adjusted to the  $f_{HCLK}$  frequency:
  - 0 wait state and Prefetch OFF from 0 to 24 MHz
  - 1 wait state and Prefetch ON above 24 MHz
- When the peripherals are enabled  $f_{PCLK} = f_{HCLK}$

The parameters given in [Table 25](#) to [Table 28](#) are derived from tests performed under ambient temperature and supply voltage conditions summarized in [Table 20: General operating conditions](#).

Table 25. Typical and maximum current consumption from the V<sub>DD</sub> supply at V<sub>DD</sub> = 3.6

| Symbol          | Parameter                                                      | Conditions          | f <sub>HCLK</sub> | All peripherals enabled |                                     |       |                     | All peripherals disabled |                                     |       |                     | Unit |
|-----------------|----------------------------------------------------------------|---------------------|-------------------|-------------------------|-------------------------------------|-------|---------------------|--------------------------|-------------------------------------|-------|---------------------|------|
|                 |                                                                |                     |                   | Typ                     | Max @ T <sub>A</sub> <sup>(1)</sup> |       |                     | Typ                      | Max @ T <sub>A</sub> <sup>(1)</sup> |       |                     |      |
|                 |                                                                |                     |                   |                         | 25 °C                               | 85 °C | 105 °C              |                          | 25 °C                               | 85 °C | 105 °C              |      |
| I <sub>DD</sub> | Supply current in Run mode, code executing from Flash          | HSE bypass, PLL on  | 48 MHz            | 22.0                    | 22.8                                | 22.8  | 23.8                | 11.8                     | 12.7                                | 12.7  | 13.3                | mA   |
|                 |                                                                |                     | 32 MHz            | 15.0                    | 15.5                                | 15.5  | 16.0                | 7.6                      | 8.7                                 | 8.7   | 9.0                 |      |
|                 |                                                                |                     | 24 MHz            | 12.2                    | 13.2                                | 13.2  | 13.6                | 7.2                      | 7.9                                 | 7.9   | 8.1                 |      |
|                 |                                                                | HSE bypass, PLL off | 8 MHz             | 4.4                     | 5.2                                 | 5.2   | 5.4                 | 2.7                      | 2.9                                 | 2.9   | 3.0                 |      |
|                 |                                                                |                     | 1 MHz             | 1.0                     | 1.3                                 | 1.3   | 1.4                 | 0.7                      | 0.9                                 | 0.9   | 0.9                 |      |
|                 |                                                                | HSI clock, PLL on   | 48 MHz            | 22.0                    | 22.8                                | 22.8  | 23.8                | 11.8                     | 12.7                                | 12.7  | 13.3                |      |
|                 |                                                                |                     | 32 MHz            | 15.0                    | 15.5                                | 15.5  | 16.0                | 7.6                      | 8.7                                 | 8.7   | 9.0                 |      |
|                 |                                                                |                     | 24 MHz            | 12.2                    | 13.2                                | 13.2  | 13.6                | 7.2                      | 7.9                                 | 7.9   | 8.1                 |      |
|                 |                                                                | HSI clock, PLL off  | 8 MHz             | 4.4                     | 5.2                                 | 5.2   | 5.4                 | 2.7                      | 2.9                                 | 2.9   | 3.0                 |      |
|                 |                                                                |                     |                   |                         |                                     |       |                     |                          |                                     |       |                     |      |
|                 | Supply current in Run mode, code executing from RAM            | HSE bypass, PLL on  | 48 MHz            | 22.2                    | 23.2 <sup>(2)</sup>                 | 23.2  | 24.4 <sup>(2)</sup> | 12.0                     | 12.7 <sup>(2)</sup>                 | 12.7  | 13.3 <sup>(2)</sup> |      |
|                 |                                                                |                     | 32 MHz            | 15.4                    | 16.3                                | 16.3  | 16.8                | 7.8                      | 8.7                                 | 8.7   | 9.0                 |      |
|                 |                                                                |                     | 24 MHz            | 11.2                    | 12.2                                | 12.2  | 12.8                | 6.2                      | 7.9                                 | 7.9   | 8.1                 |      |
|                 |                                                                | HSE bypass, PLL off | 8 MHz             | 4.0                     | 4.5                                 | 4.5   | 4.7                 | 1.9                      | 2.9                                 | 2.9   | 3.0                 |      |
|                 |                                                                |                     | 1 MHz             | 0.6                     | 0.8                                 | 0.8   | 0.9                 | 0.3                      | 0.6                                 | 0.6   | 0.7                 |      |
|                 |                                                                | HSI clock, PLL on   | 48 MHz            | 22.2                    | 23.2                                | 23.2  | 24.4                | 12.0                     | 12.7                                | 12.7  | 13.3                |      |
|                 |                                                                |                     | 32 MHz            | 15.4                    | 16.3                                | 16.3  | 16.8                | 7.8                      | 8.7                                 | 8.7   | 9.0                 |      |
|                 |                                                                |                     | 24 MHz            | 11.2                    | 12.2                                | 12.2  | 12.8                | 6.2                      | 7.9                                 | 7.9   | 8.1                 |      |
|                 |                                                                | HSI clock, PLL off  | 8 MHz             | 4.0                     | 4.5                                 | 4.5   | 4.7                 | 1.9                      | 2.9                                 | 2.9   | 3.0                 |      |
|                 |                                                                |                     |                   |                         |                                     |       |                     |                          |                                     |       |                     |      |
|                 | Supply current in Sleep mode, code executing from Flash or RAM | HSE bypass, PLL on  | 48 MHz            | 14.0                    | 15.3 <sup>(2)</sup>                 | 15.3  | 16.0 <sup>(2)</sup> | 2.8                      | 3.0 <sup>(2)</sup>                  | 3.0   | 3.2 <sup>(2)</sup>  |      |
|                 |                                                                |                     | 32 MHz            | 9.5                     | 10.2                                | 10.2  | 10.7                | 2.0                      | 2.1                                 | 2.1   | 2.3                 |      |
|                 |                                                                |                     | 24 MHz            | 7.3                     | 7.8                                 | 7.8   | 8.3                 | 1.5                      | 1.7                                 | 1.7   | 1.9                 |      |
|                 |                                                                | HSE bypass, PLL off | 8 MHz             | 2.6                     | 2.9                                 | 2.9   | 3.0                 | 0.6                      | 0.8                                 | 0.8   | 0.8                 |      |
|                 |                                                                |                     | 1 MHz             | 0.4                     | 0.6                                 | 0.6   | 0.6                 | 0.2                      | 0.4                                 | 0.4   | 0.4                 |      |
|                 |                                                                | HSI clock, PLL on   | 48 MHz            | 14.0                    | 15.3                                | 15.3  | 16.0                | 3.8                      | 4.0                                 | 4.1   | 4.2                 |      |
|                 |                                                                |                     | 32 MHz            | 9.5                     | 10.2                                | 10.2  | 10.7                | 2.6                      | 2.7                                 | 2.8   | 2.8                 |      |
|                 |                                                                |                     | 24 MHz            | 7.3                     | 7.8                                 | 7.8   | 8.3                 | 2.0                      | 2.1                                 | 2.1   | 2.1                 |      |
|                 |                                                                | HSI clock, PLL off  | 8 MHz             | 2.6                     | 2.9                                 | 2.9   | 3.0                 | 0.6                      | 0.8                                 | 0.8   | 0.8                 |      |
|                 |                                                                |                     |                   |                         |                                     |       |                     |                          |                                     |       |                     |      |

1. Data based on characterization results, not tested in production unless otherwise specified.

2. Data based on characterization results and tested in production (using one common test limit for sum of I<sub>DD</sub> and I<sub>DDA</sub>).

Table 26. Typical and maximum current consumption from the V<sub>DDA</sub> supply

| Symbol           | Parameter                                                             | Conditions<br>(1)   | f <sub>HCLK</sub> | V <sub>DDA</sub> = 2.4 V |                                     |       |                    | V <sub>DDA</sub> = 3.6 V |                                     |       |                    | Unit |
|------------------|-----------------------------------------------------------------------|---------------------|-------------------|--------------------------|-------------------------------------|-------|--------------------|--------------------------|-------------------------------------|-------|--------------------|------|
|                  |                                                                       |                     |                   | Typ                      | Max @ T <sub>A</sub> <sup>(2)</sup> |       |                    | Typ                      | Max @ T <sub>A</sub> <sup>(2)</sup> |       |                    |      |
|                  |                                                                       |                     |                   |                          | 25 °C                               | 85 °C | 105 °C             |                          | 25 °C                               | 85 °C | 105 °C             |      |
| I <sub>DDA</sub> | Supply current in Run or Sleep mode, code executing from Flash or RAM | HSE bypass, PLL on  | 48 MHz            | 150                      | 170 <sup>(3)</sup>                  | 178   | 182 <sup>(3)</sup> | 164                      | 183 <sup>(3)</sup>                  | 195   | 198 <sup>(3)</sup> | μA   |
|                  |                                                                       |                     | 32 MHz            | 104                      | 121                                 | 126   | 128                | 113                      | 129                                 | 135   | 138                |      |
|                  |                                                                       |                     | 24 MHz            | 82                       | 96                                  | 100   | 103                | 88                       | 102                                 | 106   | 108                |      |
|                  |                                                                       | HSE bypass, PLL off | 8 MHz             | 2.0                      | 2.7                                 | 3.1   | 3.3                | 3.5                      | 3.8                                 | 4.1   | 4.4                |      |
|                  |                                                                       |                     | 1 MHz             | 2.0                      | 2.7                                 | 3.1   | 3.3                | 3.5                      | 3.8                                 | 4.1   | 4.4                |      |
|                  |                                                                       | HSI clock, PLL on   | 48 MHz            | 220                      | 240                                 | 248   | 252                | 244                      | 263                                 | 275   | 278                |      |
|                  |                                                                       |                     | 32 MHz            | 174                      | 191                                 | 196   | 198                | 193                      | 209                                 | 215   | 218                |      |
|                  |                                                                       |                     | 24 MHz            | 152                      | 167                                 | 173   | 174                | 168                      | 183                                 | 190   | 192                |      |
|                  |                                                                       | HSI clock, PLL off  | 8 MHz             | 72                       | 79                                  | 82    | 83                 | 83.5                     | 91                                  | 94    | 95                 |      |

1. Current consumption from the V<sub>DDA</sub> supply is independent of whether the digital peripherals are enabled or disabled, being in Run or Sleep mode or executing from Flash or RAM. Furthermore, when the PLL is off, I<sub>DDA</sub> is independent from the frequency.
2. Data based on characterization results, not tested in production unless otherwise specified.
3. Data based on characterization results and tested in production (using one common test limit for sum of I<sub>DD</sub> and I<sub>DDA</sub>).

Table 27. Typical and maximum current consumption in Stop and Standby modes

| Sym-<br>bol      | Para-<br>meter                 | Conditions                                       | Typ @V <sub>DD</sub> (V <sub>DD</sub> = V <sub>DDA</sub> ) |       |       |       |       |       | Max <sup>(1)</sup>        |                           |                            | Unit               |
|------------------|--------------------------------|--------------------------------------------------|------------------------------------------------------------|-------|-------|-------|-------|-------|---------------------------|---------------------------|----------------------------|--------------------|
|                  |                                |                                                  | 2.0 V                                                      | 2.4 V | 2.7 V | 3.0 V | 3.3 V | 3.6 V | T <sub>A</sub> =<br>25 °C | T <sub>A</sub> =<br>85 °C | T <sub>A</sub> =<br>105 °C |                    |
| I <sub>DD</sub>  | Supply current in Stop mode    | Regulator in run mode, all oscillators OFF       | 15                                                         | 15.1  | 15.25 | 15.45 | 15.7  | 16    | 22 <sup>(2)</sup>         | 48                        | 64 <sup>(2)</sup>          | μA                 |
|                  |                                | Regulator in low-power mode, all oscillators OFF | 3.15                                                       | 3.25  | 3.35  | 3.45  | 3.7   | 4     | (2)                       | 32                        | 45 <sup>(2)</sup>          |                    |
|                  | Supply current in Standby mode | LSI ON and IWDG ON                               | 0.8                                                        | 0.95  | 1.05  | 1.2   | 1.35  | 1.5   | -                         | -                         | -                          |                    |
|                  |                                | LSI OFF and IWDG OFF                             | 0.65                                                       | 0.75  | 0.85  | 0.95  | 1.1   | 1.3   | 2 <sup>(2)</sup>          | 2.5                       | 3 <sup>(2)</sup>           |                    |
| I <sub>DDA</sub> | Supply current in Stop mode    | V <sub>DDA</sub> monitoring ON                   | Regulator in run mode, all oscillators OFF                 | 1.85  | 2     | 2.15  | 2.3   | 2.45  | 2.6                       | 3.5 <sup>(2)</sup>        | 3.5                        | 4.5 <sup>(2)</sup> |
|                  |                                |                                                  | Regulator in low-power mode, all oscillators OFF           | 1.85  | 2     | 2.15  | 2.3   | 2.45  | 2.6                       | 3.5 <sup>(2)</sup>        | 3.5                        | 4.5 <sup>(2)</sup> |
|                  | Supply current in Standby mode | V <sub>DDA</sub> monitoring ON                   | LSI ON and IWDG ON                                         | 2.25  | 2.5   | 2.65  | 2.85  | 3.05  | 3.3                       | -                         | -                          | -                  |
|                  |                                |                                                  | LSI OFF and IWDG OFF                                       | 1.75  | 1.9   | 2     | 2.15  | 2.3   | 2.5                       | 3.5 <sup>(2)</sup>        | 3.5                        | 4.5 <sup>(2)</sup> |
|                  | Supply current in Stop mode    | V <sub>DDA</sub> monitoring OFF                  | Regulator in run mode, all oscillators OFF                 | 1.11  | 1.15  | 1.18  | 1.22  | 1.27  | 1.35                      | -                         | -                          | -                  |
|                  |                                |                                                  | Regulator in low-power mode, all oscillators OFF           | 1.11  | 1.15  | 1.18  | 1.22  | 1.27  | 1.35                      | -                         | -                          | -                  |
|                  | Supply current in Standby mode | V <sub>DDA</sub> monitoring OFF                  | LSI ON and IWDG ON                                         | 1.5   | 1.58  | 1.65  | 1.78  | 1.91  | 2.04                      | -                         | -                          | -                  |
|                  |                                |                                                  | LSI OFF and IWDG OFF                                       | 1     | 1.02  | 1.05  | 1.05  | 1.15  | 1.22                      | -                         | -                          | -                  |

1. Data based on characterization results, not tested in production unless otherwise specified.

2. Data based on characterization results and tested in production (using one common test limit for sum of I<sub>DD</sub> and I<sub>DDA</sub>).

Table 28. Typical and maximum current consumption from the V<sub>BAT</sub> supply

| Symbol               | Parameter                 | Conditions                                                              | Typ @ V <sub>BAT</sub> |         |         |         |         |         | Max <sup>(1)</sup>     |                        |                         | Unit |
|----------------------|---------------------------|-------------------------------------------------------------------------|------------------------|---------|---------|---------|---------|---------|------------------------|------------------------|-------------------------|------|
|                      |                           |                                                                         | = 1.65 V               | = 1.8 V | = 2.4 V | = 2.7 V | = 3.3 V | = 3.6 V | T <sub>A</sub> = 25 °C | T <sub>A</sub> = 85 °C | T <sub>A</sub> = 105 °C |      |
| I <sub>DD-VBAT</sub> | RTC domain supply current | LSE & RTC ON; "Xtal mode": lower driving capability; LSEDRV[1:0] = '00' | 0.41                   | 0.43    | 0.53    | 0.58    | 0.71    | 0.80    | 0.85                   | 1.1                    | 1.5                     | μA   |
|                      |                           | LSE & RTC ON; "Xtal mode" higher driving capability; LSEDRV[1:0] = '11' | 0.71                   | 0.75    | 0.85    | 0.91    | 1.06    | 1.16    | 1.25                   | 1.55                   | 2                       |      |

1. Data based on characterization results, not tested in production.

### Typical current consumption

The MCU is placed under the following conditions:

- V<sub>DD</sub>=V<sub>DDA</sub>=3.3 V
- All I/O pins are in analog input configuration
- The Flash access time is adjusted to f<sub>HCLK</sub> frequency:
  - 0 wait state and Prefetch OFF from 0 to 24 MHz
  - 1 wait state and Prefetch ON above 24 MHz
- When the peripherals are enabled, f<sub>PCLK</sub> = f<sub>HCLK</sub>
- PLL is used for frequencies greater than 8 MHz
- AHB prescaler of 2, 4, 8 and 16 is used for the frequencies 4 MHz, 2 MHz, 1 MHz and 500 kHz respectively

**Table 29. Typical current consumption in Run mode, code with data processing running from Flash**

| Symbol           | Parameter                                               | Conditions                                                      | f <sub>HCLK</sub> | Typ                 |                      | Unit |
|------------------|---------------------------------------------------------|-----------------------------------------------------------------|-------------------|---------------------|----------------------|------|
|                  |                                                         |                                                                 |                   | Peripherals enabled | Peripherals disabled |      |
| I <sub>DD</sub>  | Supply current in Run mode from V <sub>DD</sub> supply  | Running from HSE crystal clock 8 MHz, code executing from Flash | 48 MHz            | 23.3                | 11.5                 | mA   |
|                  |                                                         |                                                                 | 36 MHz            | 17.6                | 9.0                  |      |
|                  |                                                         |                                                                 | 32 MHz            | 15.9                | 8.0                  |      |
|                  |                                                         |                                                                 | 24 MHz            | 12.4                | 7.5                  |      |
|                  |                                                         |                                                                 | 16 MHz            | 8.5                 | 5.2                  |      |
|                  |                                                         |                                                                 | 8 MHz             | 4.5                 | 3.0                  |      |
|                  |                                                         |                                                                 | 4 MHz             | 2.8                 | 1.9                  |      |
|                  |                                                         |                                                                 | 2 MHz             | 1.7                 | 1.3                  |      |
|                  |                                                         |                                                                 | 1 MHz             | 1.3                 | 1.0                  |      |
|                  |                                                         |                                                                 | 500 kHz           | 1.0                 | 0.9                  |      |
|                  |                                                         |                                                                 |                   |                     |                      |      |
| I <sub>DDA</sub> | Supply current in Run mode from V <sub>DDA</sub> supply | Running from HSE crystal clock 8 MHz, code executing from Flash | 48 MHz            | 158                 | 158                  | μA   |
|                  |                                                         |                                                                 | 36 MHz            | 120                 | 120                  |      |
|                  |                                                         |                                                                 | 32 MHz            | 108                 | 108                  |      |
|                  |                                                         |                                                                 | 24 MHz            | 83                  | 83                   |      |
|                  |                                                         |                                                                 | 16 MHz            | 60                  | 60                   |      |
|                  |                                                         |                                                                 | 8 MHz             | 2.43                | 2.43                 |      |
|                  |                                                         |                                                                 | 4 MHz             | 2.43                | 2.43                 |      |
|                  |                                                         |                                                                 | 2 MHz             | 2.43                | 2.43                 |      |
|                  |                                                         |                                                                 | 1 MHz             | 2.43                | 2.43                 |      |
|                  |                                                         |                                                                 | 500 kHz           | 2.43                | 2.43                 |      |

Table 30. Typical current consumption in Sleep mode, code running from Flash or RAM

| Symbol           | Parameter                                                 | Conditions                                                             | f <sub>HCLK</sub> | Typ                 |                      | Unit |
|------------------|-----------------------------------------------------------|------------------------------------------------------------------------|-------------------|---------------------|----------------------|------|
|                  |                                                           |                                                                        |                   | Peripherals enabled | Peripherals disabled |      |
| I <sub>DD</sub>  | Supply current in Sleep mode from V <sub>DD</sub> supply  | Running from HSE crystal clock 8 MHz, code executing from Flash or RAM | 48 MHz            | 13.9                | 2.98                 | mA   |
|                  |                                                           |                                                                        | 36 MHz            | 10.55               | 2.84                 |      |
|                  |                                                           |                                                                        | 32 MHz            | 9.6                 | 2.6                  |      |
|                  |                                                           |                                                                        | 24 MHz            | 7.23                | 2.09                 |      |
|                  |                                                           |                                                                        | 16 MHz            | 5.01                | 1.58                 |      |
|                  |                                                           |                                                                        | 8 MHz             |                     | 0.99                 |      |
|                  |                                                           |                                                                        | 4 MHz             | 1.81                | 0.85                 |      |
|                  |                                                           |                                                                        | 2 MHz             | 1.27                | 0.77                 |      |
|                  |                                                           |                                                                        | 1 MHz             | 1.03                | 0.73                 |      |
|                  |                                                           |                                                                        | 500 kHz           | 0.9                 | 0.71                 |      |
|                  |                                                           |                                                                        | 125 kHz           | 0.78                | 0.69                 |      |
| I <sub>DDA</sub> | Supply current in Sleep mode from V <sub>DDA</sub> supply | Running from HSE crystal clock 8 MHz, code executing from Flash or RAM | 48 MHz            | 158                 | 157                  | μA   |
|                  |                                                           |                                                                        | 36 MHz            | 119                 | 119                  |      |
|                  |                                                           |                                                                        | 32 MHz            | 108                 | 107                  |      |
|                  |                                                           |                                                                        | 24 MHz            | 83                  | 83                   |      |
|                  |                                                           |                                                                        | 16 MHz            | 60                  | 60                   |      |
|                  |                                                           |                                                                        | 8 MHz             | 2.36                | 2.38                 |      |
|                  |                                                           |                                                                        | 4 MHz             | 2.36                | 2.38                 |      |
|                  |                                                           |                                                                        | 2 MHz             | 2.36                | 2.38                 |      |
|                  |                                                           |                                                                        | 1 MHz             | 2.36                | 2.38                 |      |
|                  |                                                           |                                                                        | 500 kHz           | 2.36                | 2.38                 |      |
|                  |                                                           |                                                                        | 125 kHz           | 2.36                | 2.38                 |      |

### I/O system current consumption

The current consumption of the I/O system has two components: static and dynamic.

#### I/O static current consumption

All the I/Os used as inputs with pull-up generate current consumption when the pin is externally held low. The value of this current consumption can be simply computed by using the pull-up/pull-down resistors values given in [Table 49: I/O static characteristics](#).

For the output pins, any external pull-down or external load must also be considered to estimate the current consumption.

Additional I/O current consumption is due to I/Os configured as inputs if an intermediate voltage level is externally applied. This current consumption is caused by the input Schmitt trigger circuits used to discriminate the input value. Unless this specific configuration is required by the application, this supply current consumption can be avoided by configuring these I/Os in analog mode. This is notably the case of ADC input pins which should be configured as analog inputs.

**Caution:** Any floating input pin can also settle to an intermediate voltage level or switch inadvertently, as a result of external electromagnetic noise. To avoid current consumption related to floating pins, they must either be configured in analog mode, or forced internally to a definite digital value. This can be done either by using pull-up/down resistors or by configuring the pins in output mode.

#### I/O dynamic current consumption

In addition to the internal peripheral current consumption measured previously (see [Table 32: Peripheral current consumption](#)), the I/Os used by an application also contribute to the current consumption. When an I/O pin switches, it uses the current from the I/O supply voltage to supply the I/O pin circuitry and to charge/discharge the capacitive load (internal or external) connected to the pin:

$$I_{SW} = V_{DDIOx} \times f_{SW} \times C$$

where

$I_{SW}$  is the current sunk by a switching I/O to charge/discharge the capacitive load

$V_{DDIOx}$  is the I/O supply voltage

$f_{SW}$  is the I/O switching frequency

$C$  is the total capacitance seen by the I/O pin:  $C = C_{INT} + C_{EXT} + C_S$

$C_S$  is the PCB board capacitance including the pad pin.

The test pin is configured in push-pull output mode and is toggled by software at a fixed frequency.



Table 31. Switching output I/O current consumption

| Symbol          | Parameter               | Conditions <sup>(1)</sup>                                                                                                                  | I/O toggling frequency (f <sub>SW</sub> ) | Typ   | Unit |
|-----------------|-------------------------|--------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------------------|-------|------|
| I <sub>SW</sub> | I/O current consumption | V <sub>DDIOx</sub> = 3.3 V<br>C = C <sub>INT</sub>                                                                                         | 4 MHz                                     | 0.07  | mA   |
|                 |                         |                                                                                                                                            | 8 MHz                                     | 0.15  |      |
|                 |                         |                                                                                                                                            | 16 MHz                                    | 0.31  |      |
|                 |                         |                                                                                                                                            | 24 MHz                                    | 0.53  |      |
|                 |                         |                                                                                                                                            | 48 MHz                                    | 0.92  |      |
|                 |                         | V <sub>DDIOx</sub> = 3.3 V<br>C <sub>EXT</sub> = 0 pF<br>C = C <sub>INT</sub> + C <sub>EXT</sub> + C <sub>S</sub>                          | 4 MHz                                     | 0.18  |      |
|                 |                         |                                                                                                                                            | 8 MHz                                     | 0.37  |      |
|                 |                         |                                                                                                                                            | 16 MHz                                    | 0.76  |      |
|                 |                         |                                                                                                                                            | 24 MHz                                    | 1.39  |      |
|                 |                         |                                                                                                                                            | 48 MHz                                    | 2.188 |      |
|                 |                         | V <sub>DDIOx</sub> = 3.3 V<br>C <sub>EXT</sub> = 10 pF<br>C = C <sub>INT</sub> + C <sub>EXT</sub> + C <sub>S</sub>                         | 4 MHz                                     | 0.32  |      |
|                 |                         |                                                                                                                                            | 8 MHz                                     | 0.64  |      |
|                 |                         |                                                                                                                                            | 16 MHz                                    | 1.25  |      |
|                 |                         |                                                                                                                                            | 24 MHz                                    | 2.23  |      |
|                 |                         |                                                                                                                                            | 48 MHz                                    | 4.442 |      |
|                 |                         | V <sub>DDIOx</sub> = 3.3 V<br>C <sub>EXT</sub> = 22 pF<br>C = C <sub>INT</sub> + C <sub>EXT</sub> + C <sub>S</sub>                         | 4 MHz                                     | 0.49  |      |
|                 |                         |                                                                                                                                            | 8 MHz                                     | 0.94  |      |
|                 |                         |                                                                                                                                            | 16 MHz                                    | 2.38  |      |
|                 |                         |                                                                                                                                            | 24 MHz                                    | 3.99  |      |
|                 |                         | V <sub>DDIOx</sub> = 3.3 V<br>C <sub>EXT</sub> = 33 pF<br>C = C <sub>INT</sub> + C <sub>EXT</sub> + C <sub>S</sub>                         | 4 MHz                                     | 0.64  |      |
|                 |                         |                                                                                                                                            | 8 MHz                                     | 1.25  |      |
|                 |                         |                                                                                                                                            | 16 MHz                                    | 3.24  |      |
|                 |                         |                                                                                                                                            | 24 MHz                                    | 5.02  |      |
|                 |                         | V <sub>DDIOx</sub> = 3.3 V<br>C <sub>EXT</sub> = 47 pF<br>C = C <sub>INT</sub> + C <sub>EXT</sub> + C <sub>S</sub><br>C = C <sub>int</sub> | 4 MHz                                     | 0.81  |      |
|                 |                         |                                                                                                                                            | 8 MHz                                     | 1.7   |      |
|                 |                         |                                                                                                                                            | 16 MHz                                    | 3.67  |      |
|                 |                         |                                                                                                                                            |                                           |       |      |
|                 |                         | V <sub>DDIOx</sub> = 2.4 V<br>C <sub>EXT</sub> = 47 pF<br>C = C <sub>INT</sub> + C <sub>EXT</sub> + C <sub>S</sub><br>C = C <sub>int</sub> | 4 MHz                                     | 0.66  |      |
|                 |                         |                                                                                                                                            | 8 MHz                                     | 1.43  |      |
|                 |                         |                                                                                                                                            | 16 MHz                                    | 2.45  |      |
|                 |                         |                                                                                                                                            | 24 MHz                                    | 4.97  |      |

1. C<sub>S</sub> = 7 pF (estimated value).

### On-chip peripheral current consumption

The current consumption of the on-chip peripherals is given in [Table 32](#). The MCU is placed under the following conditions:

- All I/O pins are in input mode with a static value at  $V_{DD}$  or  $V_{SS}$  (no load)
- All peripherals are disabled unless otherwise mentioned
- The given value is calculated by measuring the current consumption
  - with all peripherals clocked off
  - with only one peripheral clocked on
- Ambient operating temperature and supply voltage conditions summarized in [Table 17: Voltage characteristics](#)
- The peripheral clock used is 48 MHz.

Table 32. Peripheral current consumption

| Peripheral         | Typical consumption at 25 °C |                         | Unit |
|--------------------|------------------------------|-------------------------|------|
|                    | I <sub>DD</sub>              | I <sub>DDA</sub>        |      |
| ADC <sup>(1)</sup> | 0.53                         | 0.964                   | mA   |
| CEC                | 0.24                         | -                       |      |
| CRC                | 0.10                         | -                       |      |
| DAC <sup>(2)</sup> | 0.27                         | 0.408                   |      |
| DBGMCU             | 0.18                         | -                       |      |
| DMA                | 0.35                         | -                       |      |
| GPIOA              | 0.48                         | -                       |      |
| GPIOB              | 0.58                         | -                       |      |
| GPIOC              | 0.12                         | -                       |      |
| GPIOD              | 0.04                         | -                       |      |
| GPIOF              | 0.06                         | -                       |      |
| I2C1               | 0.43                         | -                       |      |
| I2C2               | 0.42                         | -                       |      |
| PWR                | 0.22                         | -                       |      |
| SPI1/I2S1          | 0.63                         | -                       |      |
| SPI2               | 0.53                         | -                       |      |
| SYSCFG & COMP      | 0.28                         | See note <sup>(3)</sup> |      |
| TIM1               | 1.01                         | -                       |      |
| TIM2               | 1.00                         | -                       |      |
| TIM3               | 0.78                         | -                       |      |
| TIM6               | 0.32                         | -                       |      |
| TIM14              | 0.45                         | -                       |      |
| TIM15              | 0.66                         | -                       |      |
| TIM16              | 0.57                         | -                       |      |
| TIM17              | 0.59                         | -                       |      |
| TSC                | 0.28                         | -                       |      |
| USART1             | 1.07                         | -                       |      |
| USART2             | 0.48                         | -                       |      |
| WWDG               | 0.22                         | -                       |      |

1. ADC is in ready state after setting the ADEN bit in the ADC\_CR register (ADRDY bit in ADC\_ISR is high).

2. DAC channel 1 enabled by setting EN1 bit in DAC\_CR.

3. COMP I<sub>DDA</sub> is specified as I<sub>DD(COMP)</sub> in [Table 57: Comparator characteristics](#).

### 6.3.6 Wakeup time from low-power mode

The wakeup times given in [Table 33](#) are the latency between the event and the execution of the first user instruction. The device goes in low-power mode after the WFE (Wait For Event) instruction, in the case of a WFI (Wait For Interruption) instruction, 16 CPU cycles must be added to the following timings due to the interrupt latency in the Cortex M0 architecture.

The SYSCLK clock source setting is kept unchanged after wakeup from Sleep mode. After wakeup from Stop or Standby mode, SYSCLK takes the default setting: HSI 8 MHz.

The wakeup source from Sleep and Stop mode is an EXTI Line configured in event mode. The wakeup source from Standby mode is the WKUP1 pin (PA0).

All timings are derived from tests performed under the ambient temperature and supply voltage conditions summarized in [Table 20: General operating conditions](#) except when explicitly mentioned

**Table 33. Low-power mode wakeup timings**

| Symbol                 | Parameter                | Conditions                  | Typ @V <sub>DD</sub> |         |         |       |         | Max | Unit |
|------------------------|--------------------------|-----------------------------|----------------------|---------|---------|-------|---------|-----|------|
|                        |                          |                             | = 2.0 V              | = 2.4 V | = 2.7 V | = 3 V | = 3.3 V |     |      |
| t <sub>WUSTOP</sub>    | Wakeup from Stop mode    | Regulator in run mode       | 4.20                 | 4.20    | 4.20    | 4.20  | 4.20    | 5   | μs   |
|                        |                          | Regulator in low power mode | 8.05                 | 7.05    | 6.60    | 6.27  | 6.05    | 9   |      |
| t <sub>WUSTANDBY</sub> | Wakeup from Standby mode |                             | 60.35                | 55.60   | 53.50   | 52.02 | 50.96   | -   |      |
| t <sub>WUSLEEP</sub>   | Wakeup from Sleep mode   |                             | 4 SYSCLK cycles      |         |         |       |         | -   |      |

### 6.3.7 External clock source characteristics

#### High-speed external user clock generated from an external source

In bypass mode the HSE oscillator is switched off and the input pin is a standard GPIO.

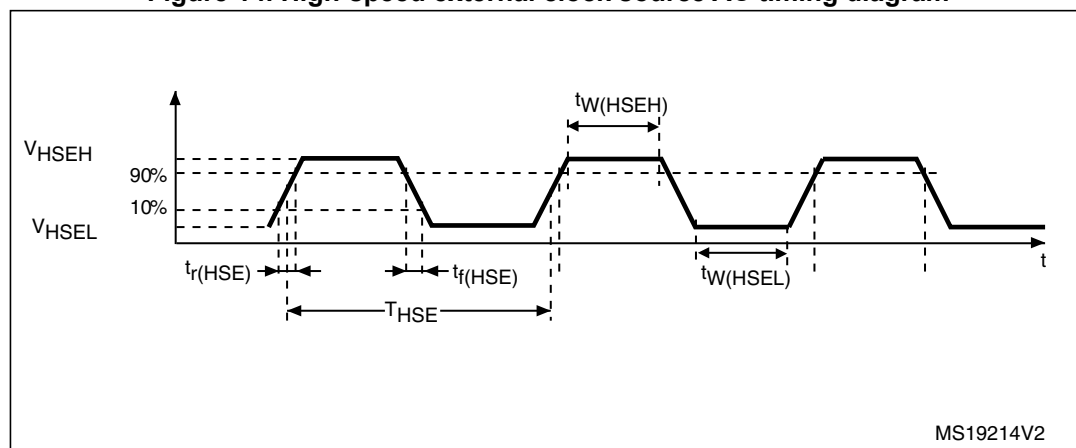
The external clock signal has to respect the I/O characteristics in [Section 6.3.14](#). However, the recommended clock input waveform is shown in [Figure 14: High-speed external clock source AC timing diagram](#).

**Table 34. High-speed external user clock characteristics**

| Symbol                         | Parameter <sup>(1)</sup>             | Conditions | Min          | Typ | Max          | Unit |
|--------------------------------|--------------------------------------|------------|--------------|-----|--------------|------|
| $f_{HSE\_ext}$                 | User external clock source frequency |            | 1            | 8   | 32           | MHz  |
| $V_{HSEH}$                     | OSC_IN input pin high level voltage  |            | $0.7 V_{DD}$ | -   | $V_{DD}$     | V    |
| $V_{HSEL}$                     | OSC_IN input pin low level voltage   |            | $V_{SS}$     | -   | $0.3 V_{DD}$ |      |
| $t_{w(HSEH)}$<br>$t_{w(HSEL)}$ | OSC_IN high or low time              |            | 15           | -   | -            | ns   |
| $t_{r(HSE)}$<br>$t_{f(HSE)}$   | OSC_IN rise or fall time             |            | -            | -   | 20           |      |

1. Guaranteed by design, not tested in production.

**Figure 14. High-speed external clock source AC timing diagram**



### Low-speed external user clock generated from an external source

In bypass mode the LSE oscillator is switched off and the input pin is a standard GPIO.

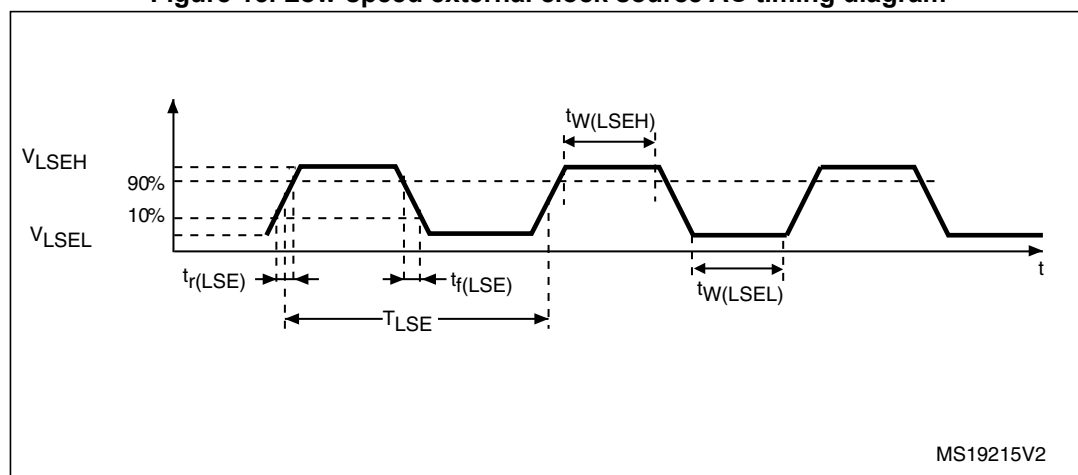
The external clock signal has to respect the I/O characteristics in [Section 6.3.14](#). However, the recommended clock input waveform is shown in [Figure 15](#).

**Table 35. Low-speed external user clock characteristics**

| Symbol                         | Parameter <sup>(1)</sup>              | Conditions | Min          | Typ    | Max          | Unit |
|--------------------------------|---------------------------------------|------------|--------------|--------|--------------|------|
| $f_{LSE\_ext}$                 | User external clock source frequency  |            | -            | 32.768 | 1000         | kHz  |
| $V_{LSEH}$                     | OSC32_IN input pin high level voltage |            | $0.7 V_{DD}$ | -      | $V_{DD}$     | V    |
| $V_{LSEL}$                     | OSC32_IN input pin low level voltage  |            | $V_{SS}$     | -      | $0.3 V_{DD}$ |      |
| $t_{w(LSEH)}$<br>$t_{w(LSEL)}$ | OSC32_IN high or low time             |            | 450          | -      | -            | ns   |
| $t_{r(LSE)}$<br>$t_{f(LSE)}$   | OSC32_IN rise or fall time            |            | -            | -      | 50           |      |

1. Guaranteed by design, not tested in production.

**Figure 15. Low-speed external clock source AC timing diagram**



### High-speed external clock generated from a crystal/ceramic resonator

The high-speed external (HSE) clock can be supplied with a 4 to 32 MHz crystal/ceramic resonator oscillator. All the information given in this paragraph are based on design simulation results obtained with typical external components specified in [Table 36](#). In the application, the resonator and the load capacitors have to be placed as close as possible to the oscillator pins in order to minimize output distortion and startup stabilization time. Refer to the crystal resonator manufacturer for more details on the resonator characteristics (frequency, package, accuracy).

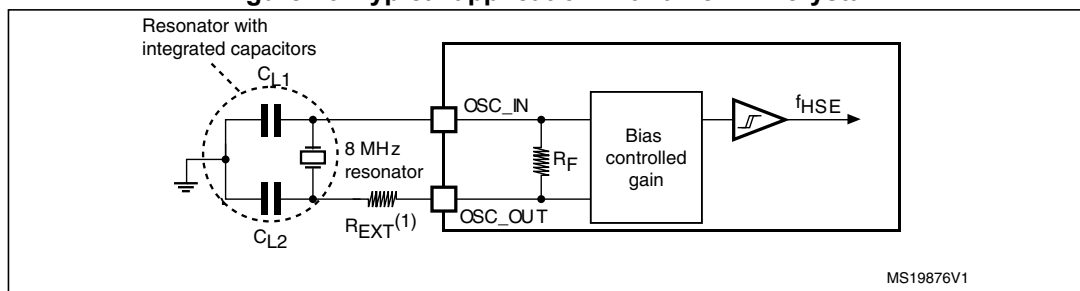
**Table 36. HSE oscillator characteristics**

| Symbol              | Parameter                   | Conditions <sup>(1)</sup>                                                              | Min <sup>(2)</sup> | Typ | Max <sup>(2)</sup> | Unit       |
|---------------------|-----------------------------|----------------------------------------------------------------------------------------|--------------------|-----|--------------------|------------|
| $f_{OSC\_IN}$       | Oscillator frequency        |                                                                                        | 4                  | 8   | 32                 | MHz        |
| $R_F$               | Feedback resistor           |                                                                                        | -                  | 200 | -                  | k $\Omega$ |
| $I_{DD}$            | HSE current consumption     | During startup <sup>(3)</sup>                                                          | -                  |     | 8.5                | mA         |
|                     |                             | $V_{DD} = 3.3\text{ V}$ ,<br>$R_m = 30\ \Omega$ ,<br>$CL = 10\text{ pF}@8\text{ MHz}$  | -                  | 0.4 | -                  |            |
|                     |                             | $V_{DD} = 3.3\text{ V}$ ,<br>$R_m = 45\ \Omega$ ,<br>$CL = 10\text{ pF}@8\text{ MHz}$  | -                  | 0.5 | -                  |            |
|                     |                             | $V_{DD} = 3.3\text{ V}$ ,<br>$R_m = 30\ \Omega$ ,<br>$CL = 5\text{ pF}@32\text{ MHz}$  | -                  | 0.8 | -                  |            |
|                     |                             | $V_{DD} = 3.3\text{ V}$ ,<br>$R_m = 30\ \Omega$ ,<br>$CL = 10\text{ pF}@32\text{ MHz}$ | -                  | 1   | -                  |            |
|                     |                             | $V_{DD} = 3.3\text{ V}$ ,<br>$R_m = 30\ \Omega$ ,<br>$CL = 20\text{ pF}@32\text{ MHz}$ | -                  | 1.5 | -                  |            |
| $g_m$               | Oscillator transconductance | Startup                                                                                | 10                 | -   | -                  | mA/V       |
| $t_{SU(HSE)}^{(4)}$ | Startup time                | $V_{DD}$ is stabilized                                                                 | -                  | 2   | -                  | ms         |

1. Resonator characteristics given by the crystal/ceramic resonator manufacturer.
2. Guaranteed by design, not tested in production.
3. This consumption level occurs during the first 2/3 of the  $t_{SU(HSE)}$  startup time
4.  $t_{SU(HSE)}$  is the startup time measured from the moment it is enabled (by software) to a stabilized 8 MHz oscillation is reached. This value is measured for a standard crystal resonator and it can vary significantly with the crystal manufacturer

For  $C_{L1}$  and  $C_{L2}$ , it is recommended to use high-quality external ceramic capacitors in the 5 pF to 20 pF range (typ.), designed for high-frequency applications, and selected to match the requirements of the crystal or resonator (see [Figure 16](#)).  $C_{L1}$  and  $C_{L2}$  are usually the same size. The crystal manufacturer typically specifies a load capacitance which is the series combination of  $C_{L1}$  and  $C_{L2}$ . PCB and MCU pin capacitance must be included (10 pF can be used as a rough estimate of the combined pin and board capacitance) when sizing  $C_{L1}$  and  $C_{L2}$ .

**Note:** For information on selecting the crystal, refer to the application note AN2867 "Oscillator design guide for ST microcontrollers" available from the ST website [www.st.com](http://www.st.com).

**Figure 16. Typical application with an 8 MHz crystal**

1.  $R_{EXT}$  value depends on the crystal characteristics.



### Low-speed external clock generated from a crystal resonator

The low-speed external (LSE) clock can be supplied with a 32.768 kHz crystal resonator oscillator. All the information given in this paragraph are based on design simulation results obtained with typical external components specified in [Table 37](#). In the application, the resonator and the load capacitors have to be placed as close as possible to the oscillator pins in order to minimize output distortion and startup stabilization time. Refer to the crystal resonator manufacturer for more details on the resonator characteristics (frequency, package, accuracy).

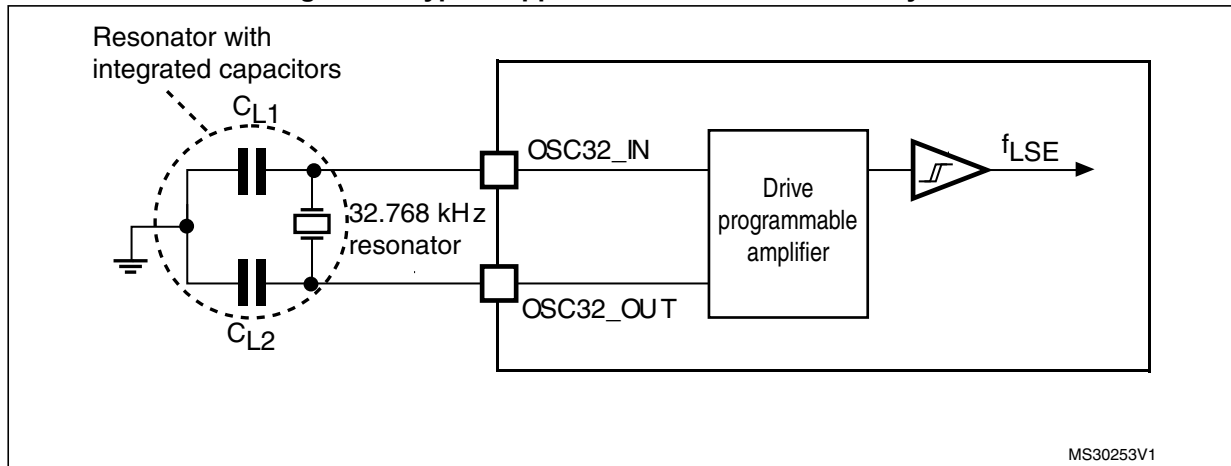
**Table 37. LSE oscillator characteristics ( $f_{LSE} = 32.768$  kHz)**

| Symbol              | Parameter                   | Conditions <sup>(1)</sup>                          | Min <sup>(2)</sup> | Typ | Max <sup>(2)</sup> | Unit      |
|---------------------|-----------------------------|----------------------------------------------------|--------------------|-----|--------------------|-----------|
| $I_{DD}$            | LSE current consumption     | LSEDRV[1:0]=00<br>lower driving capability         | -                  | 0.5 | 0.9                | $\mu A$   |
|                     |                             | LSEDRV[1:0]= 01<br>medium low driving capability   | -                  | -   | 1                  |           |
|                     |                             | LSEDRV[1:0] = 10<br>medium high driving capability | -                  | -   | 1.3                |           |
|                     |                             | LSEDRV[1:0]=11<br>higher driving capability        | -                  | -   | 1.6                |           |
| $g_m$               | Oscillator transconductance | LSEDRV[1:0]=00<br>lower driving capability         | 5                  | -   | -                  | $\mu A/V$ |
|                     |                             | LSEDRV[1:0]= 01<br>medium low driving capability   | 8                  | -   | -                  |           |
|                     |                             | LSEDRV[1:0] = 10<br>medium high driving capability | 15                 | -   | -                  |           |
|                     |                             | LSEDRV[1:0]=11<br>higher driving capability        | 25                 | -   | -                  |           |
| $t_{SU(LSE)}^{(3)}$ | Startup time                | $V_{DD}$ is stabilized                             | -                  | 2   | -                  | s         |

1. Refer to the note and caution paragraphs below the table, and to the application note AN2867 "Oscillator design guide for ST microcontrollers".
2. Guaranteed by design, not tested in production.
3.  $t_{SU(LSE)}$  is the startup time measured from the moment it is enabled (by software) to a stabilized 32.768 kHz oscillation is reached. This value is measured for a standard crystal and it can vary significantly with the crystal manufacturer

**Note:** For information on selecting the crystal, refer to the application note AN2867 "Oscillator design guide for ST microcontrollers" available from the ST website [www.st.com](http://www.st.com).

Figure 17. Typical application with a 32.768 kHz crystal



**Note:** An external resistor is not required between  $OSC32\_IN$  and  $OSC32\_OUT$  and it is forbidden to add one.

### 6.3.8 Internal clock source characteristics

The parameters given in [Table 38](#) are derived from tests performed under ambient temperature and supply voltage conditions summarized in [Table 20: General operating conditions](#). The provided curves are characterization results, not tested in production.

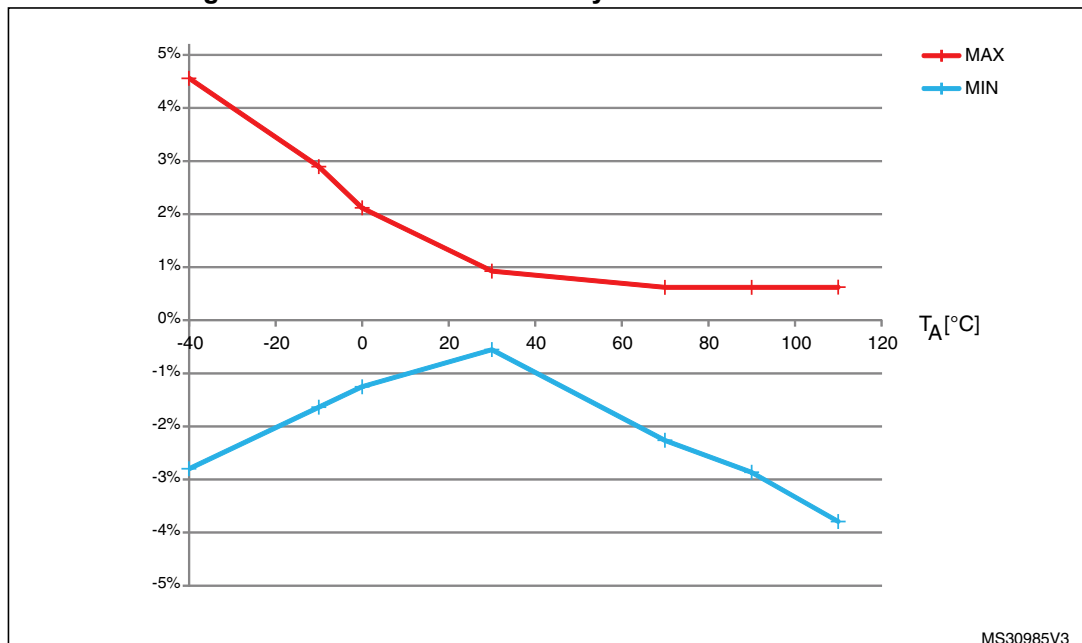
#### High-speed internal (HSI) RC oscillator

**Table 38. HSI oscillator characteristics<sup>(1)</sup>**

| Symbol                | Parameter                                           | Conditions                                   | Min                 | Typ | Max                | Unit          |
|-----------------------|-----------------------------------------------------|----------------------------------------------|---------------------|-----|--------------------|---------------|
| $f_{\text{HSI}}$      | Frequency                                           |                                              | -                   | 8   | -                  | MHz           |
| TRIM                  | HSI user trimming step                              |                                              | -                   | -   | 1 <sup>(2)</sup>   | %             |
| DuCy <sub>(HSI)</sub> | Duty cycle                                          |                                              | 45 <sup>(2)</sup>   | -   | 55 <sup>(2)</sup>  | %             |
| ACC <sub>HSI</sub>    | Accuracy of the HSI oscillator (factory calibrated) | $T_A = -40$ to $105\text{ }^{\circ}\text{C}$ | -3.8 <sup>(3)</sup> | -   | 4.6 <sup>(3)</sup> | %             |
|                       |                                                     | $T_A = -10$ to $85\text{ }^{\circ}\text{C}$  | -2.9 <sup>(3)</sup> | -   | 2.9 <sup>(3)</sup> | %             |
|                       |                                                     | $T_A = 0$ to $70\text{ }^{\circ}\text{C}$    | -1.3 <sup>(3)</sup> | -   | 2.2 <sup>(3)</sup> | %             |
|                       |                                                     | $T_A = 25\text{ }^{\circ}\text{C}$           | -1                  | -   | 1                  | %             |
| $t_{\text{su(HSI)}}$  | HSI oscillator startup time                         |                                              | 1 <sup>(2)</sup>    | -   | 2 <sup>(2)</sup>   | $\mu\text{s}$ |
| $I_{\text{DDA(HSI)}}$ | HSI oscillator power consumption                    |                                              | -                   | 80  | 100 <sup>(2)</sup> | $\mu\text{A}$ |

1.  $V_{\text{DDA}} = 3.3\text{ V}$ ,  $T_A = -40$  to  $105\text{ }^{\circ}\text{C}$  unless otherwise specified.
2. Guaranteed by design, not tested in production.
3. Data based on characterization results, not tested in production.

**Figure 18. HSI oscillator accuracy characterization results**



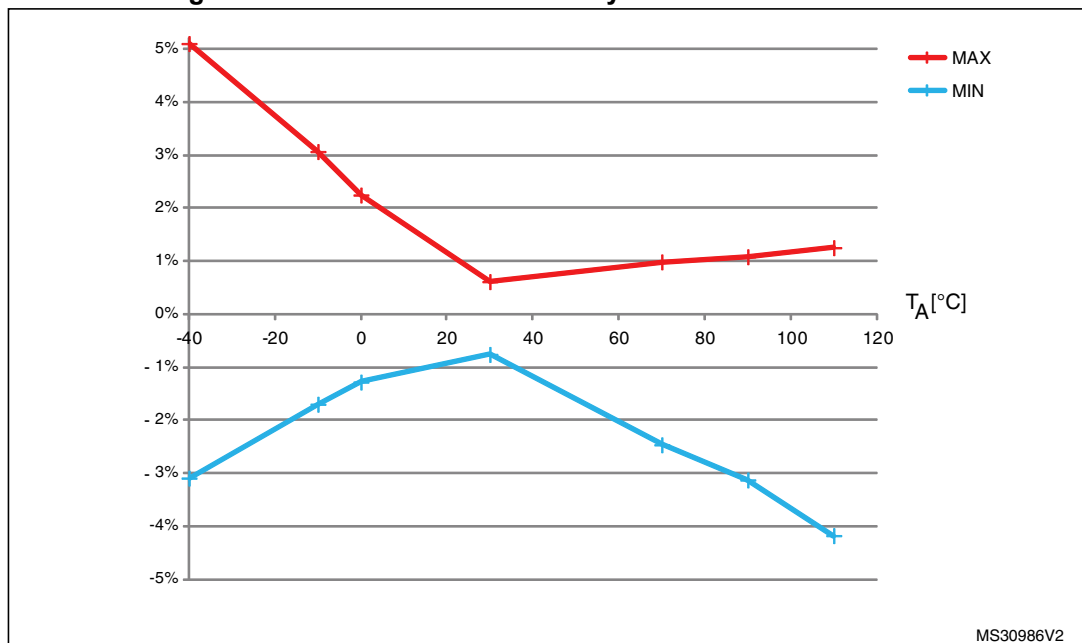
## High-speed internal 14 MHz (HSI14) RC oscillator (dedicated to ADC)

Table 39. HSI14 oscillator characteristics<sup>(1)</sup>

| Symbol                         | Parameter                                             | Conditions                                         | Min                 | Typ | Max                | Unit          |
|--------------------------------|-------------------------------------------------------|----------------------------------------------------|---------------------|-----|--------------------|---------------|
| $f_{\text{HSI14}}$             | Frequency                                             |                                                    | -                   | 14  | -                  | MHz           |
| TRIM                           | HSI14 user-trimming step                              |                                                    | -                   | -   | 1 <sup>(2)</sup>   | %             |
| DuCy(HSI14)                    | Duty cycle                                            |                                                    | 45 <sup>(2)</sup>   | -   | 55 <sup>(2)</sup>  | %             |
| ACC <sub>HSI14</sub>           | Accuracy of the HSI14 oscillator (factory calibrated) | $T_A = -40 \text{ to } 105 \text{ }^\circ\text{C}$ | -4.2 <sup>(3)</sup> | -   | 5.1 <sup>(3)</sup> | %             |
|                                |                                                       | $T_A = -10 \text{ to } 85 \text{ }^\circ\text{C}$  | -3.2 <sup>(3)</sup> | -   | 3.1 <sup>(3)</sup> | %             |
|                                |                                                       | $T_A = 0 \text{ to } 70 \text{ }^\circ\text{C}$    | -1.3 <sup>(3)</sup> | -   | 2.2 <sup>(3)</sup> | %             |
|                                |                                                       | $T_A = 25 \text{ }^\circ\text{C}$                  | -1                  | -   | 1                  | %             |
| $t_{\text{su}}(\text{HSI14})$  | HSI14 oscillator startup time                         |                                                    | 1 <sup>(2)</sup>    | -   | 2 <sup>(2)</sup>   | $\mu\text{s}$ |
| $I_{\text{DDA}}(\text{HSI14})$ | HSI14 oscillator power consumption                    |                                                    | -                   | 100 | 150 <sup>(2)</sup> | $\mu\text{A}$ |

1.  $V_{\text{DDA}} = 3.3 \text{ V}$ ,  $T_A = -40 \text{ to } 105 \text{ }^\circ\text{C}$  unless otherwise specified.
2. Guaranteed by design, not tested in production.
3. Data based on characterization results, not tested in production.

Figure 19. HSI14 oscillator accuracy characterization results



### Low-speed internal (LSI) RC oscillator

**Table 40. LSI oscillator characteristics<sup>(1)</sup>**

| Symbol               | Parameter                        | Min | Typ  | Max | Unit    |
|----------------------|----------------------------------|-----|------|-----|---------|
| $f_{LSI}$            | Frequency                        | 30  | 40   | 50  | kHz     |
| $t_{su(LSI)}^{(2)}$  | LSI oscillator startup time      | -   | -    | 85  | $\mu$ s |
| $I_{DDA(LSI)}^{(2)}$ | LSI oscillator power consumption | -   | 0.75 | 1.2 | $\mu$ A |

1.  $V_{DDA} = 3.3$  V,  $T_A = -40$  to  $105$  °C unless otherwise specified.

2. Guaranteed by design, not tested in production.

### 6.3.9 PLL characteristics

The parameters given in [Table 41](#) are derived from tests performed under ambient temperature and supply voltage conditions summarized in [Table 20: General operating conditions](#).

**Table 41. PLL characteristics**

| Symbol                | Parameter                      | Value             |     |                    | Unit    |
|-----------------------|--------------------------------|-------------------|-----|--------------------|---------|
|                       |                                | Min               | Typ | Max                |         |
| $f_{PLL\_IN}$         | PLL input clock <sup>(1)</sup> | 1 <sup>(2)</sup>  | 8.0 | 24 <sup>(2)</sup>  | MHz     |
|                       | PLL input clock duty cycle     | 40 <sup>(2)</sup> | -   | 60 <sup>(2)</sup>  | %       |
| $f_{PLL\_OUT}$        | PLL multiplier output clock    | 16 <sup>(2)</sup> | -   | 48                 | MHz     |
| $t_{LOCK}$            | PLL lock time                  | -                 | -   | 200 <sup>(2)</sup> | $\mu$ s |
| Jitter <sub>PLL</sub> | Cycle-to-cycle jitter          | -                 | -   | 300 <sup>(2)</sup> | ps      |

1. Take care to use the appropriate multiplier factors to obtain PLL input clock values compatible with the range defined by  $f_{PLL\_OUT}$ .

2. Guaranteed by design, not tested in production.

### 6.3.10 Memory characteristics

#### Flash memory

The characteristics are given at  $T_A = -40$  to  $+105$  °C unless otherwise specified.

**Table 42. Flash memory characteristics**

| Symbol             | Parameter               | Conditions               | Min | Typ  | Max <sup>(1)</sup> | Unit |
|--------------------|-------------------------|--------------------------|-----|------|--------------------|------|
| $t_{\text{prog}}$  | 16-bit programming time | $T_A = -40$ to $+105$ °C | 40  | 53.5 | 60                 | µs   |
| $t_{\text{ERASE}}$ | Page (1 KB) erase time  | $T_A = -40$ to $+105$ °C | 20  | -    | 40                 | ms   |
| $t_{\text{ME}}$    | Mass erase time         | $T_A = -40$ to $+105$ °C | 20  | -    | 40                 | ms   |
| $I_{\text{DD}}$    | Supply current          | Write mode               | -   | -    | 10                 | mA   |
|                    |                         | Erase mode               | -   | -    | 12                 | mA   |
| $V_{\text{prog}}$  | Programming voltage     |                          | 2   | -    | 3.6                | V    |

1. Guaranteed by design, not tested in production.

**Table 43. Flash memory endurance and data retention**

| Symbol           | Parameter      | Conditions                                 | Min <sup>(1)</sup> | Unit    |
|------------------|----------------|--------------------------------------------|--------------------|---------|
| $N_{\text{END}}$ | Endurance      | $T_A = -40$ to $+105$ °C                   | 10                 | kcycles |
| $t_{\text{RET}}$ | Data retention | 1 kcycle <sup>(2)</sup> at $T_A = 85$ °C   | 30                 | Years   |
|                  |                | 1 kcycle <sup>(2)</sup> at $T_A = 105$ °C  | 10                 |         |
|                  |                | 10 kcycles <sup>(2)</sup> at $T_A = 55$ °C | 20                 |         |

1. Data based on characterization results, not tested in production.

2. Cycling performed over the whole temperature range.

### 6.3.11 EMC characteristics

Susceptibility tests are performed on a sample basis during device characterization.

#### Functional EMS (electromagnetic susceptibility)

While a simple application is executed on the device (toggling 2 LEDs through I/O ports), the device is stressed by two electromagnetic events until a failure occurs. The failure is indicated by the LEDs:

- **Electrostatic discharge (ESD)** (positive and negative) is applied to all device pins until a functional disturbance occurs. This test is compliant with the IEC 61000-4-2 standard.
- **FTB:** A Burst of Fast Transient voltage (positive and negative) is applied to  $V_{\text{DD}}$  and  $V_{\text{SS}}$  through a 100 pF capacitor, until a functional disturbance occurs. This test is compliant with the IEC 61000-4-4 standard.

A device reset allows normal operations to be resumed.

The test results are given in [Table 44](#). They are based on the EMS levels and classes defined in application note AN1709.

Table 44. EMS characteristics

| Symbol     | Parameter                                                                                                                         | Conditions                                                                                                                       | Level/Class |
|------------|-----------------------------------------------------------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------|-------------|
| $V_{FESD}$ | Voltage limits to be applied on any I/O pin to induce a functional disturbance                                                    | $V_{DD} = 3.3\text{ V}$ , LQFP64, $T_A = +25\text{ }^{\circ}\text{C}$ , $f_{HCLK} = 48\text{ MHz}$ , conforming to IEC 61000-4-2 | 2B          |
| $V_{EFTB}$ | Fast transient voltage burst limits to be applied through 100 pF on $V_{DD}$ and $V_{SS}$ pins to induce a functional disturbance | $V_{DD} = 3.3\text{ V}$ , LQFP64, $T_A = +25\text{ }^{\circ}\text{C}$ , $f_{HCLK} = 48\text{ MHz}$ , conforming to IEC 61000-4-4 | 3B          |

### Designing hardened software to avoid noise problems

EMC characterization and optimization are performed at component level with a typical application environment and simplified MCU software. It should be noted that good EMC performance is highly dependent on the user application and the software in particular.

Therefore it is recommended that the user applies EMC software optimization and prequalification tests in relation with the EMC level requested for his application.

### Software recommendations

The software flowchart must include the management of runaway conditions such as:

- Corrupted program counter
- Unexpected reset
- Critical Data corruption (control registers...)

### Prequalification trials

Most of the common failures (unexpected reset and program counter corruption) can be reproduced by manually forcing a low state on the NRST pin or the Oscillator pins for 1 second.

To complete these trials, ESD stress can be applied directly on the device, over the range of specification values. When unexpected behavior is detected, the software can be hardened to prevent unrecoverable errors occurring (see application note AN1015).

### Electromagnetic Interference (EMI)

The electromagnetic field emitted by the device are monitored while a simple application is executed (toggling 2 LEDs through the I/O ports). This emission test is compliant with IEC 61967-2 standard which specifies the test board and the pin loading.

Table 45. EMI characteristics

| Symbol    | Parameter  | Conditions                                                                                               | Monitored frequency band | Max vs. $[f_{HSE}/f_{HCLK}]$ | Unit       |
|-----------|------------|----------------------------------------------------------------------------------------------------------|--------------------------|------------------------------|------------|
|           |            |                                                                                                          |                          | 8/48 MHz                     |            |
| $S_{EMI}$ | Peak level | $V_{DD} = 3.6\text{ V}$ , $T_A = 25\text{ }^{\circ}\text{C}$ , LQFP64 package compliant with IEC 61967-2 | 0.1 to 30 MHz            | -3                           | dB $\mu$ V |
|           |            |                                                                                                          | 30 to 130 MHz            | 28                           |            |
|           |            |                                                                                                          | 130 MHz to 1GHz          | 23                           |            |
|           |            |                                                                                                          | SAE EMI Level            | 4                            | -          |

### 6.3.12 Electrical sensitivity characteristics

Based on three different tests (ESD, LU) using specific measurement methods, the device is stressed in order to determine its performance in terms of electrical sensitivity.

#### Electrostatic discharge (ESD)

Electrostatic discharges (a positive then a negative pulse separated by 1 second) are applied to the pins of each sample according to each pin combination. The sample size depends on the number of supply pins in the device (3 parts  $\times$  (n+1) supply pins). This test conforms to the JESD22-A114/C101 standard.

**Table 46. ESD absolute maximum ratings**

| Symbol                | Ratings                                               | Conditions                                                            | Class | Maximum value <sup>(1)</sup> | Unit |
|-----------------------|-------------------------------------------------------|-----------------------------------------------------------------------|-------|------------------------------|------|
| $V_{\text{ESD(HBM)}}$ | Electrostatic discharge voltage (human body model)    | $T_A = +25\text{ }^{\circ}\text{C}$ , conforming to JESD22-A114       | 2     | 2000                         | V    |
| $V_{\text{ESD(CDM)}}$ | Electrostatic discharge voltage (charge device model) | $T_A = +25\text{ }^{\circ}\text{C}$ , conforming to ANSI/ESD STM5.3.1 | II    | 500                          |      |

1. Data based on characterization results, not tested in production.

#### Static latch-up

Two complementary static tests are required on six parts to assess the latch-up performance:

- A supply overvoltage is applied to each power supply pin.
- A current injection is applied to each input, output and configurable I/O pin.

These tests are compliant with EIA/JESD 78A IC latch-up standard.

**Table 47. Electrical sensitivities**

| Symbol | Parameter             | Conditions                                                 | Class      |
|--------|-----------------------|------------------------------------------------------------|------------|
| LU     | Static latch-up class | $T_A = +105\text{ }^{\circ}\text{C}$ conforming to JESD78A | II level A |

### 6.3.13 I/O current injection characteristics

As a general rule, current injection to the I/O pins, due to external voltage below  $V_{\text{SS}}$  or above  $V_{\text{DDIOx}}$  (for standard, 3.3 V-capable I/O pins) should be avoided during normal product operation. However, in order to give an indication of the robustness of the microcontroller in cases when abnormal injection accidentally happens, susceptibility tests are performed on a sample basis during device characterization.



### Functional susceptibility to I/O current injection

While a simple application is executed on the device, the device is stressed by injecting current into the I/O pins programmed in floating input mode. While current is injected into the I/O pin, one at a time, the device is checked for functional failures.

The failure is indicated by an out of range parameter: ADC error above a certain limit (higher than 5 LSB TUE), out of conventional limits of induced leakage current on adjacent pins (out of the  $-5\ \mu\text{A}/+0\ \mu\text{A}$  range) or other functional failure (for example reset occurrence or oscillator frequency deviation).

The characterization results are given in [Table 48](#).

Negative induced leakage current is caused by negative injection and positive induced leakage current is caused by positive injection.

**Table 48. I/O current injection susceptibility**

| Symbol           | Description                                                                                                                                  | Functional susceptibility |                    | Unit |
|------------------|----------------------------------------------------------------------------------------------------------------------------------------------|---------------------------|--------------------|------|
|                  |                                                                                                                                              | Negative injection        | Positive injection |      |
| $I_{\text{INJ}}$ | Injected current on BOOT0                                                                                                                    | -0                        | NA                 | mA   |
|                  | Injected current on PA10, PA12, PB4, PB5, PB10, PB15 and PD2 pins with induced leakage current on adjacent pins less than $-10\ \mu\text{A}$ | -5                        | NA                 |      |
|                  | Injected current on all other FT and FTf pins                                                                                                | -5                        | NA                 |      |
|                  | Injected current on PA6 and PC0                                                                                                              | -0                        | +5                 |      |
|                  | Injected current on all other TTa, TC and RST pins                                                                                           | -5                        | +5                 |      |

## 6.3.14 I/O port characteristics

### General input/output characteristics

Unless otherwise specified, the parameters given in [Table 49](#) are derived from tests performed under the conditions summarized in [Table 20: General operating conditions](#). All I/Os are designed as CMOS- and TTL-compliant (except BOOT0).

**Table 49. I/O static characteristics**

| Symbol          | Parameter               | Conditions                | Min | Typ | Max                                   | Unit |
|-----------------|-------------------------|---------------------------|-----|-----|---------------------------------------|------|
| $V_{\text{IL}}$ | Low level input voltage | TC and TTa I/O            | -   | -   | $0.3\ V_{\text{DDIOx}} + 0.07^{(1)}$  | V    |
|                 |                         | FT and FTf I/O            | -   | -   | $0.475\ V_{\text{DDIOx}} - 0.2^{(1)}$ |      |
|                 |                         | BOOT0                     | -   | -   | $0.3\ V_{\text{DDIOx}} - 0.3^{(1)}$   |      |
|                 |                         | All I/Os except BOOT0 pin | -   | -   | $0.3\ V_{\text{DDIOx}}$               |      |

Table 49. I/O static characteristics (continued)

| Symbol    | Parameter                                         | Conditions                                                                       | Min                             | Typ         | Max       | Unit      |
|-----------|---------------------------------------------------|----------------------------------------------------------------------------------|---------------------------------|-------------|-----------|-----------|
| $V_{IH}$  | High level input voltage                          | TC and TTa I/O                                                                   | $0.445 V_{DDIOx} + 0.398^{(1)}$ | -           | -         | V         |
|           |                                                   | FT and FTf I/O                                                                   | $0.5 V_{DDIOx} + 0.2^{(1)}$     | -           | -         |           |
|           |                                                   | BOOT0                                                                            | $0.2 V_{DDIOx} + 0.95^{(1)}$    | -           | -         |           |
|           |                                                   | All I/Os except BOOT0 pin                                                        | $0.7 V_{DDIOx}$                 | -           | -         |           |
| $V_{hys}$ | Schmitt trigger hysteresis                        | TC and TTa I/O                                                                   | -                               | $200^{(1)}$ | -         | mV        |
|           |                                                   | FT and FTf I/O                                                                   | -                               | $100^{(1)}$ | -         |           |
|           |                                                   | BOOT0                                                                            | -                               | $300^{(1)}$ | -         |           |
| $I_{lk}$  | Input leakage current <sup>(2)</sup>              | TC, FT and FTf I/O<br>TTa in digital mode<br>$V_{SS} \leq V_{IN} \leq V_{DDIOx}$ | -                               | -           | $\pm 0.1$ | $\mu A$   |
|           |                                                   | TTa in digital mode<br>$V_{DDIOx} \leq V_{IN} \leq V_{DDA}$                      | -                               | -           | 1         |           |
|           |                                                   | TTa in analog mode<br>$V_{SS} \leq V_{IN} \leq V_{DDA}$                          | -                               | -           | $\pm 0.2$ |           |
|           |                                                   | FT and FTf I/O <sup>(3)</sup><br>$V_{DDIOx} \leq V_{IN} \leq 5 V$                | -                               | -           | 10        |           |
| $R_{PU}$  | Weak pull-up equivalent resistor <sup>(4)</sup>   | $V_{IN} = V_{SS}$                                                                | 25                              | 40          | 55        | $k\Omega$ |
| $R_{PD}$  | Weak pull-down equivalent resistor <sup>(4)</sup> | $V_{IN} = V_{DDIOx}$                                                             | 25                              | 40          | 55        | $k\Omega$ |
| $C_{IO}$  | I/O pin capacitance                               |                                                                                  | -                               | 5           | -         | pF        |

1. Data based on design simulation only. Not tested in production.

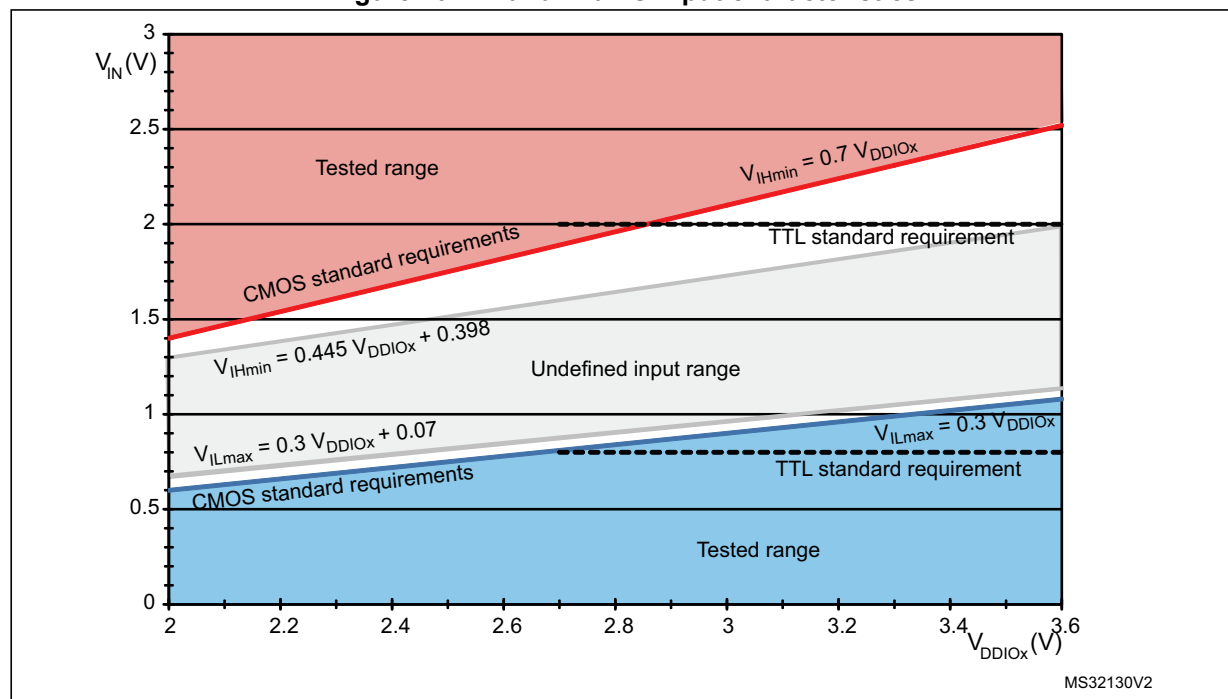
2. The leakage could be higher than the maximum value, if negative current is injected on adjacent pins. Refer to [Table 48: I/O current injection susceptibility](#).

3. To sustain a voltage higher than  $V_{DDIOx} + 0.3 V$ , the internal pull-up/pull-down resistors must be disabled.

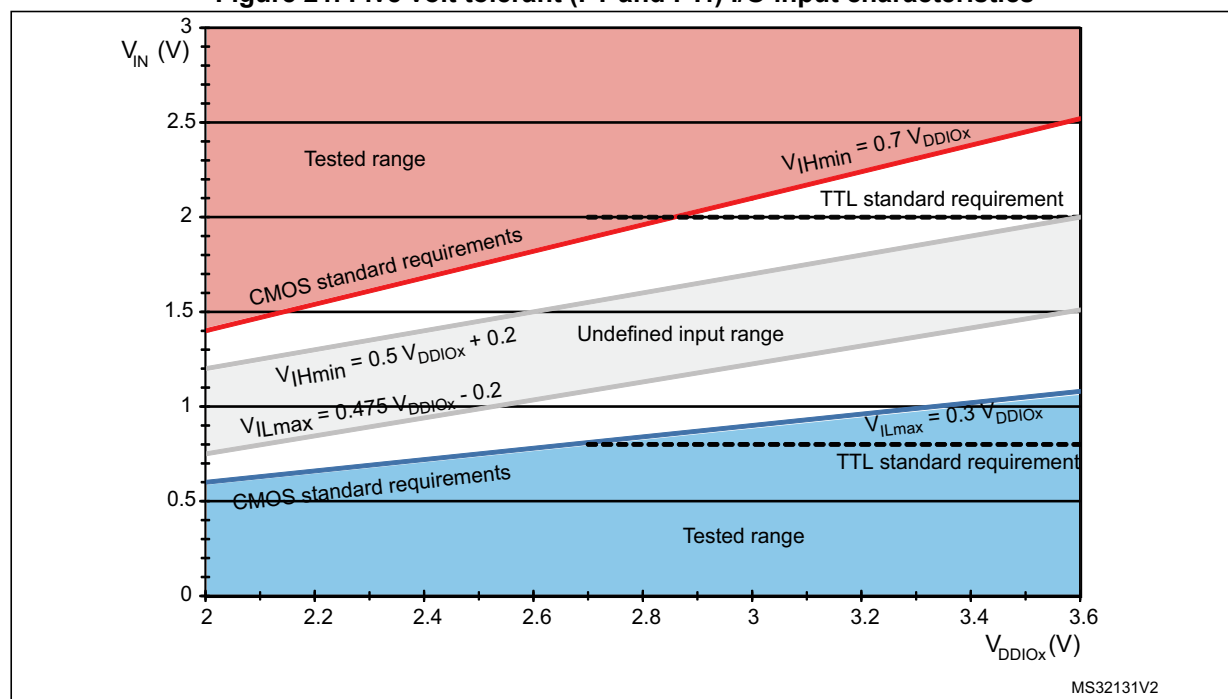
4. Pull-up and pull-down resistors are designed with a true resistance in series with a switchable PMOS/NMOS. This PMOS/NMOS contribution to the series resistance is minimal (~10% order).

All I/Os are CMOS- and TTL-compliant (no software configuration required). Their characteristics cover more than the strict CMOS-technology or TTL parameters. The coverage of these requirements is shown in [Figure 20](#) for standard I/Os, and in [Figure 21](#) for 5 V tolerant I/Os.

**Figure 20. TC and TTa I/O input characteristics**



**Figure 21. Five volt tolerant (FT and FTf) I/O input characteristics**



### Output driving current

The GPIOs (general purpose input/outputs) can sink or source up to  $\pm 8$  mA, and sink or source up to  $\pm 20$  mA (with a relaxed  $V_{OL}/V_{OH}$ ).

In the user application, the number of I/O pins which can drive current must be limited to respect the absolute maximum rating specified in [Section 6.2](#):

- The sum of the currents sourced by all the I/Os on  $V_{DDIOx}$ , plus the maximum consumption of the MCU sourced on  $V_{DD}$ , cannot exceed the absolute maximum rating  $\Sigma I_{VDD}$  (see [Table 18: Current characteristics](#)).
- The sum of the currents sunk by all the I/Os on  $V_{SS}$ , plus the maximum consumption of the MCU sunk on  $V_{SS}$ , cannot exceed the absolute maximum rating  $\Sigma I_{VSS}$  (see [Table 18: Current characteristics](#)).

### Output voltage levels

Unless otherwise specified, the parameters given in the table below are derived from tests performed under the ambient temperature and supply voltage conditions summarized in [Table 20: General operating conditions](#). All I/Os are CMOS- and TTL-compliant (FT, TTa or TC unless otherwise specified).

**Table 50. Output voltage characteristics<sup>(1)</sup>**

| Symbol            | Parameter                                               | Conditions                                                              | Min               | Max | Unit |
|-------------------|---------------------------------------------------------|-------------------------------------------------------------------------|-------------------|-----|------|
| $V_{OL}$          | Output low level voltage for an I/O pin                 | CMOS port <sup>(2)</sup><br>$ I_{IO}  = 8$ mA<br>$V_{DDIOx} \geq 2.7$ V | -                 | 0.4 | V    |
| $V_{OH}$          | Output high level voltage for an I/O pin                |                                                                         | $V_{DDIOx} - 0.4$ | -   |      |
| $V_{OL}$          | Output low level voltage for an I/O pin                 | TTL port <sup>(2)</sup><br>$ I_{IO}  = 8$ mA<br>$V_{DDIOx} \geq 2.7$ V  | -                 | 0.4 | V    |
| $V_{OH}$          | Output high level voltage for an I/O pin                |                                                                         | 2.4               | -   |      |
| $V_{OL}^{(3)}$    | Output low level voltage for an I/O pin                 | $ I_{IO}  = 20$ mA<br>$V_{DDIOx} \geq 2.7$ V                            | -                 | 1.3 | V    |
| $V_{OH}^{(3)}$    | Output high level voltage for an I/O pin                |                                                                         | $V_{DDIOx} - 1.3$ | -   |      |
| $V_{OL}^{(3)}$    | Output low level voltage for an I/O pin                 | $ I_{IO}  = 6$ mA                                                       | -                 | 0.4 | V    |
| $V_{OH}^{(3)}$    | Output high level voltage for an I/O pin                |                                                                         | $V_{DDIOx} - 0.4$ | -   |      |
| $V_{OLFM+}^{(4)}$ | Output low level voltage for an FTf I/O pin in FM+ mode | $ I_{IO}  = 20$ mA<br>$V_{DDIOx} \geq 2.7$ V                            | -                 | 0.4 | V    |
|                   |                                                         | $ I_{IO}  = 10$ mA                                                      | -                 | 0.4 | V    |

1. The  $I_{IO}$  current sourced or sunk by the device must always respect the absolute maximum rating specified in [Table 18: Current characteristics](#), and the sum of the currents sourced or sunk by all the I/Os (I/O ports and control pins) must always respect the absolute maximum ratings  $\Sigma I_{IO}$ .
2. TTL and CMOS outputs are compatible with JEDEC standards JESD36 and JESD52.
3. Data based on characterization results. Not tested in production.
4. Data based on design simulation only. Not tested in production.

### Input/output AC characteristics

The definition and values of input/output AC characteristics are given in [Figure 22](#) and [Table 51](#), respectively.

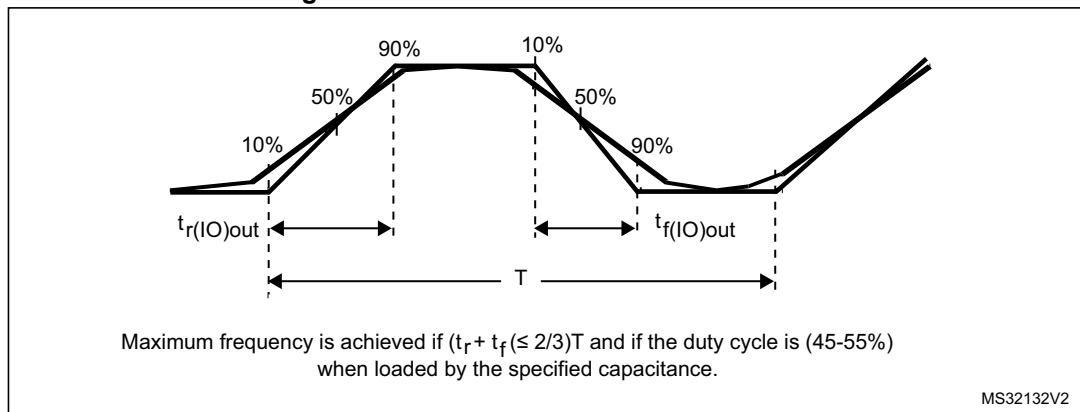
Unless otherwise specified, the parameters given are derived from tests performed under the ambient temperature and supply voltage conditions summarized in [Table 20: General operating conditions](#).

**Table 51. I/O AC characteristics<sup>(1)(2)</sup>**

| OSPEEDRx<br>[1:0]<br>value <sup>(1)</sup> | Symbol                          | Parameter                                                       | Conditions                                                 | Min | Max | Unit |
|-------------------------------------------|---------------------------------|-----------------------------------------------------------------|------------------------------------------------------------|-----|-----|------|
| x0                                        | $f_{\max(\text{IO})\text{out}}$ | Maximum frequency <sup>(3)</sup>                                | $C_L = 50 \text{ pF}$                                      | -   | 2   | MHz  |
|                                           | $t_{f(\text{IO})\text{out}}$    | Output fall time                                                |                                                            | -   | 125 | ns   |
|                                           | $t_{r(\text{IO})\text{out}}$    | Output rise time                                                |                                                            | -   | 125 |      |
| 01                                        | $f_{\max(\text{IO})\text{out}}$ | Maximum frequency <sup>(3)</sup>                                | $C_L = 50 \text{ pF}$                                      | -   | 10  | MHz  |
|                                           | $t_{f(\text{IO})\text{out}}$    | Output fall time                                                |                                                            | -   | 25  | ns   |
|                                           | $t_{r(\text{IO})\text{out}}$    | Output rise time                                                |                                                            | -   | 25  |      |
| 11                                        | $f_{\max(\text{IO})\text{out}}$ | Maximum frequency <sup>(3)</sup>                                | $C_L = 30 \text{ pF}, V_{\text{DDIOx}} \geq 2.7 \text{ V}$ | -   | 50  | MHz  |
|                                           |                                 |                                                                 | $C_L = 50 \text{ pF}, V_{\text{DDIOx}} \geq 2.7 \text{ V}$ | -   | 30  |      |
|                                           |                                 |                                                                 | $C_L = 50 \text{ pF}, V_{\text{DDIOx}} < 2.7 \text{ V}$    | -   | 20  |      |
|                                           | $t_{f(\text{IO})\text{out}}$    | Output fall time                                                | $C_L = 30 \text{ pF}, V_{\text{DDIOx}} \geq 2.7 \text{ V}$ | -   | 5   | ns   |
|                                           |                                 |                                                                 | $C_L = 50 \text{ pF}, V_{\text{DDIOx}} \geq 2.7 \text{ V}$ | -   | 8   |      |
|                                           |                                 |                                                                 | $C_L = 50 \text{ pF}, V_{\text{DDIOx}} < 2.7 \text{ V}$    | -   | 12  |      |
|                                           | $t_{r(\text{IO})\text{out}}$    | Output rise time                                                | $C_L = 30 \text{ pF}, V_{\text{DDIOx}} \geq 2.7 \text{ V}$ | -   | 5   |      |
|                                           |                                 |                                                                 | $C_L = 50 \text{ pF}, V_{\text{DDIOx}} \geq 2.7 \text{ V}$ | -   | 8   |      |
|                                           |                                 |                                                                 | $C_L = 50 \text{ pF}, V_{\text{DDIOx}} < 2.7 \text{ V}$    | -   | 12  |      |
| FM+<br>configuration <sup>(4)</sup>       | $f_{\max(\text{IO})\text{out}}$ | Maximum frequency <sup>(3)</sup>                                | $C_L = 50 \text{ pF}$                                      | -   | 2   | MHz  |
|                                           | $t_{f(\text{IO})\text{out}}$    | Output fall time                                                |                                                            | -   | 12  | ns   |
|                                           | $t_{r(\text{IO})\text{out}}$    | Output rise time                                                |                                                            | -   | 34  |      |
|                                           | $t_{\text{EXTI}pw}$             | Pulse width of external signals detected by the EXTI controller |                                                            | 10  | -   | ns   |

1. The I/O speed is configured using the OSPEEDRx[1:0] bits. Refer to the STM32F0xxx RM0091 reference manual for a description of GPIO Port configuration register.
2. Guaranteed by design, not tested in production.
3. The maximum frequency is defined in [Figure 22](#).
4. When FM+ configuration is set, the I/O speed control is bypassed. Refer to the STM32F0xxx reference manual RM0091 for a detailed description of FM+ I/O configuration.

Figure 22. I/O AC characteristics definition



### 6.3.15 NRST pin characteristics

The NRST pin input driver uses the CMOS technology. It is connected to a permanent pull-up resistor,  $R_{PU}$ .

Unless otherwise specified, the parameters given in the table below are derived from tests performed under the ambient temperature and supply voltage conditions summarized in [Table 20: General operating conditions](#).

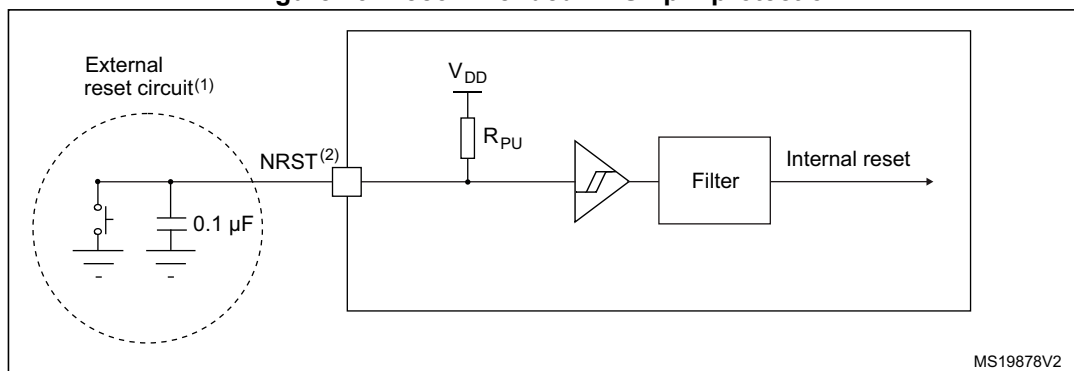
Table 52. NRST pin characteristics

| Symbol          | Parameter                                       | Conditions           | Min                          | Typ | Max                       | Unit       |
|-----------------|-------------------------------------------------|----------------------|------------------------------|-----|---------------------------|------------|
| $V_{IL(NRST)}$  | NRST input low level voltage                    |                      | -                            | -   | $0.3 V_{DD} + 0.07^{(1)}$ | V          |
| $V_{IH(NRST)}$  | NRST input high level voltage                   |                      | $0.445 V_{DD} + 0.398^{(1)}$ | -   | -                         |            |
| $V_{hys(NRST)}$ | NRST Schmitt trigger voltage hysteresis         |                      | -                            | 200 | -                         | mV         |
| $R_{PU}$        | Weak pull-up equivalent resistor <sup>(2)</sup> | $V_{IN} = V_{SS}$    | 25                           | 40  | 55                        | k $\Omega$ |
| $V_{F(NRST)}$   | NRST input filtered pulse                       |                      | -                            | -   | $100^{(1)}$               | ns         |
| $V_{NF(NRST)}$  | NRST input not filtered pulse                   | $2.7 < V_{DD} < 3.6$ | $300^{(1)}$                  | -   | -                         | ns         |
|                 |                                                 | $2.0 < V_{DD} < 3.6$ | $500^{(1)}$                  | -   | -                         |            |

1. Data based on design simulation only. Not tested in production.

2. The pull-up is designed with a true resistance in series with a switchable PMOS. This PMOS contribution to the series resistance is minimal (~10% order).

Figure 23. Recommended NRST pin protection



1. The external capacitor protects the device against parasitic resets.
2. The user must ensure that the level on the NRST pin can go below the  $V_{IL(NRST)}$  max level specified in [Table 52: NRST pin characteristics](#). Otherwise the reset will not be taken into account by the device.

### 6.3.16 12-bit ADC characteristics

Unless otherwise specified, the parameters given in [Table 53](#) are preliminary values derived from tests performed under ambient temperature,  $f_{PCLK}$  frequency and  $V_{DDA}$  supply voltage conditions summarized in [Table 20: General operating conditions](#).

**Note:** *It is recommended to perform a calibration after each power-up.*

Table 53. ADC characteristics

| Symbol           | Parameter                                     | Conditions                                                              | Min  | Typ | Max       | Unit          |
|------------------|-----------------------------------------------|-------------------------------------------------------------------------|------|-----|-----------|---------------|
| $V_{DDA}$        | Analog supply voltage for ADC ON              |                                                                         | 2.4  | -   | 3.6       | V             |
| $I_{DDA(ADC)}$   | Current consumption of the ADC <sup>(1)</sup> | $V_{DD} = V_{DDA} = 3.3\text{ V}$                                       | -    | 0.9 | -         | mA            |
| $f_{ADC}$        | ADC clock frequency                           |                                                                         | 0.6  | -   | 14        | MHz           |
| $f_S^{(2)}$      | Sampling rate                                 |                                                                         | 0.05 | -   | 1         | MHz           |
| $f_{TRIG}^{(2)}$ | External trigger frequency                    | $f_{ADC} = 14\text{ MHz}$                                               | -    | -   | 823       | kHz           |
|                  |                                               |                                                                         | -    | -   | 17        | $1/f_{ADC}$   |
| $V_{AIN}$        | Conversion voltage range                      |                                                                         | 0    | -   | $V_{DDA}$ | V             |
| $R_{AIN}^{(2)}$  | External input impedance                      | See <a href="#">Equation 1</a> and <a href="#">Table 54</a> for details | -    | -   | 50        | k $\Omega$    |
| $R_{ADC}^{(2)}$  | Sampling switch resistance                    |                                                                         | -    | -   | 1         | k $\Omega$    |
| $C_{ADC}^{(2)}$  | Internal sample and hold capacitor            |                                                                         | -    | -   | 8         | pF            |
| $t_{CAL}^{(2)}$  | Calibration time                              | $f_{ADC} = 14\text{ MHz}$                                               | 5.9  |     |           | $\mu\text{s}$ |
|                  |                                               |                                                                         | 83   |     |           | $1/f_{ADC}$   |

Table 53. ADC characteristics (continued)

| Symbol                       | Parameter                                       | Conditions                                            | Min                                                                          | Typ | Max                                         | Unit                    |
|------------------------------|-------------------------------------------------|-------------------------------------------------------|------------------------------------------------------------------------------|-----|---------------------------------------------|-------------------------|
| $W_{\text{LATENCY}}^{(2)}$   | ADC_DR register write latency                   | ADC clock = HSI14                                     | 1.5 ADC cycles + 2 $f_{\text{PCLK}}$ cycles                                  | -   | 1.5 ADC cycles + 3 $f_{\text{PCLK}}$ cycles |                         |
|                              |                                                 | ADC clock = PCLK/2                                    | -                                                                            | 4.5 | -                                           | $f_{\text{PCLK}}$ cycle |
|                              |                                                 | ADC clock = PCLK/4                                    | -                                                                            | 8.5 | -                                           | $f_{\text{PCLK}}$ cycle |
| $t_{\text{latr}}^{(2)}$      | Trigger conversion latency                      | $f_{\text{ADC}} = f_{\text{PCLK}}/2 = 14 \text{ MHz}$ | 0.196                                                                        |     |                                             | $\mu\text{s}$           |
|                              |                                                 | $f_{\text{ADC}} = f_{\text{PCLK}}/2$                  | 5.5                                                                          |     |                                             | $1/f_{\text{PCLK}}$     |
|                              |                                                 | $f_{\text{ADC}} = f_{\text{PCLK}}/4 = 12 \text{ MHz}$ | 0.219                                                                        |     |                                             | $\mu\text{s}$           |
|                              |                                                 | $f_{\text{ADC}} = f_{\text{PCLK}}/4$                  | 10.5                                                                         |     |                                             | $1/f_{\text{PCLK}}$     |
|                              |                                                 | $f_{\text{ADC}} = f_{\text{HSI14}} = 14 \text{ MHz}$  | 0.188                                                                        | -   | 0.259                                       | $\mu\text{s}$           |
| $\text{Jitter}_{\text{ADC}}$ | ADC jitter on trigger conversion                | $f_{\text{ADC}} = f_{\text{HSI14}}$                   | -                                                                            | 1   | -                                           | $1/f_{\text{HSI14}}$    |
| $t_{\text{S}}^{(2)}$         | Sampling time                                   | $f_{\text{ADC}} = 14 \text{ MHz}$                     | 0.107                                                                        | -   | 17.1                                        | $\mu\text{s}$           |
|                              |                                                 |                                                       | 1.5                                                                          | -   | 239.5                                       | $1/f_{\text{ADC}}$      |
| $t_{\text{STAB}}^{(2)}$      | Power-up time                                   |                                                       | 0                                                                            | 0   | 1                                           | $\mu\text{s}$           |
| $t_{\text{CONV}}^{(2)}$      | Total conversion time (including sampling time) | $f_{\text{ADC}} = 14 \text{ MHz}$                     | 1                                                                            | -   | 18                                          | $\mu\text{s}$           |
|                              |                                                 |                                                       | 14 to 252 ( $t_{\text{S}}$ for sampling + 12.5 for successive approximation) |     |                                             | $1/f_{\text{ADC}}$      |

- During conversion of the sampled value ( $12.5 \times \text{ADC clock period}$ ), an additional consumption of  $100 \mu\text{A}$  on  $I_{\text{DDA}}$  and  $60 \mu\text{A}$  on  $I_{\text{DD}}$  should be taken into account.
- Guaranteed by design, not tested in production.

**Equation 1:  $R_{\text{AIN}}$  max formula**

$$R_{\text{AIN}} < \frac{T_{\text{S}}}{f_{\text{ADC}} \times C_{\text{ADC}} \times \ln(2^{N+2})} - R_{\text{ADC}}$$

The formula above ([Equation 1](#)) is used to determine the maximum external impedance allowed for an error below 1/4 of LSB. Here  $N = 12$  (from 12-bit resolution).

Table 54.  $R_{\text{AIN}}$  max for  $f_{\text{ADC}} = 14 \text{ MHz}$ 

| $T_{\text{S}}$ (cycles) | $t_{\text{S}}$ ( $\mu\text{s}$ ) | $R_{\text{AIN}}$ max ( $\text{k}\Omega$ ) <sup>(1)</sup> |
|-------------------------|----------------------------------|----------------------------------------------------------|
| 1.5                     | 0.11                             | 0.4                                                      |
| 7.5                     | 0.54                             | 5.9                                                      |
| 13.5                    | 0.96                             | 11.4                                                     |
| 28.5                    | 2.04                             | 25.2                                                     |
| 41.5                    | 2.96                             | 37.2                                                     |
| 55.5                    | 3.96                             | 50                                                       |



Table 54.  $R_{AIN}$  max for  $f_{ADC} = 14$  MHz (continued)

| $T_s$ (cycles) | $t_s$ ( $\mu s$ ) | $R_{AIN}$ max ( $k\Omega$ ) <sup>(1)</sup> |
|----------------|-------------------|--------------------------------------------|
| 71.5           | 5.11              | NA                                         |
| 239.5          | 17.1              | NA                                         |

1. Guaranteed by design, not tested in production.

Table 55. ADC accuracy<sup>(1)(2)(3)</sup>

| Symbol | Parameter                    | Test conditions                                                                                                             | Typ       | Max <sup>(4)</sup> | Unit |
|--------|------------------------------|-----------------------------------------------------------------------------------------------------------------------------|-----------|--------------------|------|
| ET     | Total unadjusted error       | $f_{PCLK} = 48$ MHz,<br>$f_{ADC} = 14$ MHz, $R_{AIN} < 10$ $k\Omega$<br>$V_{DDA} = 3$ V to 3.6 V<br>$T_A = 25$ °C           | $\pm 1.3$ | $\pm 2$            | LSB  |
| EO     | Offset error                 |                                                                                                                             | $\pm 1$   | $\pm 1.5$          |      |
| EG     | Gain error                   |                                                                                                                             | $\pm 0.5$ | $\pm 1.5$          |      |
| ED     | Differential linearity error |                                                                                                                             | $\pm 0.7$ | $\pm 1$            |      |
| EL     | Integral linearity error     |                                                                                                                             | $\pm 0.8$ | $\pm 1.5$          |      |
| ET     | Total unadjusted error       | $f_{PCLK} = 48$ MHz,<br>$f_{ADC} = 14$ MHz, $R_{AIN} < 10$ $k\Omega$<br>$V_{DDA} = 2.7$ V to 3.6 V<br>$T_A = -40$ to 105 °C | $\pm 3.3$ | $\pm 4$            | LSB  |
| EO     | Offset error                 |                                                                                                                             | $\pm 1.9$ | $\pm 2.8$          |      |
| EG     | Gain error                   |                                                                                                                             | $\pm 2.8$ | $\pm 3$            |      |
| ED     | Differential linearity error |                                                                                                                             | $\pm 0.7$ | $\pm 1.3$          |      |
| EL     | Integral linearity error     |                                                                                                                             | $\pm 1.2$ | $\pm 1.7$          |      |
| ET     | Total unadjusted error       | $f_{PCLK} = 48$ MHz,<br>$f_{ADC} = 14$ MHz, $R_{AIN} < 10$ $k\Omega$<br>$V_{DDA} = 2.4$ V to 3.6 V<br>$T_A = 25$ °C         | $\pm 3.3$ | $\pm 4$            | LSB  |
| EO     | Offset error                 |                                                                                                                             | $\pm 1.9$ | $\pm 2.8$          |      |
| EG     | Gain error                   |                                                                                                                             | $\pm 2.8$ | $\pm 3$            |      |
| ED     | Differential linearity error |                                                                                                                             | $\pm 0.7$ | $\pm 1.3$          |      |
| EL     | Integral linearity error     |                                                                                                                             | $\pm 1.2$ | $\pm 1.7$          |      |

1. ADC DC accuracy values are measured after internal calibration.
2. ADC Accuracy vs. Negative Injection Current: Injecting negative current on any of the standard (non-robust) analog input pins should be avoided as this significantly reduces the accuracy of the conversion being performed on another analog input. It is recommended to add a Schottky diode (pin to ground) to standard analog pins which may potentially inject negative current. Any positive injection current within the limits specified for  $I_{INJ(PIN)}$  and  $\Sigma I_{INJ(PIN)}$  in [Section 6.3.14](#) does not affect the ADC accuracy.
3. Better performance may be achieved in restricted  $V_{DDA}$ , frequency and temperature ranges.
4. Data based on characterization results, not tested in production.

Figure 24. ADC accuracy characteristics

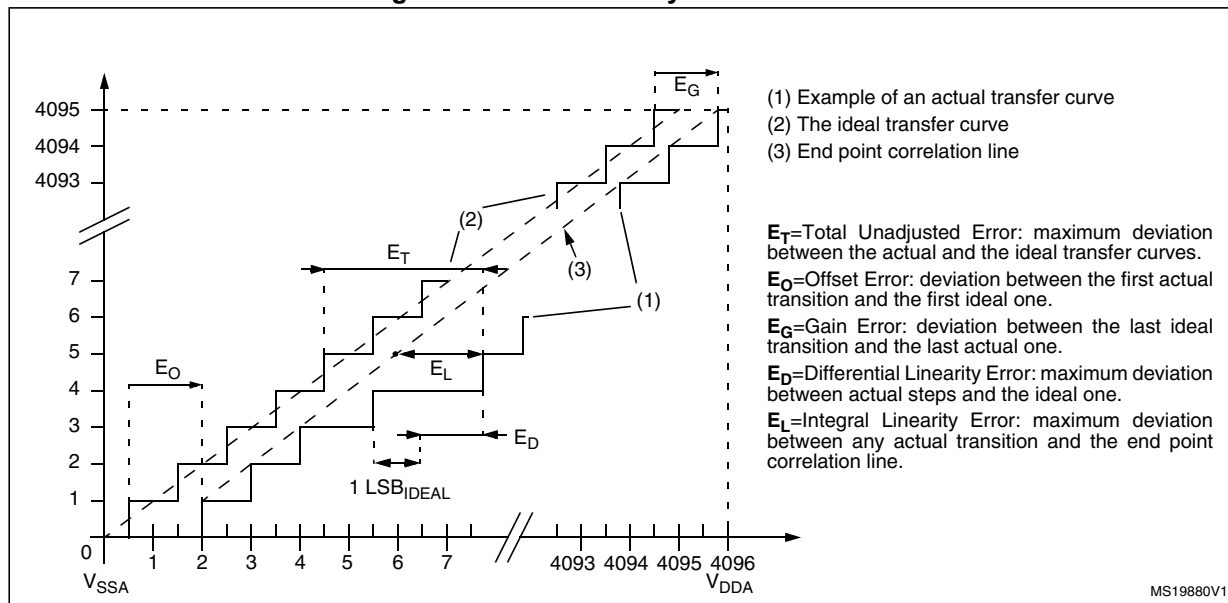
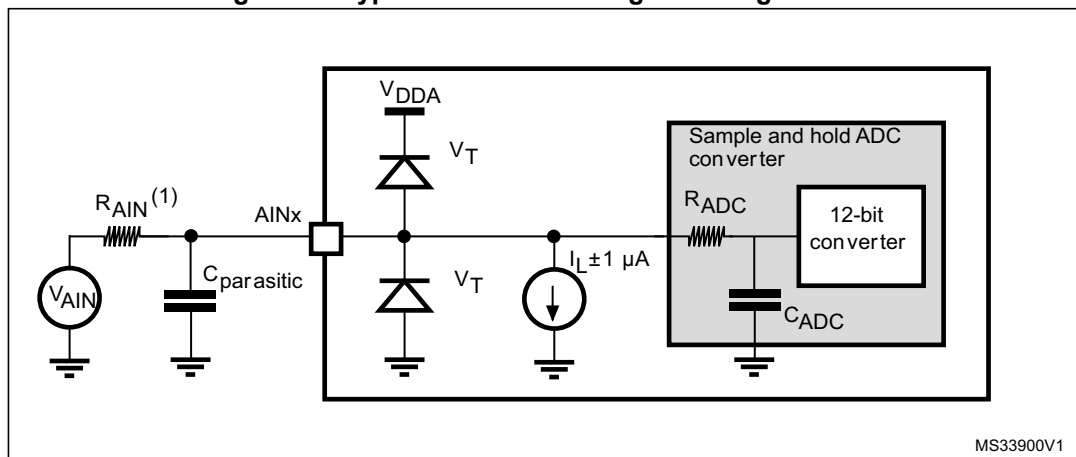


Figure 25. Typical connection diagram using the ADC



1. Refer to [Table 53: ADC characteristics](#) for the values of  $R_{AIN}$ ,  $R_{ADC}$  and  $C_{ADC}$ .
2.  $C_{parasitic}$  represents the capacitance of the PCB (dependent on soldering and PCB layout quality) plus the pad capacitance (roughly 7 pF). A high  $C_{parasitic}$  value will downgrade conversion accuracy. To remedy this,  $f_{ADC}$  should be reduced.

### General PCB design guidelines

Power supply decoupling should be performed as shown in [Figure 12: Power supply scheme](#). The 10 nF capacitor should be ceramic (good quality) and it should be placed as close as possible to the chip.

## 6.3.17 DAC electrical specifications

Table 56. DAC characteristics

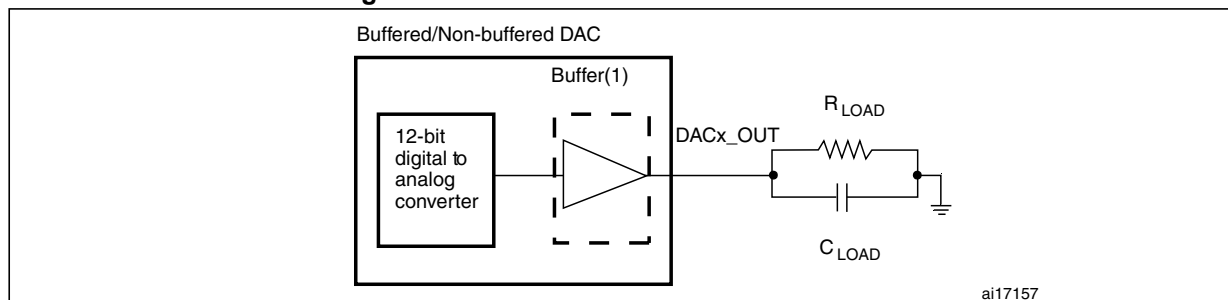
| Symbol                     | Parameter                                                                                                                                         | Min | Typ | Max                     | Unit       | Comments                                                                                                                                                                      |
|----------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------|-----|-----|-------------------------|------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| $V_{DDA}$                  | Analog supply voltage for DAC ON                                                                                                                  | 2.4 | -   | 3.6                     | V          |                                                                                                                                                                               |
| $R_{LOAD}^{(1)}$           | Resistive load with buffer ON                                                                                                                     | 5   | -   | -                       | k $\Omega$ | Load is referred to ground                                                                                                                                                    |
| $R_O^{(1)}$                | Impedance output with buffer OFF                                                                                                                  | -   | -   | 15                      | k $\Omega$ | When the buffer is OFF, the Minimum resistive load between DAC_OUT and $V_{SS}$ to have a 1% accuracy is 1.5 M $\Omega$                                                       |
| $C_{LOAD}^{(1)}$           | Capacitive load                                                                                                                                   | -   | -   | 50                      | pF         | Maximum capacitive load at DAC_OUT pin (when the buffer is ON).                                                                                                               |
| DAC_OUT min <sup>(1)</sup> | Lower DAC_OUT voltage with buffer ON                                                                                                              | 0.2 | -   | -                       | V          | It gives the maximum output excursion of the DAC.<br>It corresponds to 12-bit input code (0x0E0) to (0xF1C) at $V_{DDA} = 3.6$ V and (0x155) and (0xEAB) at $V_{DDA} = 2.4$ V |
| DAC_OUT max <sup>(1)</sup> | Higher DAC_OUT voltage with buffer ON                                                                                                             | -   | -   | $V_{DDA} - 0.2$         | V          |                                                                                                                                                                               |
| DAC_OUT min <sup>(1)</sup> | Lower DAC_OUT voltage with buffer OFF                                                                                                             | -   | 0.5 | -                       | mV         | It gives the maximum output excursion of the DAC.                                                                                                                             |
| DAC_OUT max <sup>(1)</sup> | Higher DAC_OUT voltage with buffer OFF                                                                                                            | -   | -   | $V_{DDA} - 1\text{LSB}$ | V          |                                                                                                                                                                               |
| $I_{DDA}^{(1)}$            | DAC DC current consumption in quiescent mode <sup>(2)</sup>                                                                                       | -   | -   | 380                     | $\mu$ A    | With no load, middle code (0x800) on the input                                                                                                                                |
|                            |                                                                                                                                                   | -   | -   | 480                     | $\mu$ A    | With no load, worst code (0xF1C) on the input                                                                                                                                 |
| DNL <sup>(3)</sup>         | Differential non linearity<br>Difference between two consecutive code-1LSB)                                                                       | -   | -   | $\pm 0.5$               | LSB        | Given for the DAC in 10-bit configuration                                                                                                                                     |
|                            |                                                                                                                                                   | -   | -   | $\pm 2$                 | LSB        | Given for the DAC in 12-bit configuration                                                                                                                                     |
| INL <sup>(3)</sup>         | Integral non linearity<br>(difference between measured value at Code i and the value at Code i on a line drawn between Code 0 and last Code 1023) | -   | -   | $\pm 1$                 | LSB        | Given for the DAC in 10-bit configuration                                                                                                                                     |
|                            |                                                                                                                                                   | -   | -   | $\pm 4$                 | LSB        | Given for the DAC in 12-bit configuration                                                                                                                                     |
| Offset <sup>(3)</sup>      | Offset error<br>(difference between measured value at Code (0x800) and the ideal value = $V_{DDA}/2$ )                                            | -   | -   | $\pm 10$                | mV         |                                                                                                                                                                               |
|                            |                                                                                                                                                   | -   | -   | $\pm 3$                 | LSB        | Given for the DAC in 10-bit at $V_{DDA} = 3.6$ V                                                                                                                              |
|                            |                                                                                                                                                   | -   | -   | $\pm 12$                | LSB        | Given for the DAC in 12-bit at $V_{DDA} = 3.6$ V                                                                                                                              |
| Gain error <sup>(3)</sup>  | Gain error                                                                                                                                        | -   | -   | $\pm 0.5$               | %          | Given for the DAC in 12-bit configuration                                                                                                                                     |

Table 56. DAC characteristics (continued)

| Symbol                      | Parameter                                                                                                                                                         | Min | Typ | Max | Unit          | Comments                                                                                                                              |
|-----------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----|-----|-----|---------------|---------------------------------------------------------------------------------------------------------------------------------------|
| $t_{\text{SETTLING}}^{(3)}$ | Settling time (full scale: for a 10-bit input code transition between the lowest and the highest input codes when DAC_OUT reaches final value $\pm 1\text{LSB}$ ) | -   | 3   | 4   | $\mu\text{s}$ | $C_{\text{LOAD}} \leq 50\text{ pF}$ , $R_{\text{LOAD}} \geq 5\text{ k}\Omega$                                                         |
| Update rate <sup>(3)</sup>  | Max frequency for a correct DAC_OUT change when small variation in the input code (from code i to i+1LSB)                                                         | -   | -   | 1   | MS/s          | $C_{\text{LOAD}} \leq 50\text{ pF}$ , $R_{\text{LOAD}} \geq 5\text{ k}\Omega$                                                         |
| $t_{\text{WAKEUP}}^{(3)}$   | Wakeup time from off state (Setting the ENx bit in the DAC Control register)                                                                                      | -   | 6.5 | 10  | $\mu\text{s}$ | $C_{\text{LOAD}} \leq 50\text{ pF}$ , $R_{\text{LOAD}} \geq 5\text{ k}\Omega$<br>input code between lowest and highest possible ones. |
| PSRR+ <sup>(1)</sup>        | Power supply rejection ratio (to $V_{\text{DDA}}$ ) (static DC measurement)                                                                                       | -   | -67 | -40 | dB            | No $R_{\text{LOAD}}$ , $C_{\text{LOAD}} = 50\text{ pF}$                                                                               |

1. Guaranteed by design, not tested in production.
2. The DAC is in “quiescent mode” when it keeps the value steady on the output so no dynamic consumption is involved.
3. Data based on characterization results, not tested in production.

Figure 26. 12-bit buffered / non-buffered DAC



1. The DAC integrates an output buffer that can be used to reduce the output impedance and to drive external loads directly without the use of an external operational amplifier. The buffer can be bypassed by configuring the BOFFx bit in the DAC\_CR register.

### 6.3.18 Comparator characteristics

Table 57. Comparator characteristics

| Symbol           | Parameter                                                   | Conditions                                            | Min <sup>(1)</sup>          | Typ     | Max <sup>(1)</sup> | Unit              |
|------------------|-------------------------------------------------------------|-------------------------------------------------------|-----------------------------|---------|--------------------|-------------------|
| $V_{DDA}$        | Analog supply voltage                                       |                                                       | 2                           | -       | 3.6                | V                 |
| $V_{IN}$         | Comparator input voltage range                              |                                                       | 0                           | -       | $V_{DDA}$          |                   |
| $V_{BG}$         | Scaler input voltage                                        |                                                       | -                           | 1.2     | -                  |                   |
| $V_{SC}$         | Scaler offset voltage                                       |                                                       | -                           | $\pm 5$ | $\pm 10$           | mV                |
| $t_{S\_SC}$      | Scaler startup time from power down                         |                                                       | -                           | -       | 0.1                | ms                |
| $t_{START}$      | Comparator startup time                                     | Startup time to reach propagation delay specification | -                           | -       | 60                 | $\mu s$           |
| $t_D$            | Propagation delay for 200 mV step with 100 mV overdrive     | Ultra-low power mode                                  | -                           | 2       | 4.5                | $\mu s$           |
|                  |                                                             | Low power mode                                        | -                           | 0.7     | 1.5                |                   |
|                  |                                                             | Medium power mode                                     | -                           | 0.3     | 0.6                |                   |
|                  |                                                             | High speed mode                                       | $V_{DDA} \geq 2.7\text{ V}$ |         | -                  | ns                |
|                  |                                                             |                                                       | $V_{DDA} < 2.7\text{ V}$    |         | -                  |                   |
|                  | Propagation delay for full range step with 100 mV overdrive | Ultra-low power mode                                  | -                           | 2       | 7                  | $\mu s$           |
|                  |                                                             | Low power mode                                        | -                           | 0.7     | 2.1                |                   |
|                  |                                                             | Medium power mode                                     | -                           | 0.3     | 1.2                |                   |
|                  |                                                             | High speed mode                                       | $V_{DDA} \geq 2.7\text{ V}$ |         | -                  | ns                |
|                  |                                                             |                                                       | $V_{DDA} < 2.7\text{ V}$    |         | -                  |                   |
|                  |                                                             |                                                       | -                           | 110     | 300                |                   |
| $V_{offset}$     | Comparator offset error                                     |                                                       | -                           | $\pm 4$ | $\pm 10$           | mV                |
| $dV_{offset}/dT$ | Offset error temperature coefficient                        |                                                       | -                           | 18      | -                  | $\mu V/^{\circ}C$ |
| $I_{DD(Comp)}$   | COMP current consumption                                    | Ultra-low power mode                                  | -                           | 1.2     | 1.5                | $\mu A$           |
|                  |                                                             | Low power mode                                        | -                           | 3       | 5                  |                   |
|                  |                                                             | Medium power mode                                     | -                           | 10      | 15                 |                   |
|                  |                                                             | High speed mode                                       | -                           | 75      | 100                |                   |

Table 57. Comparator characteristics (continued)

| Symbol           | Parameter             | Conditions                               | Min <sup>(1)</sup>    | Typ | Max <sup>(1)</sup> | Unit |
|------------------|-----------------------|------------------------------------------|-----------------------|-----|--------------------|------|
| $V_{\text{hys}}$ | Comparator hysteresis | No hysteresis<br>(COMPxHYST[1:0]=00)     | -                     | 0   | -                  | mV   |
|                  |                       | Low hysteresis<br>(COMPxHYST[1:0]=01)    | High speed mode       | 8   | 13                 |      |
|                  |                       |                                          | All other power modes |     | 10                 |      |
|                  |                       | Medium hysteresis<br>(COMPxHYST[1:0]=10) | High speed mode       | 15  | 26                 |      |
|                  |                       |                                          | All other power modes |     | 19                 |      |
|                  |                       | High hysteresis<br>(COMPxHYST[1:0]=11)   | High speed mode       | 31  | 49                 |      |
|                  |                       |                                          | All other power modes |     | 40                 |      |

1. Data based on characterization results, not tested in production.

### 6.3.19 Temperature sensor characteristics

Table 58. TS characteristics

| Symbol                        | Parameter                                      | Min  | Typ     | Max     | Unit  |
|-------------------------------|------------------------------------------------|------|---------|---------|-------|
| $T_L^{(1)}$                   | $V_{\text{SENSE}}$ linearity with temperature  | -    | $\pm 1$ | $\pm 2$ | °C    |
| Avg_Slope <sup>(1)</sup>      | Average slope                                  | 4.0  | 4.3     | 4.6     | mV/°C |
| $V_{30}$                      | Voltage at 30 °C ( $\pm 5$ °C) <sup>(2)</sup>  | 1.34 | 1.43    | 1.52    | V     |
| $t_{\text{START}}^{(1)}$      | Startup time                                   | 4    | -       | 10      | μs    |
| $T_{\text{S\_temp}}^{(1)(3)}$ | ADC sampling time when reading the temperature | 17.1 | -       | -       | μs    |

1. Guaranteed by design, not tested in production.

2. Measured at  $V_{\text{DDA}} = 3.3 \text{ V} \pm 10 \text{ mV}$ . The  $V_{30}$  ADC conversion result is stored in the TS\_CAL1 byte. Refer to [Table 3: Temperature sensor calibration values](#).

3. The shortest sampling time can be determined in the application by multiple iterations.

### 6.3.20 $V_{\text{BAT}}$ monitoring characteristics

Table 59.  $V_{\text{BAT}}$  monitoring characteristics

| Symbol                        | Parameter                                                                  | Min | Typ | Max | Unit |
|-------------------------------|----------------------------------------------------------------------------|-----|-----|-----|------|
| R                             | Resistor bridge for $V_{\text{BAT}}$                                       | -   | 50  | -   | kΩ   |
| Q                             | Ratio on $V_{\text{BAT}}$ measurement                                      | -   | 2   | -   |      |
| $E_r^{(1)}$                   | Error on Q                                                                 | -1  | -   | +1  | %    |
| $T_{\text{S\_vbat}}^{(1)(2)}$ | ADC sampling time when reading the $V_{\text{BAT}}$<br>(for 1 mV accuracy) | 5   | -   | -   | μs   |

1. Guaranteed by design, not tested in production.

2. The shortest sampling time can be determined in the application by multiple iterations.

### 6.3.21 Timer characteristics

The parameters given in the following tables are guaranteed by design.

Refer to [Section 6.3.14: I/O port characteristics](#) for details on the input/output alternate function characteristics (output compare, input capture, external clock, PWM output).

**Table 60. TIMx<sup>(1)</sup> characteristics**

| Symbol           | Parameter                                    | Conditions                    | Min    | Max                  | Unit          |
|------------------|----------------------------------------------|-------------------------------|--------|----------------------|---------------|
| $t_{res(TIM)}$   | Timer resolution time                        |                               | 1      | -                    | $t_{TIMxCLK}$ |
|                  |                                              | $f_{TIMxCLK} = 48\text{ MHz}$ | 20.8   | -                    | ns            |
| $f_{EXT}$        | Timer external clock frequency on CH1 to CH4 |                               | 0      | $f_{TIMxCLK}/2$      | MHz           |
|                  |                                              | $f_{TIMxCLK} = 48\text{ MHz}$ | 0      | 24                   | MHz           |
| $Res_{TIM}$      | Timer resolution                             | TIMx (except TIM2)            | -      | 16                   | bit           |
|                  |                                              | TIM2                          | -      | 32                   |               |
| $t_{COUNTER}$    | 16-bit counter clock period                  |                               | 1      | 65536                | $t_{TIMxCLK}$ |
|                  |                                              | $f_{TIMxCLK} = 48\text{ MHz}$ | 0.0208 | 1365                 | $\mu s$       |
| $t_{MAX\_COUNT}$ | Maximum possible count with 32-bit counter   |                               | -      | $65536 \times 65536$ | $t_{TIMxCLK}$ |
|                  |                                              | $f_{TIMxCLK} = 48\text{ MHz}$ | -      | 89.48                | s             |

1. TIMx is used as a general term to refer to the TIM1, TIM2, TIM3, TIM6, TIM14, TIM15, TIM16 and TIM17 timers.

**Table 61. IWDG min/max timeout period at 40 kHz (LSI)<sup>(1)</sup>**

| Prescaler divider | PR[2:0] bits | Min timeout RL[11:0]= 0x000 | Max timeout RL[11:0]= 0xFFFF | Unit |
|-------------------|--------------|-----------------------------|------------------------------|------|
| /4                | 0            | 0.1                         | 409.6                        | ms   |
| /8                | 1            | 0.2                         | 819.2                        |      |
| /16               | 2            | 0.4                         | 1638.4                       |      |
| /32               | 3            | 0.8                         | 3276.8                       |      |
| /64               | 4            | 1.6                         | 6553.6                       |      |
| /128              | 5            | 3.2                         | 13107.2                      |      |
| /256              | 6 or 7       | 6.4                         | 26214.4                      |      |

1. These timings are given for a 40 kHz clock but the microcontroller's internal RC frequency can vary from 30 to 60 kHz. Moreover, given an exact RC oscillator frequency, the exact timings still depend on the phasing of the APB interface clock versus the LSI clock so that there is always a full RC period of uncertainty.

Table 62. WWDG min/max timeout value at 48 MHz (PCLK)

| Prescaler | WDGTB | Min timeout value | Max timeout value | Unit |
|-----------|-------|-------------------|-------------------|------|
| 1         | 0     | 0.0853            | 5.4613            | ms   |
| 2         | 1     | 0.1706            | 10.9226           |      |
| 4         | 2     | 0.3413            | 21.8453           |      |
| 8         | 3     | 0.6826            | 43.6906           |      |

### 6.3.22 Communication interfaces

#### I<sup>2</sup>C interface characteristics

The I<sup>2</sup>C interface meets the requirements of the standard I<sup>2</sup>C communication protocol with the following restrictions: the I/O pins SDA and SCL are mapped to are not “true” open-drain. When configured as open-drain, the PMOS connected between the I/O pin and V<sub>DDIOx</sub> is disabled, but is still present.

The I<sup>2</sup>C characteristics are described in [Table 63](#). Refer also to [Section 6.3.14: I/O port characteristics](#) for more details on the input/output alternate function characteristics (SDA and SCL).

Table 63. I2C characteristics<sup>(1)</sup>

| Symbol              | Parameter                                        | Standard |                     | Fast mode |                    | Fast mode + |                     | Unit |
|---------------------|--------------------------------------------------|----------|---------------------|-----------|--------------------|-------------|---------------------|------|
|                     |                                                  | Min      | Max                 | Min       | Max                | Min         | Max                 |      |
| f <sub>SCL</sub>    | SCL clock frequency                              | 0        | 100                 | 0         | 400                | 0           | 1000                | KHz  |
| t <sub>LOW</sub>    | Low period of the SCL clock                      | 4.7      | -                   | 1.3       | -                  | 0.5         | -                   | μs   |
| t <sub>HIGH</sub>   | High Period of the SCL clock                     | 4        | -                   | 0.6       | -                  | 0.26        | -                   | μs   |
| t <sub>r</sub>      | Rise time of both SDA and SCL signals            | -        | 1000                | -         | 300                | -           | 120                 | ns   |
| t <sub>f</sub>      | Fall time of both SDA and SCL signals            | -        | 300                 | -         | 300                | -           | 120                 | ns   |
| t <sub>HD;DAT</sub> | Data hold time                                   | 0        | -                   | 0         | -                  | 0           | -                   | μs   |
| t <sub>VD;DAT</sub> | Data valid time                                  | -        | 3.45 <sup>(2)</sup> | -         | 0.9 <sup>(2)</sup> | -           | 0.45 <sup>(2)</sup> | μs   |
| t <sub>VD;ACK</sub> | Data valid acknowledge time                      | -        | 3.45 <sup>(2)</sup> | -         | 0.9 <sup>(2)</sup> | -           | 0.45 <sup>(2)</sup> | μs   |
| t <sub>SU;DAT</sub> | Data setup time                                  | 250      | -                   | 100       | -                  | 50          | -                   | ns   |
| t <sub>HD;STA</sub> | Hold time (repeated) START condition             | 4.0      | -                   | 0.6       | -                  | 0.26        | -                   | μs   |
| t <sub>SU;STA</sub> | Set-up time for a repeated START condition       | 4.7      | -                   | 0.6       | -                  | 0.26        | -                   | μs   |
| t <sub>SU;STO</sub> | Set-up time for STOP condition                   | 4.0      | -                   | 0.6       | -                  | 0.26        | -                   | μs   |
| t <sub>BUF</sub>    | Bus free time between a STOP and START condition | 4.7      | -                   | 1.3       | -                  | 0.5         | -                   | μs   |



Table 63. I2C characteristics<sup>(1)</sup> (continued)

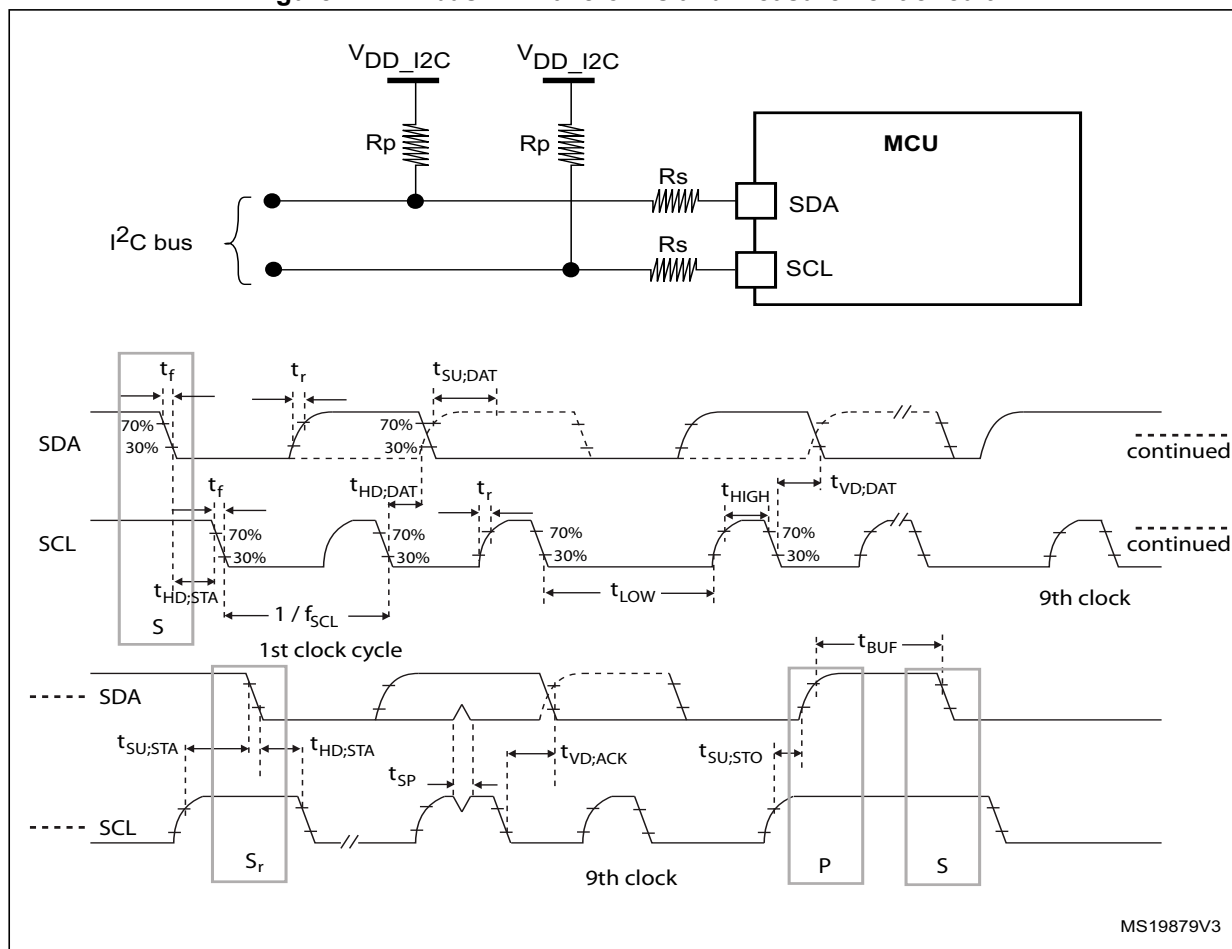
| Symbol   | Parameter                                                      | Standard |                   | Fast mode |                   | Fast mode + |                   | Unit |
|----------|----------------------------------------------------------------|----------|-------------------|-----------|-------------------|-------------|-------------------|------|
|          |                                                                | Min      | Max               | Min       | Max               | Min         | Max               |      |
| $C_b$    | Capacitive load for each bus line                              | -        | 400               | -         | 400               | -           | 550               | pF   |
| $t_{SP}$ | Pulse width of spikes that are suppressed by the analog filter | 0        | 50 <sup>(3)</sup> | 0         | 50 <sup>(3)</sup> | 0           | 50 <sup>(3)</sup> | ns   |

1. The I2C characteristics are the requirements from the I2C bus specification rev03. They are guaranteed by design when the I2Cx\_TIMING register is correctly programmed (refer to reference manual). These characteristics are not tested in production.
2. The maximum  $t_{HD;DAT}$  could be 3.45  $\mu$ s, 0.9  $\mu$ s and 0.45  $\mu$ s for standard mode, fast mode and fast mode plus, but must be less than the maximum of  $t_{VD;DAT}$  or  $t_{VD;ACK}$  by a transition time.
3. The minimum width of the spikes filtered by the analog filter is above  $t_{SP(max)}$ .

Table 64. I2C analog filter characteristics<sup>(1)</sup>

| Symbol   | Parameter                                                              | Min               | Max                | Unit |
|----------|------------------------------------------------------------------------|-------------------|--------------------|------|
| $t_{AF}$ | Maximum pulse width of spikes that are suppressed by the analog filter | 50 <sup>(2)</sup> | 260 <sup>(3)</sup> | ns   |

1. Guaranteed by design, not tested in production.
2. Spikes with widths below  $t_{AF(min)}$  are filtered.
3. Spikes with widths above  $t_{AF(max)}$  are not filtered

Figure 27. I<sup>2</sup>C bus AC waveforms and measurement circuit

Legend: Rs: Series protection resistors. Rp: Pull-up resistors.  $V_{DD\_I2C}$ : I<sup>2</sup>C bus supply.

### SPI/I<sup>2</sup>S characteristics

Unless otherwise specified, the parameters given in [Table 65](#) for SPI or in [Table 66](#) for I<sup>2</sup>S are derived from tests performed under the ambient temperature,  $f_{PCLKx}$  frequency and supply voltage conditions summarized in [Table 20: General operating conditions](#).

Refer to [Section 6.3.14: I/O port characteristics](#) for more details on the input/output alternate function characteristics (NSS, SCK, MOSI, MISO for SPI and WS, CK, SD for I<sup>2</sup>S).

Table 65. SPI characteristics<sup>(1)</sup>

| Symbol                       | Parameter                    | Conditions                 | Min | Max | Unit |
|------------------------------|------------------------------|----------------------------|-----|-----|------|
| $f_{SCK}$<br>$1/t_{c(SCK)}$  | SPI clock frequency          | Master mode                | -   | 18  | MHz  |
|                              |                              | Slave mode                 | -   | 18  |      |
| $t_{r(SCK)}$<br>$t_{f(SCK)}$ | SPI clock rise and fall time | Capacitive load: C = 15 pF | -   | 6   | ns   |

Table 65. SPI characteristics<sup>(1)</sup> (continued)

| Symbol                         | Parameter                        | Conditions                                     | Min         | Max         | Unit |
|--------------------------------|----------------------------------|------------------------------------------------|-------------|-------------|------|
| $t_{su(NSS)}$                  | NSS setup time                   | Slave mode                                     | 4Tpclk      | -           | ns   |
| $t_{h(NSS)}$                   | NSS hold time                    | Slave mode                                     | 2Tpclk + 10 | -           |      |
| $t_{w(SCKH)}$<br>$t_{w(SCKL)}$ | SCK high and low time            | Master mode, $f_{PCLK} = 36$ MHz,<br>presc = 4 | Tpclk/2 - 2 | Tpclk/2 + 1 |      |
| $t_{su(MI)}$<br>$t_{su(SI)}$   | Data input setup time            | Master mode                                    | 4           | -           |      |
|                                |                                  | Slave mode                                     | 5           | -           |      |
| $t_{h(MI)}$<br>$t_{h(SI)}$     | Data input hold time             | Master mode                                    | 4           | -           |      |
|                                |                                  | Slave mode                                     | 5           | -           |      |
| $t_{a(SO)}^{(2)}$              | Data output access time          | Slave mode, $f_{PCLK} = 20$ MHz                | 0           | 3Tpclk      |      |
| $t_{dis(SO)}^{(3)}$            | Data output disable time         | Slave mode                                     | 0           | 18          |      |
| $t_{v(SO)}$                    | Data output valid time           | Slave mode (after enable edge)                 | -           | 22.5        |      |
| $t_{v(MO)}$                    | Data output valid time           | Master mode (after enable edge)                | -           | 6           |      |
| $t_{h(SO)}$<br>$t_{h(MO)}$     | Data output hold time            | Slave mode (after enable edge)                 | 11.5        | -           |      |
|                                |                                  | Master mode (after enable edge)                | 2           | -           |      |
| DuCy(SCK)                      | SPI slave input clock duty cycle | Slave mode                                     | 25          | 75          | %    |

1. Data based on characterization results, not tested in production.

2. Min time is for the minimum time to drive the output and the max time is for the maximum time to validate the data.

3. Min time is for the minimum time to invalidate the output and the max time is for the maximum time to put the data in Hi-Z

Figure 28. SPI timing diagram - slave mode and CPHA = 0

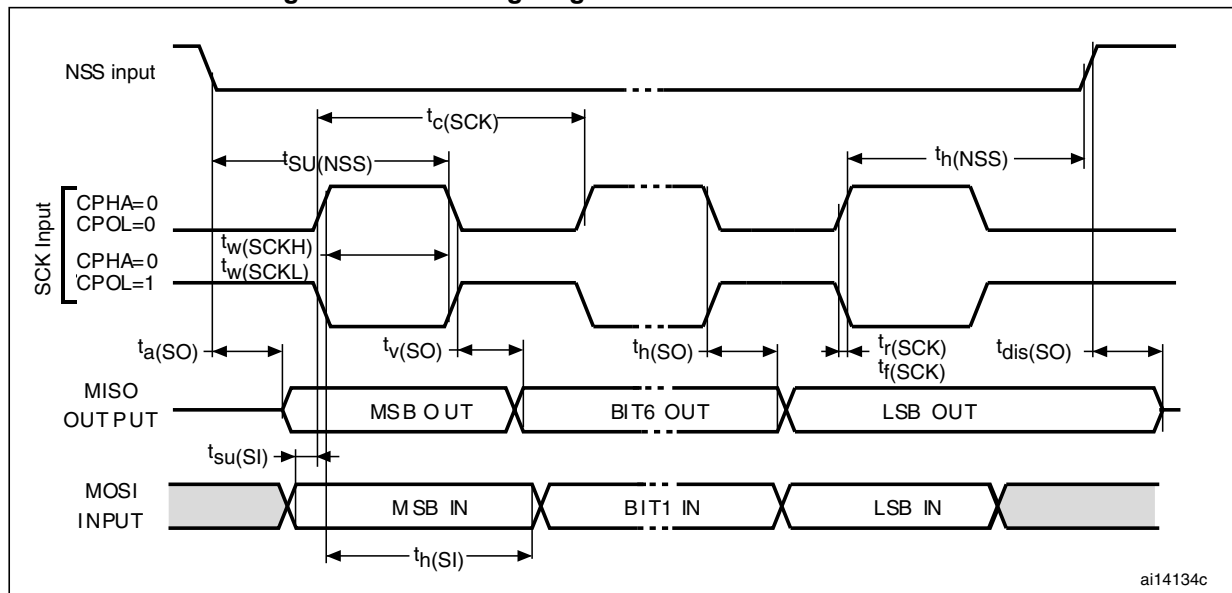
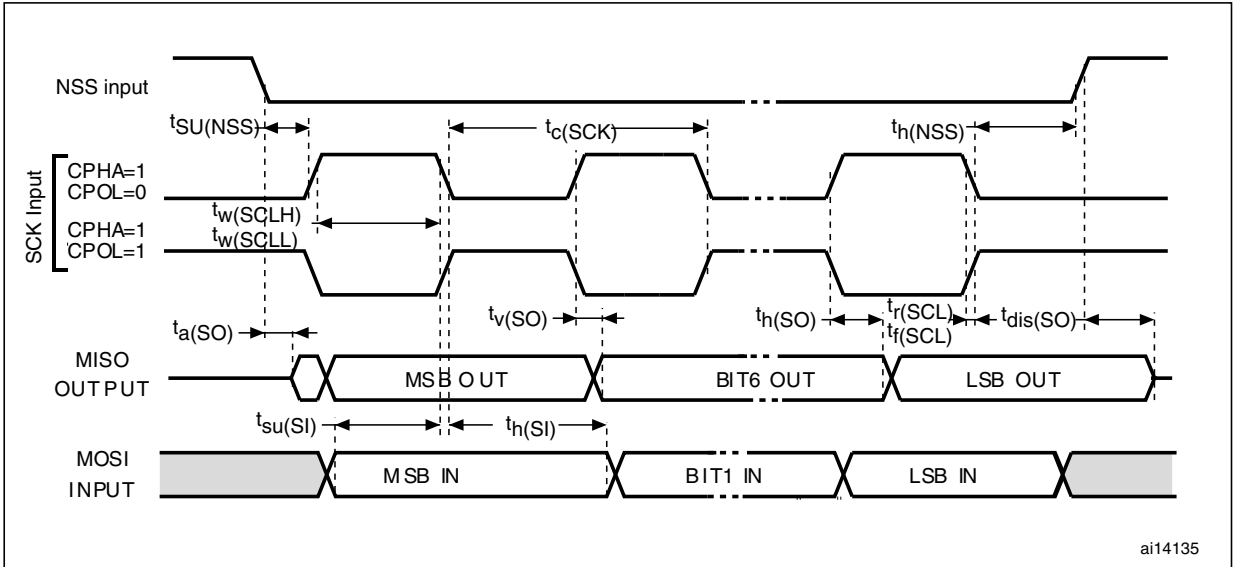
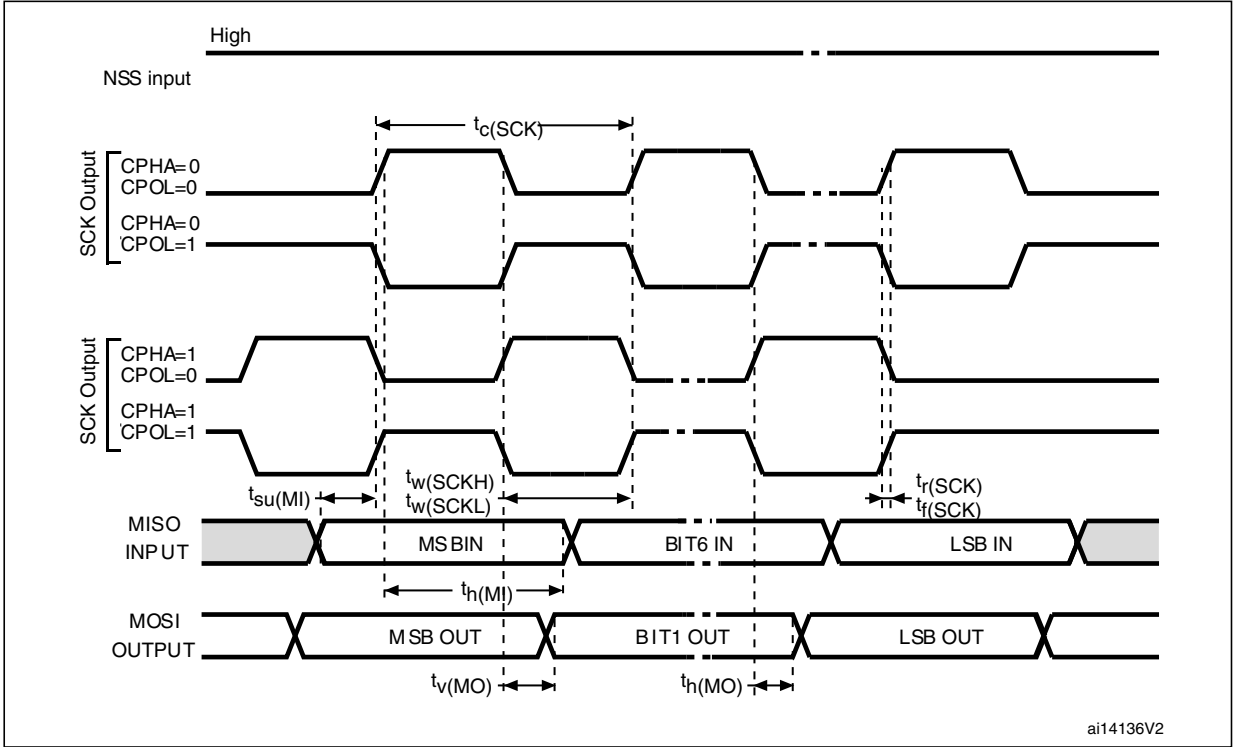


Figure 29. SPI timing diagram - slave mode and CPHA = 1



1. Measurement points are done at CMOS levels: 0.3  $V_{DD}$  and 0.7  $V_{DD}$ .

Figure 30. SPI timing diagram - master mode



1. Measurement points are done at CMOS levels: 0.3  $V_{DD}$  and 0.7  $V_{DD}$ .

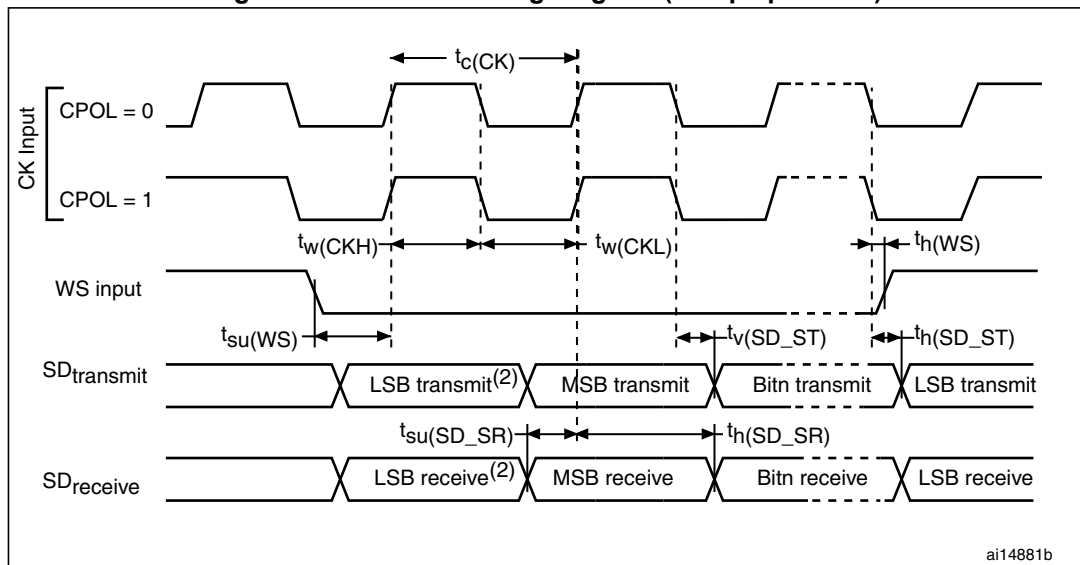
Table 66. I<sup>2</sup>S characteristics<sup>(1)</sup>

| Symbol                    | Parameter                        | Conditions                                            | Min   | Max   | Unit |
|---------------------------|----------------------------------|-------------------------------------------------------|-------|-------|------|
| $f_{CK}$<br>$1/t_{c(CK)}$ | I <sup>2</sup> S clock frequency | Master mode (data: 16 bits, Audio frequency = 48 kHz) | 1.597 | 1.601 | MHz  |
|                           |                                  | Slave mode                                            | 0     | 6.5   |      |
| $t_{r(CK)}$               | I <sup>2</sup> S clock rise time | Capacitive load $C_L = 15$ pF                         | -     | 10    | ns   |
| $t_{f(CK)}$               | I <sup>2</sup> S clock fall time |                                                       | -     | 12    |      |
| $t_{w(CKH)}$              | I2S clock high time              | Master $f_{PCLK} = 16$ MHz, audio frequency = 48 kHz  | 306   | -     |      |
| $t_{w(CKL)}$              | I2S clock low time               |                                                       | 312   | -     |      |
| $t_{v(WS)}$               | WS valid time                    | Master mode                                           | 2     | -     |      |
| $t_{h(WS)}$               | WS hold time                     | Master mode                                           | 2     | -     |      |
| $t_{su(WS)}$              | WS setup time                    | Slave mode                                            | 7     | -     |      |
| $t_{h(WS)}$               | WS hold time                     | Slave mode                                            | 0     | -     |      |
| DuCy(SCK)                 | I2S slave input clock duty cycle | Slave mode                                            | 25    | 75    | %    |
| $t_{su(SD\_MR)}$          | Data input setup time            | Master receiver                                       | 6     | -     | ns   |
| $t_{su(SD\_SR)}$          | Data input setup time            | Slave receiver                                        | 2     | -     |      |
| $t_{h(SD\_MR)}^{(2)}$     | Data input hold time             | Master receiver                                       | 4     | -     |      |
| $t_{h(SD\_SR)}^{(2)}$     |                                  | Slave receiver                                        | 0.5   | -     |      |
| $t_{v(SD\_ST)}^{(2)}$     | Data output valid time           | Slave transmitter (after enable edge)                 | -     | 20    |      |
| $t_{h(SD\_ST)}$           | Data output hold time            | Slave transmitter (after enable edge)                 | 13    | -     |      |
| $t_{v(SD\_MT)}^{(2)}$     | Data output valid time           | Master transmitter (after enable edge)                | -     | 4     |      |
| $t_{h(SD\_MT)}$           | Data output hold time            | Master transmitter (after enable edge)                | 0     | -     |      |

1. Data based on design simulation and/or characterization results, not tested in production.

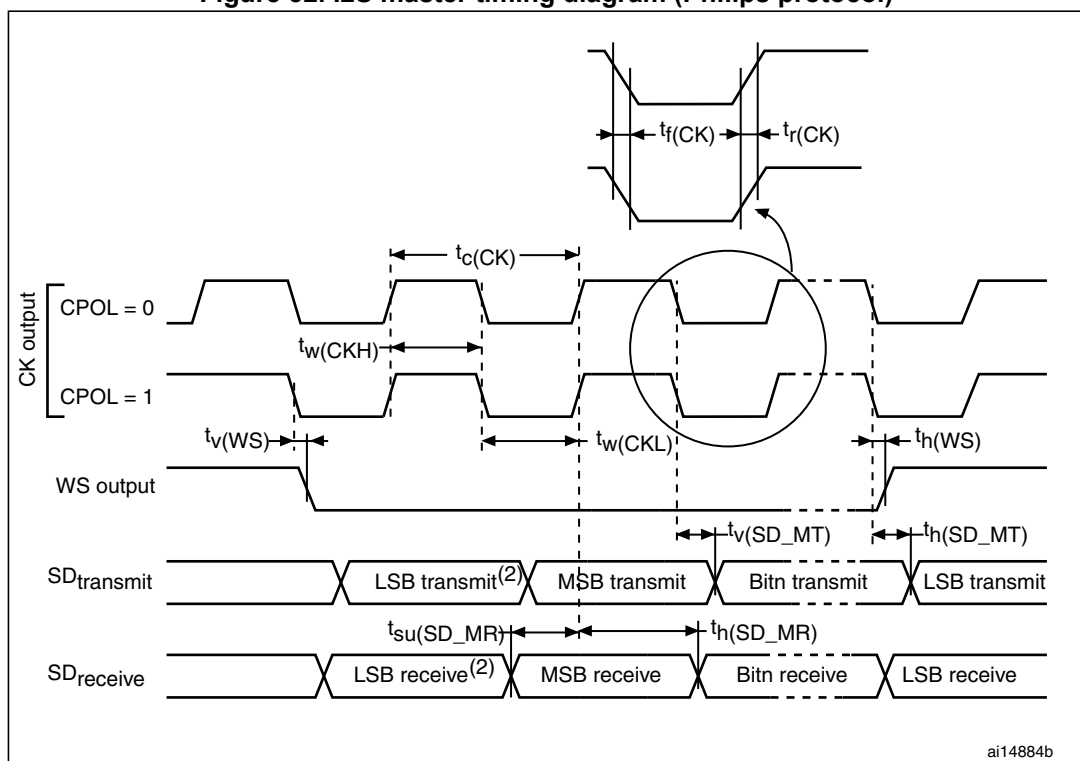
2. Depends on  $f_{PCLK}$ . For example, if  $f_{PCLK} = 8$  MHz, then  $T_{PCLK} = 1/f_{PCLK} = 125$  ns.

Figure 31. I2S slave timing diagram (Philips protocol)



1. Measurement points are done at CMOS levels:  $0.3 \times V_{DDIOx}$  and  $0.7 \times V_{DDIOx}$ .
2. LSB transmit/receive of the previously transmitted byte. No LSB transmit/receive is sent before the first byte.

Figure 32. I2S master timing diagram (Philips protocol)



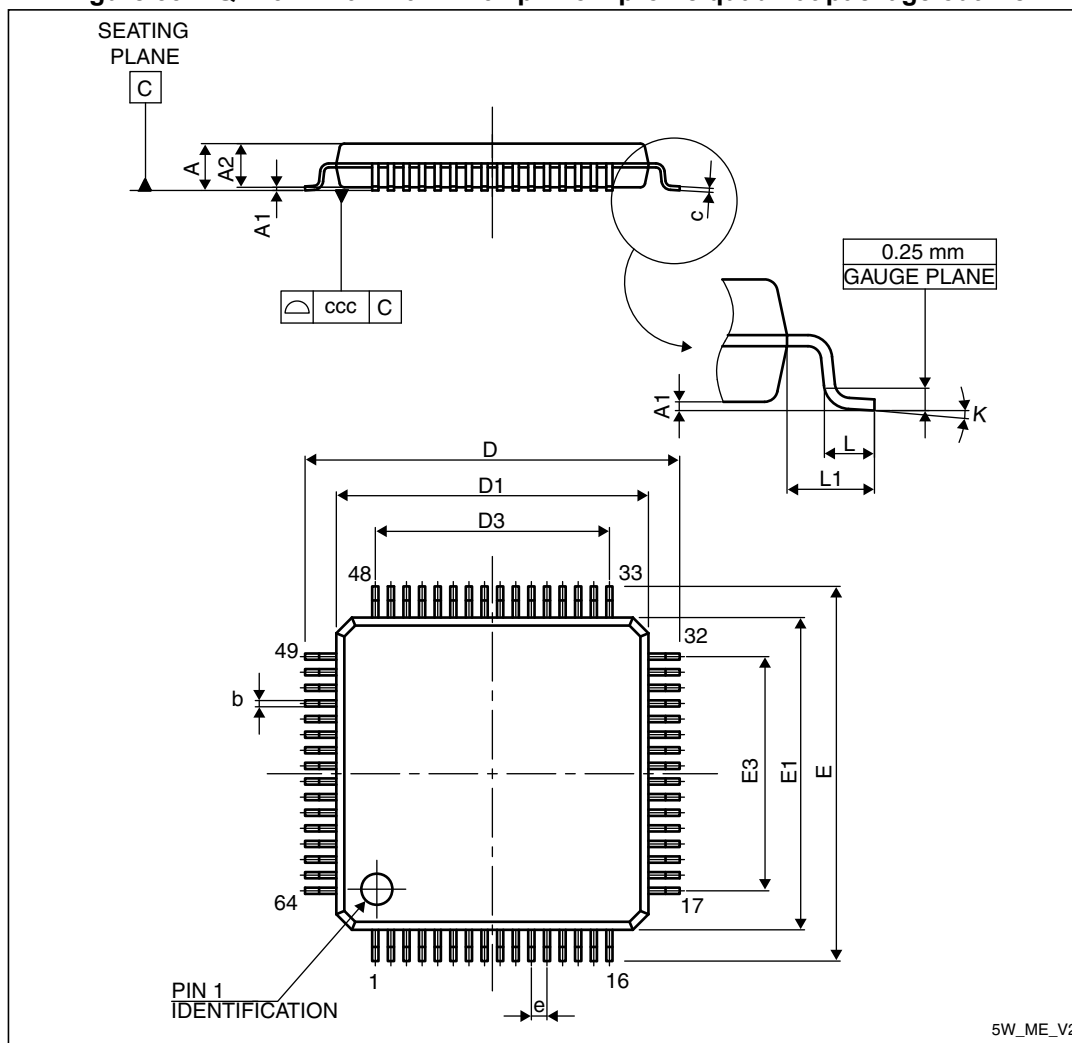
1. Data based on characterization results, not tested in production.
2. LSB transmit/receive of the previously transmitted byte. No LSB transmit/receive is sent before the first byte.

## 7 Package characteristics

### 7.1 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK<sup>®</sup> is an ST trademark.

Figure 33. LQFP64 – 10 x 10 mm 64 pin low-profile quad flat package outline



1. Drawing is not to scale.

Table 67. LQFP64 – 10 x 10 mm 64 pin low-profile quad flat package mechanical data

| Symbol | millimeters |        |        | inches <sup>(1)</sup> |        |        |
|--------|-------------|--------|--------|-----------------------|--------|--------|
|        | Min         | Typ    | Max    | Min                   | Typ    | Max    |
| A      | -           | -      | 1.600  | -                     | -      | 0.0630 |
| A1     | 0.050       | -      | 0.150  | 0.0020                | -      | 0.0059 |
| A2     | 1.350       | 1.400  | 1.450  | 0.0531                | 0.0551 | 0.0571 |
| b      | 0.170       | 0.220  | 0.270  | 0.0067                | 0.0087 | 0.0106 |
| c      | 0.090       | -      | 0.200  | 0.0035                | -      | 0.0079 |
| D      | 11.800      | 12.000 | 12.200 | 0.4646                | 0.4724 | 0.4803 |
| D1     | 9.800       | 10.000 | 10.200 | 0.3858                | 0.3937 | 0.4016 |
| D.     | -           | 7.500  | -      | -                     | -      | -      |

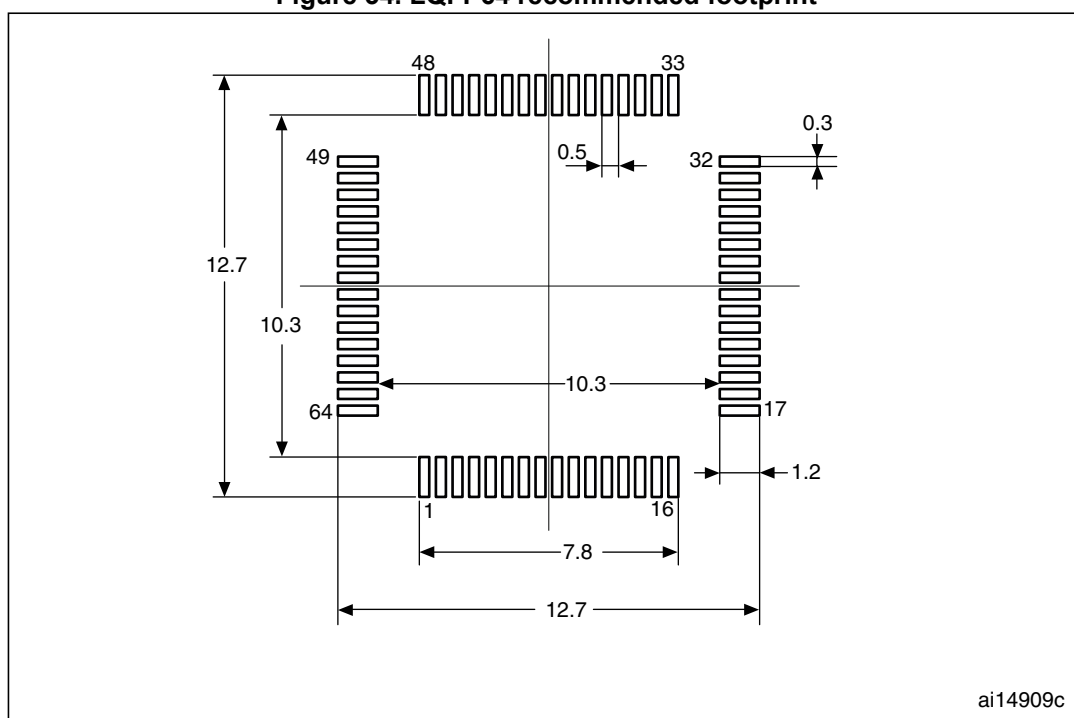


**Table 67. LQFP64 – 10 x 10 mm 64 pin low-profile quad flat package mechanical data (continued)**

| Symbol | millimeters |        |        | inches <sup>(1)</sup> |        |        |
|--------|-------------|--------|--------|-----------------------|--------|--------|
|        | Min         | Typ    | Max    | Min                   | Typ    | Max    |
| E      | 11.800      | 12.000 | 12.200 | 0.4646                | 0.4724 | 0.4803 |
| E1     | 9.800       | 10.000 | 10.200 | 0.3858                | 0.3937 | 0.4016 |
| e      | -           | 0.500  | -      | -                     | 0.0197 | -      |
| k      | 0°          | 3.5°   | 7°     | 0°                    | 3.5°   | 7°     |
| L      | 0.450       | 0.600  | 0.750  | 0.0177                | 0.0236 | 0.0295 |
| L1     | -           | 1.000  | -      | -                     | 0.0394 | -      |
| ccc    | 0.080       |        |        | 0.0031                |        |        |

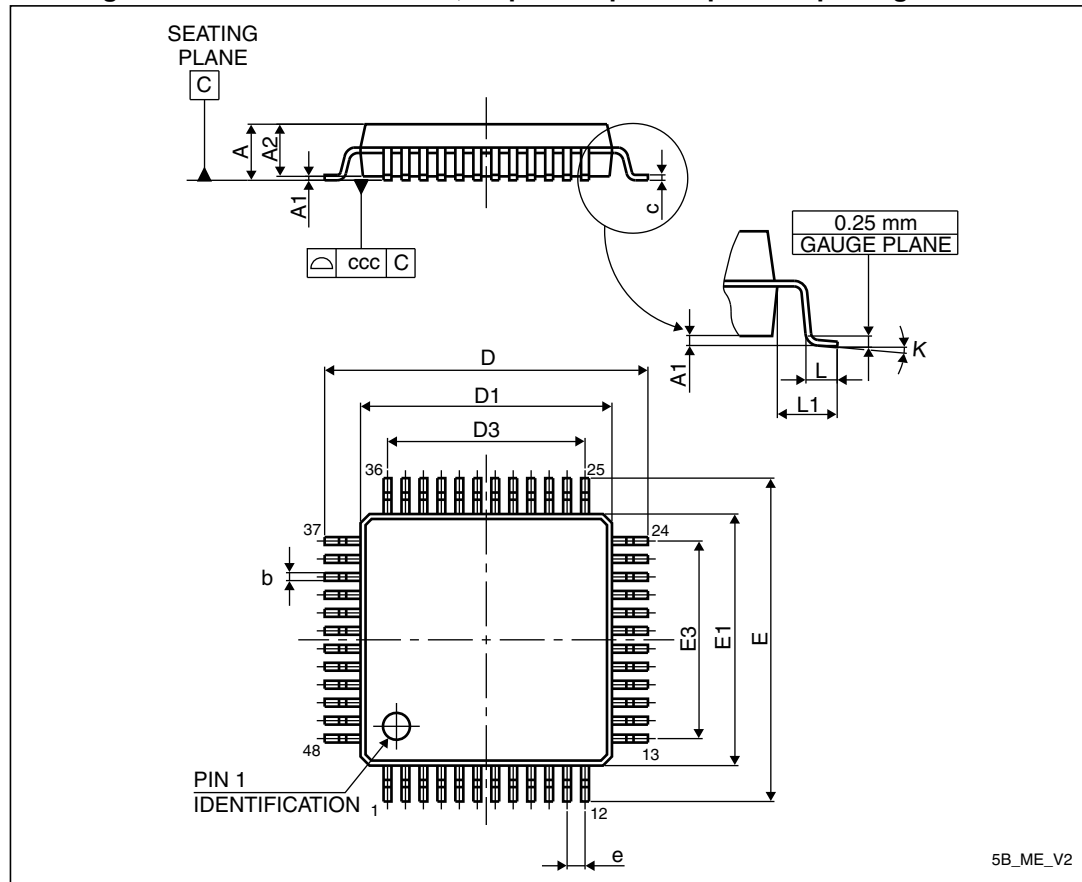
1. Values in inches are converted from mm and rounded to 4 decimal digits.

**Figure 34. LQFP64 recommended footprint**



1. Drawing is not to scale.
2. Dimensions are in millimeters.

Figure 35. LQFP48 – 7 x 7 mm, 48 pin low-profile quad flat package outline



1. Drawing is not to scale.

Table 68. LQFP48 – 7 x 7 mm, 48-pin low-profile quad flat package mechanical data

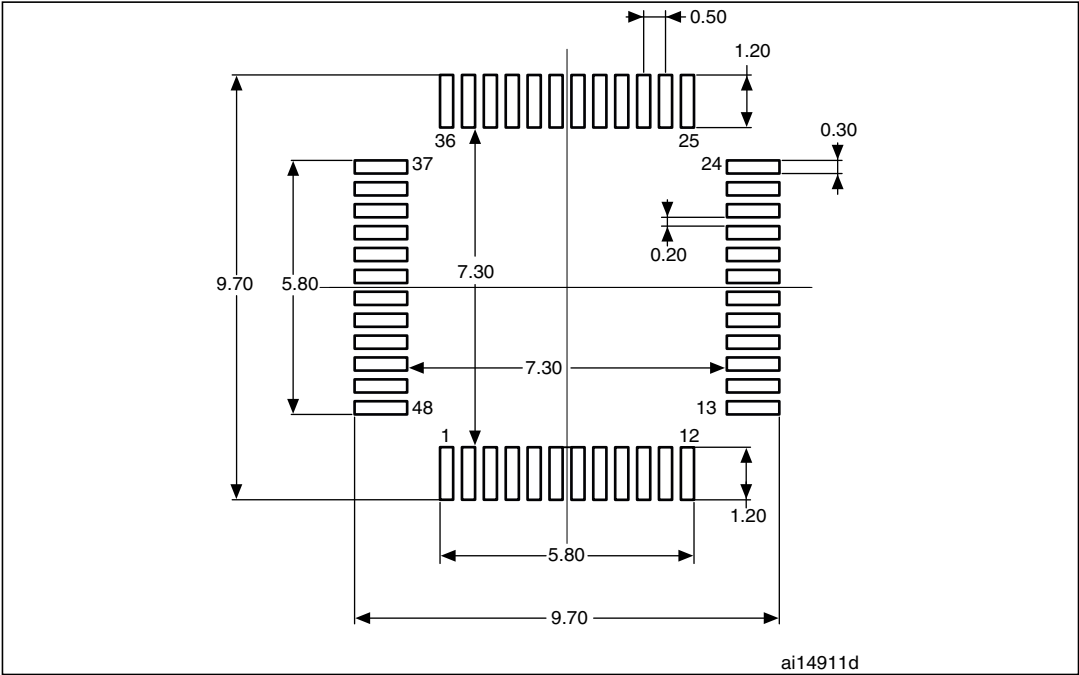
| Symbol | millimeters |       |       | inches <sup>(1)</sup> |        |        |
|--------|-------------|-------|-------|-----------------------|--------|--------|
|        | Min         | Typ   | Max   | Min                   | Typ    | Max    |
| A      | -           | -     | 1.600 | -                     | -      | 0.0630 |
| A1     | 0.050       | -     | 0.150 | 0.0020                | -      | 0.0059 |
| A2     | 1.350       | 1.400 | 1.450 | 0.0531                | 0.0551 | 0.0571 |
| b      | 0.170       | 0.220 | 0.270 | 0.0067                | 0.0087 | 0.0106 |
| c      | 0.090       | -     | 0.200 | 0.0035                | -      | 0.0079 |
| D      | 8.800       | 9.000 | 9.200 | 0.3465                | 0.3543 | 0.3622 |
| D1     | 6.800       | 7.000 | 7.200 | 0.2677                | 0.2756 | 0.2835 |
| D3     | -           | 5.500 | -     | -                     | 0.2165 | -      |
| E      | 8.800       | 9.000 | 9.200 | 0.3465                | 0.3543 | 0.3622 |
| E1     | 6.800       | 7.000 | 7.200 | 0.2677                | 0.2756 | 0.2835 |
| E3     | -           | 5.500 | -     | -                     | 0.2165 | -      |
| e      | -           | 0.500 | -     | -                     | 0.0197 | -      |
| L      | 0.450       | 0.600 | 0.750 | 0.0177                | 0.0236 | 0.0295 |

Table 68. LQFP48 – 7 x 7 mm, 48-pin low-profile quad flat package mechanical data (continued)

| Symbol | millimeters |       |     | inches <sup>(1)</sup> |        |     |
|--------|-------------|-------|-----|-----------------------|--------|-----|
|        | Min         | Typ   | Max | Min                   | Typ    | Max |
| L1     | -           | 1.000 | -   | -                     | 0.0394 | -   |
| k      | 0°          | 3.5°  | 7°  | 0°                    | 3.5°   | 7°  |
| ccc    | 0.080       |       |     | 0.0031                |        |     |

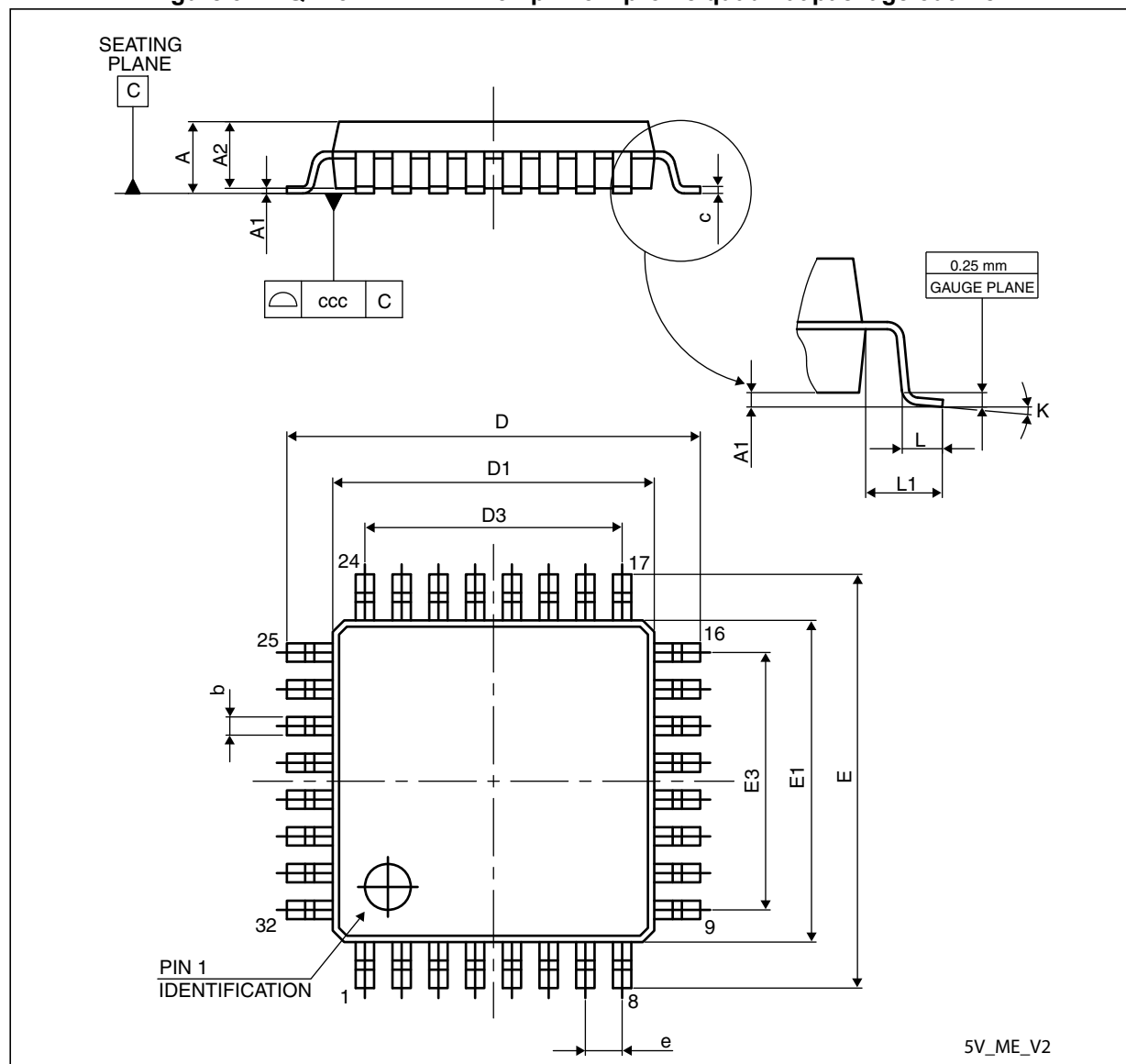
1. Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 36. LQFP48 recommended footprint



- 1. Drawing is not to scale.
- 2. Dimensions are in millimeters.

Figure 37. LQFP32 – 7 x 7mm 32-pin low-profile quad flat package outline



1. Drawing is not to scale.

Table 69. LQFP32 – 7 x 7mm 32-pin low-profile quad flat package mechanical data

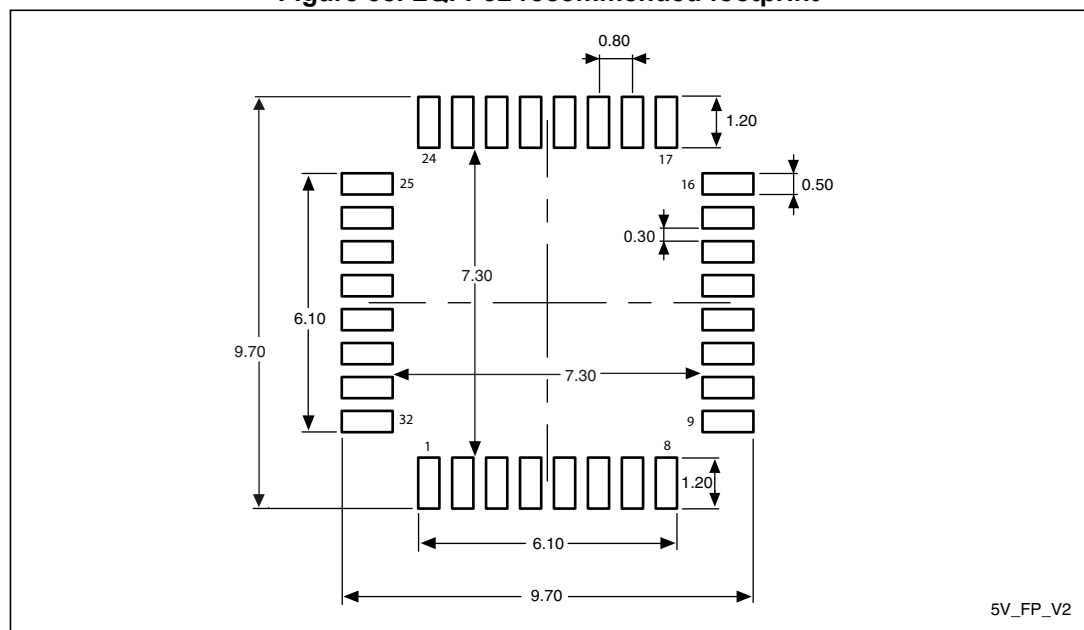
| Symbol | millimeters |       |       | inches <sup>(1)</sup> |        |        |
|--------|-------------|-------|-------|-----------------------|--------|--------|
|        | Min         | Typ   | Max   | Min                   | Typ    | Max    |
| A      | -           | -     | 1.600 | -                     | -      | 0.0630 |
| A1     | 0.050       | -     | 0.150 | 0.0020                | -      | 0.0059 |
| A2     | 1.350       | 1.400 | 1.450 | 0.0531                | 0.0551 | 0.0571 |
| b      | 0.300       | 0.370 | 0.450 | 0.0118                | 0.0146 | 0.0177 |
| c      | 0.090       | -     | 0.200 | 0.0035                | -      | 0.0079 |
| D      | 8.800       | 9.000 | 9.200 | 0.3465                | 0.3543 | 0.3622 |

Table 69. LQFP32 – 7 x 7mm 32-pin low-profile quad flat package mechanical data (continued)

| Symbol | millimeters |       |       | inches <sup>(1)</sup> |        |        |
|--------|-------------|-------|-------|-----------------------|--------|--------|
|        | Min         | Typ   | Max   | Min                   | Typ    | Max    |
| D1     | 6.800       | 7.000 | 7.200 | 0.2677                | 0.2756 | 0.2835 |
| D3     | -           | 5.600 | -     | -                     | 0.2205 | -      |
| E      | 8.800       | 9.000 | 9.200 | 0.3465                | 0.3543 | 0.3622 |
| E1     | 6.800       | 7.000 | 7.200 | 0.2677                | 0.2756 | 0.2835 |
| E3     | -           | 5.600 | -     | -                     | 0.2205 | -      |
| e      | -           | 0.800 | -     | -                     | 0.0315 | -      |
| L      | 0.450       | 0.600 | 0.750 | 0.0177                | 0.0236 | 0.0295 |
| L1     | -           | 1.000 | -     | -                     | 0.0394 | -      |
| k      | 0.0°        | 3.5°  | 7.0°  | 0.0°                  | 3.5°   | 7.0°   |
| ccc    | -           | -     | 0.100 | -                     | -      | 0.0039 |

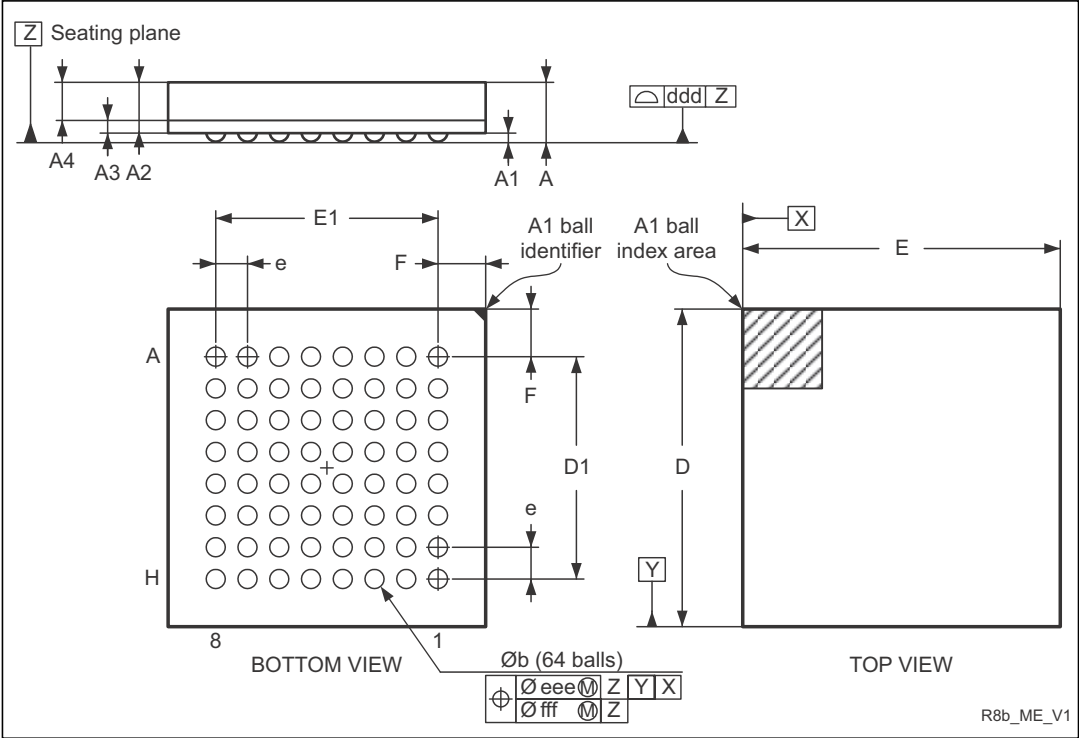
1. Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 38. LQFP32 recommended footprint



1. Drawing is not to scale.
2. Dimensions are in millimeters.

Figure 39. UFBGA64 - 5 x 5 mm, 0.5 mm pitch, package outline



1. Drawing is not to scale.

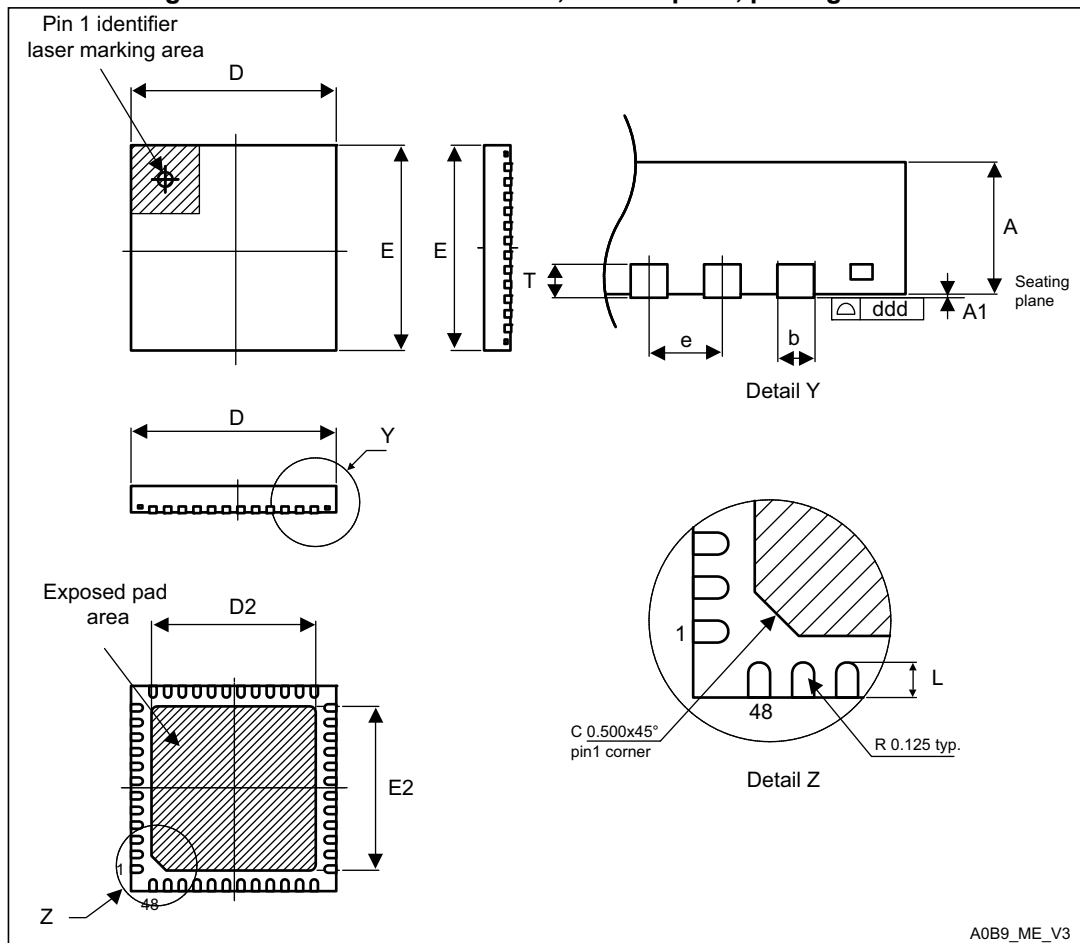
Table 70. UFBGA64 – 5 x 5 mm, 0.5 mm pitch, package mechanical data<sup>(1)</sup>

| Symbol | millimeters |       |       | inches <sup>(2)</sup> |        |        |
|--------|-------------|-------|-------|-----------------------|--------|--------|
|        | Min         | Typ   | Max   | Min                   | Typ    | Max    |
| A      | 0.460       | 0.530 | 0.600 | 0.0181                | 0.0209 | 0.0236 |
| A1     | 0.050       | 0.080 | 0.110 | 0.0020                | 0.0031 | 0.0043 |
| A2     | 0.400       | 0.450 | 0.500 | 0.0157                | 0.0177 | 0.0197 |
| A3     | 0.080       | 0.130 | 0.180 | 0.0031                | 0.0051 | 0.0071 |
| A4     | 0.270       | 0.320 | 0.370 | 0.0106                | 0.0126 | 0.0146 |
| b      | 0.170       | 0.280 | 0.330 | 0.0067                | 0.0110 | 0.0130 |
| D      | 4.850       | 5.000 | 5.150 | 0.1909                | 0.1969 | 0.2028 |
| D1     | 3.450       | 3.500 | 3.550 | 0.1358                | 0.1378 | 0.1398 |
| E      | 4.850       | 5.000 | 5.150 | 0.1909                | 0.1969 | 0.2028 |
| E1     | 3.450       | 3.500 | 3.550 | 0.1358                | 0.1378 | 0.1398 |
| e      | -           | 0.500 | -     | -                     | 0.0197 | -      |
| F      | 0.700       | 0.750 | 0.800 | 0.0276                | 0.0295 | 0.0315 |
| ddd    | -           | -     | 0.080 | -                     | -      | 0.0031 |
| eee    | -           | -     | 0.150 | -                     | -      | 0.0059 |
| fff    | -           | -     | 0.050 | -                     | -      | 0.0020 |

1. Preliminary data.

2. Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 40. UFQFPN48 – 7 x 7 mm, 0.5 mm pitch, package outline



1. Drawing is not to scale.
2. All leads/pads should also be soldered to the PCB to improve the lead/pad solder joint life.
3. There is an exposed die pad on the underside of the UFQFPN package. It is recommended to connect and solder this back-side pad to PCB ground.

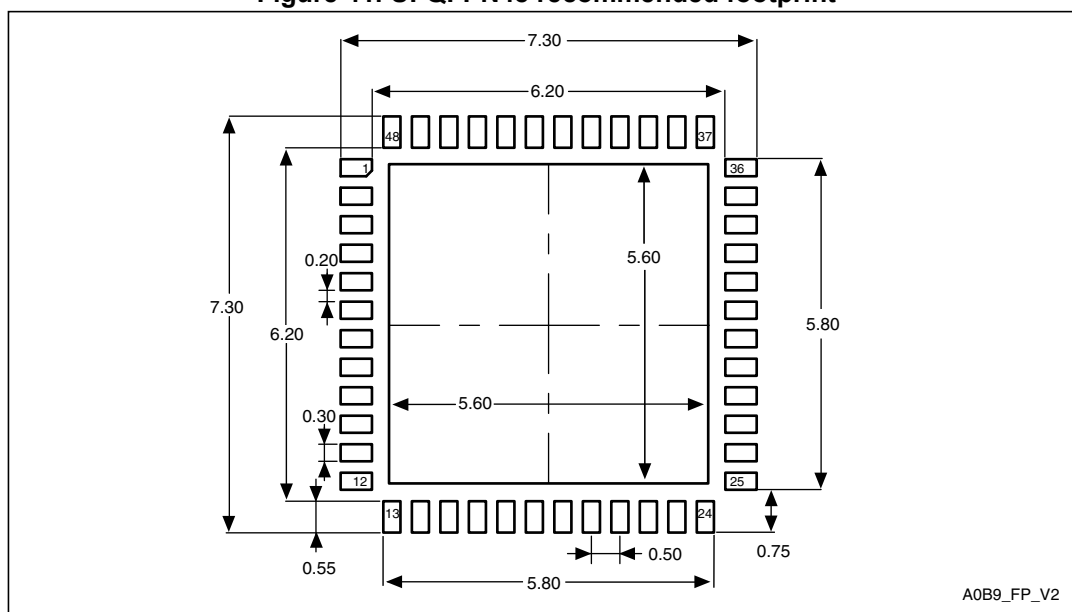


**Table 71. UFQFPN48 – 7 x 7 mm, 0.5 mm pitch, package mechanical data**

| Symbol | millimeters |       |       | inches <sup>(1)</sup> |        |        |
|--------|-------------|-------|-------|-----------------------|--------|--------|
|        | Min         | Typ   | Max   | Min                   | Typ    | Max    |
| A      | 0.500       | 0.550 | 0.600 | 0.0197                | 0.0217 | 0.0236 |
| A1     | 0.000       | 0.020 | 0.050 | 0.0000                | 0.0008 | 0.0020 |
| D      | 6.900       | 7.000 | 7.100 | 0.2717                | 0.2756 | 0.2795 |
| E      | 6.900       | 7.000 | 7.100 | 0.2717                | 0.2756 | 0.2795 |
| D2     | 5.500       | 5.600 | 5.700 | 0.2165                | 0.2205 | 0.2244 |
| E2     | 5.500       | 5.600 | 5.700 | 0.2165                | 0.2205 | 0.2244 |
| L      | 0.300       | 0.400 | 0.500 | 0.0118                | 0.0157 | 0.0197 |
| T      | -           | 0.152 | -     | -                     | 0.0060 | -      |
| b      | 0.200       | 0.250 | 0.300 | 0.0079                | 0.0098 | 0.0118 |
| e      | -           | 0.500 | -     | -                     | 0.0197 | -      |

1. Values in inches are converted from mm and rounded to 4 decimal digits.

**Figure 41. UFQFPN48 recommended footprint**



1. Dimensions are in millimeters.

PIN 1 IDENTIFIER  
LASER MARKING AREA

D A B W (4X) 0.100

Y

0.100 C A B 0.050 C

DETAIL Y

0.300x45°

1 32 R0.115 TYP.

DETAIL Z

3.500±0.100 0.100 C A B 3.500±0.100 3.500 REF. 0.100 C A B EXPOSED PAD AREA

PIN 1 CORNER Z

SEATING PLANE

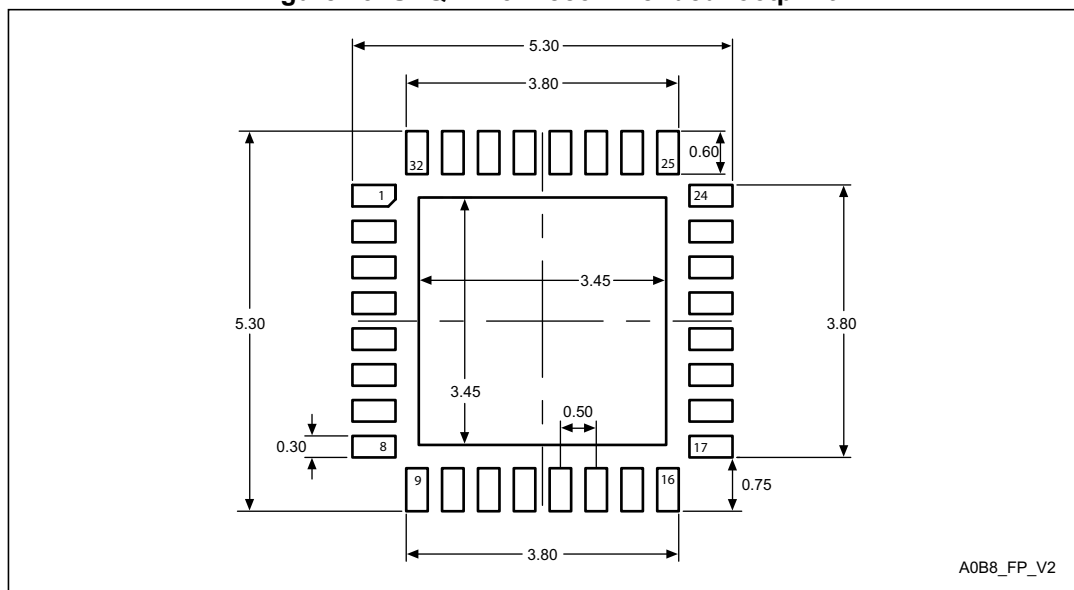
A0B8\_ME\_V2

- 

**Table 72. UFQFPN32 – 32-lead ultra thin fine pitch quad flat no-lead package (5 x 5),  
package mechanical data**

| Dim. | mm     |       |       | inches <sup>(1)</sup> |        |        |
|------|--------|-------|-------|-----------------------|--------|--------|
|      | Min    | Typ   | Max   | Min                   | Typ    | Max    |
| A    | 0.500  | 0.550 | 0.600 | 0.0197                | 0.0217 | 0.0236 |
| A1   | 0      | 0.020 | 0.050 | 0                     | 0.0008 | 0.0020 |
| A3   | -      | 0.152 | -     | -                     | 0.006  | -      |
| b    | 0.180  | 0.230 | 0.280 | 0.0071                | 0.0091 | 0.0110 |
| D    | 4.900  | 5.000 | 5.100 | 0.1929                | 0.1969 | 0.2008 |
| D2   | -      | 3.500 | -     | -                     | 0.1378 | -      |
| E    | 4.900  | 5.000 | 5.100 | 0.1929                | 0.1969 | 0.2008 |
| E2   | 3.400  | 3.500 | 3.600 | 0.1339                | 0.1378 | 0.1417 |
| e    | -      | 0.500 | -     | -                     | 0.0197 | -      |
| L    | 0.300  | 0.400 | 0.500 | 0.0118                | 0.0157 | 0.0197 |
| ddd  | 0.0800 |       |       | 0.0031                |        |        |

1. Values in inches are converted from mm and rounded to 4 decimal digits.

**Figure 43. UFQFPN32 recommended footprint**

1. Drawing is not to scale.
2. Dimensions are in millimeters.

## 7.2 Thermal characteristics

The maximum chip junction temperature ( $T_{Jmax}$ ) must never exceed the values given in [Table 20: General operating conditions](#).

The maximum chip-junction temperature,  $T_J$  max, in degrees Celsius, may be calculated using the following equation:

$$T_J \text{ max} = T_A \text{ max} + (P_D \text{ max} \times \Theta_{JA})$$

Where:

- $T_A$  max is the maximum ambient temperature in °C,
- $\Theta_{JA}$  is the package junction-to-ambient thermal resistance, in °C/W,
- $P_D$  max is the sum of  $P_{INT}$  max and  $P_{I/O}$  max ( $P_D \text{ max} = P_{INT} \text{ max} + P_{I/O} \text{ max}$ ),
- $P_{INT}$  max is the product of  $I_{DD}$  and  $V_{DD}$ , expressed in Watts. This is the maximum chip internal power.

$P_{I/O}$  max represents the maximum power dissipation on output pins where:

$$P_{I/O} \text{ max} = \Sigma (V_{OL} \times I_{OL}) + \Sigma ((V_{DDIOx} - V_{OH}) \times I_{OH}),$$

taking into account the actual  $V_{OL}$  /  $I_{OL}$  and  $V_{OH}$  /  $I_{OH}$  of the I/Os at low and high level in the application.

**Table 73. Package thermal characteristics**

| Symbol        | Parameter                                                                        | Value | Unit |
|---------------|----------------------------------------------------------------------------------|-------|------|
| $\Theta_{JA}$ | <b>Thermal resistance junction-ambient</b><br>LQFP64 - 10 × 10 mm / 0.5 mm pitch | 45    | °C/W |
|               | <b>Thermal resistance junction-ambient</b><br>LQFP48 - 7 × 7 mm                  | 55    |      |
|               | <b>Thermal resistance junction-ambient</b><br>LQFP32 - 7 × 7 mm                  | 56    |      |
|               | <b>Thermal resistance junction-ambient</b><br>UFBGA64 - 5 × 5 mm                 | 65    |      |
|               | <b>Thermal resistance junction-ambient</b><br>UFQFPN48 - 7 × 7 mm                | 32    |      |
|               | <b>Thermal resistance junction-ambient</b><br>UFQFPN32 - 5 × 5 mm                | 38    |      |

### 7.2.1 Reference document

JESD51-2 Integrated Circuits Thermal Test Method Environment Conditions - Natural Convection (Still Air). Available from [www.jedec.org](http://www.jedec.org)

### 7.2.2 Selecting the product temperature range

When ordering the microcontroller, the temperature range is specified in the ordering information scheme shown in [Section 8: Part numbering](#).

Each temperature range suffix corresponds to a specific guaranteed ambient temperature at maximum dissipation and, to a specific maximum junction temperature.

As applications do not commonly use the STM32F0xx at maximum dissipation, it is useful to calculate the exact power consumption and junction temperature to determine which temperature range will be best suited to the application.

The following examples show how to calculate the temperature range needed for a given application.

### Example 1: High-performance application

Assuming the following application conditions:

Maximum ambient temperature  $T_{Amax} = 82\text{ }^{\circ}\text{C}$  (measured according to JESD51-2),  
 $I_{DDmax} = 50\text{ mA}$ ,  $V_{DD} = 3.5\text{ V}$ , maximum 20 I/Os used at the same time in output at low level with  $I_{OL} = 8\text{ mA}$ ,  $V_{OL} = 0.4\text{ V}$  and maximum 8 I/Os used at the same time in output at low level with  $I_{OL} = 20\text{ mA}$ ,  $V_{OL} = 1.3\text{ V}$

$$P_{INTmax} = 50\text{ mA} \times 3.5\text{ V} = 175\text{ mW}$$

$$P_{IOmax} = 20 \times 8\text{ mA} \times 0.4\text{ V} + 8 \times 20\text{ mA} \times 1.3\text{ V} = 272\text{ mW}$$

This gives:  $P_{INTmax} = 175\text{ mW}$  and  $P_{IOmax} = 272\text{ mW}$ :

$$P_{Dmax} = 175 + 272 = 447\text{ mW}$$

Using the values obtained in [Table 73](#)  $T_{Jmax}$  is calculated as follows:

– For LQFP64,  $45\text{ }^{\circ}\text{C/W}$

$$T_{Jmax} = 82\text{ }^{\circ}\text{C} + (45\text{ }^{\circ}\text{C/W} \times 447\text{ mW}) = 82\text{ }^{\circ}\text{C} + 20.115\text{ }^{\circ}\text{C} = 102.115\text{ }^{\circ}\text{C}$$

This is within the range of the suffix 6 version parts ( $-40 < T_J < 105\text{ }^{\circ}\text{C}$ ) see [Table 20: General operating conditions](#).

In this case, parts must be ordered at least with the temperature range suffix 6 (see [Section 8: Part numbering](#)).

**Note:** With this given  $P_{Dmax}$  we can find the  $T_{Amax}$  allowed for a given device temperature range (order code suffix 6 or 7).

$$\text{Suffix 6: } T_{Amax} = T_{Jmax} - (45\text{ }^{\circ}\text{C/W} \times 447\text{ mW}) = 105 - 20.115 = 84.885\text{ }^{\circ}\text{C}$$

$$\text{Suffix 7: } T_{Amax} = T_{Jmax} - (45\text{ }^{\circ}\text{C/W} \times 447\text{ mW}) = 125 - 20.115 = 104.885\text{ }^{\circ}\text{C}$$

### Example 2: High-temperature application

Using the same rules, it is possible to address applications that run at high ambient temperatures with a low dissipation, as long as junction temperature  $T_J$  remains within the specified range.

Assuming the following application conditions:

Maximum ambient temperature  $T_{Amax} = 100\text{ }^{\circ}\text{C}$  (measured according to JESD51-2),  
 $I_{DDmax} = 20\text{ mA}$ ,  $V_{DD} = 3.5\text{ V}$ , maximum 20 I/Os used at the same time in output at low level with  $I_{OL} = 8\text{ mA}$ ,  $V_{OL} = 0.4\text{ V}$

$$P_{INTmax} = 20\text{ mA} \times 3.5\text{ V} = 70\text{ mW}$$

$$P_{IOmax} = 20 \times 8\text{ mA} \times 0.4\text{ V} = 64\text{ mW}$$

This gives:  $P_{INTmax} = 70\text{ mW}$  and  $P_{IOmax} = 64\text{ mW}$ :

$$P_{Dmax} = 70 + 64 = 134\text{ mW}$$

Thus:  $P_{Dmax} = 134\text{ mW}$

Using the values obtained in [Table 73](#)  $T_{Jmax}$  is calculated as follows:

– For LQFP64, 45 °C/W

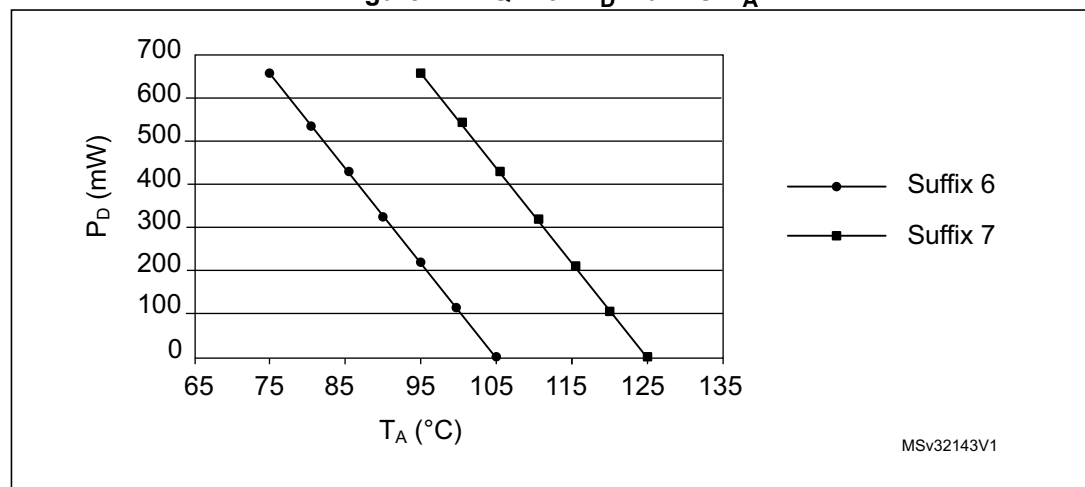
$$T_{Jmax} = 100\text{ °C} + (45\text{ °C/W} \times 134\text{ mW}) = 100\text{ °C} + 6.03\text{ °C} = 106.03\text{ °C}$$

This is above the range of the suffix 6 version parts ( $-40 < T_J < 105\text{ °C}$ ).

In this case, parts must be ordered at least with the temperature range suffix 7 (see [Section 8: Part numbering](#)) unless we reduce the power dissipation in order to be able to use suffix 6 parts.

Refer to [Figure 44](#) to select the required temperature range (suffix 6 or 7) according to your ambient temperature or power requirements.

**Figure 44. LQFP64  $P_D$  max vs.  $T_A$**



# 8 Part numbering

For a list of available options (memory, package, and so on) or for further information on any aspect of this device, please contact your nearest ST sales office.

Table 74. Ordering information scheme

|                                          |       |   |     |   |   |   |   |   |  |  |  |  |  |  |  |  |
|------------------------------------------|-------|---|-----|---|---|---|---|---|--|--|--|--|--|--|--|--|
| Example:                                 | STM32 | F | 051 | R | 8 | T | 6 | x |  |  |  |  |  |  |  |  |
| Device family                            |       |   |     |   |   |   |   |   |  |  |  |  |  |  |  |  |
| STM32 = ARM-based 32-bit microcontroller |       |   |     |   |   |   |   |   |  |  |  |  |  |  |  |  |
| Product type                             |       |   |     |   |   |   |   |   |  |  |  |  |  |  |  |  |
| F = General-purpose                      |       |   |     |   |   |   |   |   |  |  |  |  |  |  |  |  |
| Sub-family                               |       |   |     |   |   |   |   |   |  |  |  |  |  |  |  |  |
| 051 = STM32F051xx                        |       |   |     |   |   |   |   |   |  |  |  |  |  |  |  |  |
| Pin count                                |       |   |     |   |   |   |   |   |  |  |  |  |  |  |  |  |
| K = 32 pins                              |       |   |     |   |   |   |   |   |  |  |  |  |  |  |  |  |
| C = 48 pins                              |       |   |     |   |   |   |   |   |  |  |  |  |  |  |  |  |
| R = 64 pins                              |       |   |     |   |   |   |   |   |  |  |  |  |  |  |  |  |
| Code size                                |       |   |     |   |   |   |   |   |  |  |  |  |  |  |  |  |
| 4 = 16 Kbytes of Flash memory            |       |   |     |   |   |   |   |   |  |  |  |  |  |  |  |  |
| 6 = 32 Kbytes of Flash memory            |       |   |     |   |   |   |   |   |  |  |  |  |  |  |  |  |
| 8 = 64 Kbytes of Flash memory            |       |   |     |   |   |   |   |   |  |  |  |  |  |  |  |  |
| Package                                  |       |   |     |   |   |   |   |   |  |  |  |  |  |  |  |  |
| H = UFBGA                                |       |   |     |   |   |   |   |   |  |  |  |  |  |  |  |  |
| T = LQFP                                 |       |   |     |   |   |   |   |   |  |  |  |  |  |  |  |  |
| U = UFQFPN                               |       |   |     |   |   |   |   |   |  |  |  |  |  |  |  |  |
| Temperature range                        |       |   |     |   |   |   |   |   |  |  |  |  |  |  |  |  |
| 6 = −40 °C to +85 °C                     |       |   |     |   |   |   |   |   |  |  |  |  |  |  |  |  |
| 7 = −40 °C to +105 °C                    |       |   |     |   |   |   |   |   |  |  |  |  |  |  |  |  |
| Options                                  |       |   |     |   |   |   |   |   |  |  |  |  |  |  |  |  |
| xxx = programmed parts                   |       |   |     |   |   |   |   |   |  |  |  |  |  |  |  |  |
| TR = tape and reel                       |       |   |     |   |   |   |   |   |  |  |  |  |  |  |  |  |

## 9 Revision history

**Table 75. Document revision history**

| Date        | Revision | Changes                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                   |
|-------------|----------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 05-Apr-2012 | 1        | Initial release                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           |
| 25-Apr-2012 | 2        | Updated <a href="#">Table 2: STM32F051xx family device features and peripheral counts</a> for 1 SPI and 1 I2C in 32-pin package<br>Corrected Group 3 pin order in <a href="#">Table 5: Capacitive sensing GPIOs available on STM32F051xx devices</a> .<br>Updated current consumption <a href="#">Table 25</a> to <a href="#">Table 28</a> .<br>Updated <a href="#">Table 39: HSI14 oscillator characteristics</a>                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                        |
| 23-Jul-2012 | 3        | Features reorganized and <a href="#">Section Figure 1.: Block diagram</a> structure changed.<br>Added LQFP32 package.<br>Updated <a href="#">Section 3.4: Cyclic redundancy check calculation unit (CRC)</a> .<br>Modified number of priority levels in <a href="#">Section 3.9.1: Nested vectored interrupt controller (NVIC)</a> .<br>Added note 3. for PB2 and PB8, changed TIM2_CH_ETR into TIM2_CH1_ETR in <a href="#">Table 13: Pin definitions</a> and <a href="#">Table 14: Alternate functions selected through GPIOA_AFR registers for port A</a> . Added <a href="#">Table 15: Alternate functions selected through GPIOB_AFR registers for port B</a> .<br>Updated $I_{VDD}$ , $I_{VSS}$ , and $I_{INJ(PIN)}$ in <a href="#">Table 18: Current characteristics</a> .<br>Updated $ACC_{HSI}$ in <a href="#">Table 38: HSI oscillator characteristics</a> and <a href="#">Table 39: HSI14 oscillator characteristics</a> .<br>Updated <a href="#">Table 48: I/O current injection susceptibility</a> .<br>Added BOOT0 input low and high level voltage in <a href="#">Table 49: I/O static characteristics</a> .<br>Modified number of pins in $V_{OL}$ and $V_{OH}$ description, and changed condition for $V_{OLFM+}$ in <a href="#">Table 50: Output voltage characteristics</a> .<br>Changed $V_{DD}$ to $V_{DDA}$ in <a href="#">Figure 37: Typical connection diagram using the ADC</a> .<br>Updated $T_{s\_temp}$ in <a href="#">Table 58: TS characteristics</a> .<br>Updated <a href="#">Figure 27: I2C bus AC waveforms and measurement circuit</a> . |



Table 75. Document revision history (continued)

| Date        | Revision | Changes                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                             |
|-------------|----------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 13-Jan-2014 | 4        | <p>Modified datasheet title.</p> <p>Added packages UFQFPN48 and UFBGA64.</p> <p>Replaced “backup domain with “RTC domain” throughout the document.</p> <p>Changed SRAM value from “4 to 8 Kbytes” to “8 Kbytes”</p> <p>Replaced IWWDG with IWDG in <a href="#">Figure 1: Block diagram</a>.</p> <p>Added inputs LSI and LSE to the multiplexer in <a href="#">Figure 2: Clock tree</a>.</p> <p>Added feature “Reference clock detection” in <a href="#">Section 3.15: Real-time clock (RTC) and backup registers</a>.</p> <p>Modified junction temperature in <a href="#">Table 2: STM32F051xx family device features and peripheral counts</a>.</p> <p>Renamed <a href="#">Table 4: Internal voltage reference calibration values</a>.</p> <p>Replaced <math>V_{DD}</math> with <math>V_{DDA}</math> and <math>V_{RERINT}</math> with <math>\Delta V_{REFINT}</math> in <a href="#">Table 24: Embedded internal reference voltage</a>.</p> <p>Rephrased introduction of <a href="#">Section 3.13: Touch sensing controller (TSC)</a>.</p> <p>Rephrased <a href="#">Section 3.5.3: Voltage regulator</a>.</p> <p>Added sentence “If this is used when the voltage regulator is put in low power mode...” under “Stop mode” in <a href="#">Section 3.5.4: Low-power modes</a>.</p> <p>Removed sentence “The internal voltage reference is also connected to ADC_IN17 input channel of the ADC.” in <a href="#">Section 3.12: Comparators (COMP)</a>.</p> <p>Removed feature “Periodic wakeup from Stop/Standby” in <a href="#">Section 3.15: Real-time clock (RTC) and backup registers</a>.</p> <p>Replaced <math>I_{DD}</math> with <math>I_{DDA}</math> in <a href="#">Table 38: HSI oscillator characteristics</a>, <a href="#">Table 39: HSI14 oscillator characteristics</a> and <a href="#">Table 40: LSI oscillator characteristics</a>.</p> <p>Moved section “Wakeup time from low-power mode” to <a href="#">Section 6.3.6</a> and rephrased the section.</p> <p>Added lines D2 and E2 in <a href="#">Table 71: UFQFPN48 – 7 x 7 mm, 0.5 mm pitch, package mechanical data</a>.</p> <p>Added “The peripheral clock used is 48 MHz.” in <a href="#">Section On-chip peripheral current consumption</a>.</p> |

Table 75. Document revision history (continued)

| Date        | Revision         | Changes                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                          |
|-------------|------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 13-Jan-2014 | 4<br>(continued) | <p>Added "Negative induced leakage current is caused by negative injection and positive induced leakage current is caused by positive injection" in Section <i>Functional susceptibility to I/O current injection</i>.</p> <p>Replaced reference "JESD22-C101" with "ANSI/ESD STM5.3.1" in <i>Table 46: ESD absolute maximum ratings</i>.</p> <p>Merged <i>Table 27: Typical and maximum <math>V_{DD}</math> consumption in Stop and Standby modes</i> and <i>Table 28: Typical and maximum <math>V_{DDA}</math> consumption in Stop and Standby modes</i> into <i>Table 27: Typical and maximum current consumption in Stop and Standby modes</i>.</p> <p>Updated:</p> <ul style="list-style-type: none"> <li>– <i>Table 3: Temperature sensor calibration values</i></li> <li>– <i>Table 4: Internal voltage reference calibration values</i></li> <li>– <i>Table 18: Current characteristics</i></li> <li>– <i>Table 20: General operating conditions</i></li> <li>– <i>Table 26: Typical and maximum current consumption from the VDDA supply</i></li> <li>– <i>Table 33: Low-power mode wakeup timings</i></li> <li>– <i>Table 48: I/O current injection susceptibility</i></li> <li>– <i>Table 49: I/O static characteristics</i></li> <li>– <i>Table 50: Output voltage characteristics</i></li> <li>– <i>Table 52: NRST pin characteristics</i></li> <li>– <i>Table 63: I2C characteristics</i></li> <li>– <i>Figure 12: Power supply scheme</i></li> <li>– <i>Figure 20: TC and TTA I/O input characteristics</i></li> <li>– <i>Figure 21: Five volt tolerant (FT and FTf) I/O input characteristics</i></li> <li>– <i>Figure 22: I/O AC characteristics definition</i></li> <li>– <i>Figure 27: I2C bus AC waveforms and measurement circuit</i></li> <li>– <i>Figure 25: Typical connection diagram using the ADC</i></li> <li>– <i>Figure 33: LQFP64 – 10 x 10 mm 64 pin low-profile quad flat package outline</i></li> <li>– <i>Figure 34: LQFP64 recommended footprint</i></li> <li>– <i>Figure 35: LQFP48 – 7 x 7 mm, 48 pin low-profile quad flat package outline</i></li> <li>– <i>Figure 36: LQFP48 recommended footprint</i></li> <li>– <i>Figure 37: LQFP32 – 7 x 7 mm 32-pin low-profile quad flat package outline</i></li> <li>– <i>Figure 38: LQFP32 recommended footprint</i></li> <li>– <i>Figure 40: UFQFPN48 – 7 x 7 mm, 0.5 mm pitch, package outline</i></li> </ul> |

**Please Read Carefully:**

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

**UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.**

**ST PRODUCTS ARE NOT DESIGNED OR AUTHORIZED FOR USE IN: (A) SAFETY CRITICAL APPLICATIONS SUCH AS LIFE SUPPORTING, ACTIVE IMPLANTED DEVICES OR SYSTEMS WITH PRODUCT FUNCTIONAL SAFETY REQUIREMENTS; (B) AERONAUTIC APPLICATIONS; (C) AUTOMOTIVE APPLICATIONS OR ENVIRONMENTS, AND/OR (D) AEROSPACE APPLICATIONS OR ENVIRONMENTS. WHERE ST PRODUCTS ARE NOT DESIGNED FOR SUCH USE, THE PURCHASER SHALL USE PRODUCTS AT PURCHASER'S SOLE RISK, EVEN IF ST HAS BEEN INFORMED IN WRITING OF SUCH USAGE, UNLESS A PRODUCT IS EXPRESSLY DESIGNATED BY ST AS BEING INTENDED FOR "AUTOMOTIVE, AUTOMOTIVE SAFETY OR MEDICAL" INDUSTRY DOMAINS ACCORDING TO ST PRODUCT DESIGN SPECIFICATIONS. PRODUCTS FORMALLY ESCC, QML OR JAN QUALIFIED ARE DEEMED SUITABLE FOR USE IN AEROSPACE BY THE CORRESPONDING GOVERNMENTAL AGENCY.**

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2014 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

[www.st.com](http://www.st.com)





Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

**Телефон:** 8 (812) 309 58 32 (многоканальный)

**Факс:** 8 (812) 320-02-42

**Электронная почта:** [org@eplast1.ru](mailto:org@eplast1.ru)

**Адрес:** 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.